

1. OUTLINE

1.1 Features

Ultra-low power consumption technology

- V_{DD} = 2.4 to 5.5 V
- HALT mode
- STOP mode
- SNOOZE mode

RL78 CPU core

- CISC architecture with 3-stage pipeline
- Minimum instruction execution time: Can be changed from high speed (0.03125 μ s: @ 32 MHz operation with high-speed on-chip oscillator or PLL clock)^{Note} to ultra-low speed (1 μ s: @ 1 MHz operation with high-speed on-chip oscillator or PLL clock)
- Multiply/divide/multiply & accumulate instructions are supported.
- Address space: 1 MB
- General-purpose registers: (8-bit register \times 8) \times 4 banks
- On-chip RAM: 8 KB

Note For industrial applications (M; TA = -40 to +125°C): 0.04167 μ s @ 24 MHz operation with high-speed on-chip oscillator or PLL clock

Code flash memory

- Code flash memory: 32 KB
- Block size: 1 KB
- Prohibition of block erase and rewriting (security function)
- On-chip debug function
- Self-programming (with boot swap function/flash shield window function)

Data flash memory

- Data flash memory: 4 KB
- Back ground operation (BGO): Instructions can be executed from the program memory while rewriting the data flash memory.
- Number of rewrites: 1,000,000 times (TYP.)
- Voltage of rewrites: V_{DD} = 2.4 to 5.5 V

High-speed on-chip oscillator

- Select from 32 MHz, 24 MHz, 16 MHz, 12 MHz, 8 MHz, 6 MHz, 4 MHz, 3 MHz, 2 MHz, and 1 MHz
- High accuracy:
 - $\pm 2.0\%$ (V_{DD} = 2.4 to 5.5 V, TA = -40 to +105°C)
 - $\pm 3.0\%$ (V_{DD} = 2.4 to 5.5 V, TA = -40 to +125°C)

Operating ambient temperature

- TA = -40 to +105°C (G: Industrial applications)
- TA = -40 to +125°C (M: Industrial applications)

Power management and reset function

- On-chip power-on-reset (POR) circuit
- On-chip voltage detector (LVD) (Select interrupt and reset from 7 levels)

Data transfer controller (DTC)

- Transfer modes: Normal transfer mode, repeat transfer mode, block transfer mode
- Activation sources: Activated by interrupt sources.
- Chain transfer function

Event link controller (ELC)

- Event signals of 16 types can be linked to the specified peripheral function.

Serial interfaces

- Simplified SPI(CSI): 2 channels
- UART: 2 channels (UART with LIN-bus supported: 1 channel)
- I²C/simplified I²C: 2 channels

Timer

- 16-bit timer: 8 channels
(Timer Array Unit (TAU): 6 channels, timer RJ: 1 channel, timer RG: 1 channel)
- Interval timer: 1 channel
- Real-time clock: 1 channel (calendar for 99 years, alarm function, and clock correction function)
- Watchdog timer: 1 channel (operable with the dedicated low-speed on-chip oscillator)

Analog front-end (AFE) power supply

- Sensor power supply (SBIAS) output: 0.5 V to 2.2 V

24-bit $\Delta\Sigma$ A/D converter with programmable gain instrumentation amplifier

- 24-bit second-order $\Delta\Sigma$ A/D converter (AV_{DD} = 2.7 to 5.5 V)
- SNDR: 85 dB (TYP.)
- Output data rate:
 - 488 sps to 15.625 ksps in normal mode
 - 61 sps to 1.953 ksps in low power mode
- Programmable gain instrumentation amplifier input: 3 or 4 channels
(differential input mode or single-ended input mode can be specified for each input channel)
- DAC for offset adjustment
- Variable gain: x1 to x64
- On-chip temperature sensor

10-bit A/D converter

- 8-bit/10-bit successive approximation A/D converter (AV_{DD} = 2.7 to 5.5 V)
- Analog input: 8 or 10 channels, sensor power supply (SBIAS), and internal reference voltage
- Internal reference voltage (1.45 V)

Configurable amplifier

- Matrix configuration that consists of 3 operational amplifier channels and a configurable switch (AV_{DD} = 2.7 to 5.5 V)
- Can be used as a 2- or 3-channel general operational amplifier
- Operational amplifier output: 3 channels
- General-purpose Analog I/O ports: 5 or 6 channels
- Offset voltage calibration

D/A converter

- 12-bit R-2R resistor ladder type D/A converter (AV_{DD} = 2.7 to 5.5 V)
- Analog output: 1 channel (via configurable amplifier)

I/O port

- CMOS I/O: 10 to 14 (N-ch open drain I/O [withstanding voltage of V_{DD}]: 6, CMOS I/O: 7 to 11, CMOS input: 3)
- Can be set to TTL input buffer and on-chip pull-up resistor
- Different potential interface: Can connect to a 2.5/3 V device
- On-chip clock output/buzzer output controller

Others

- On-chip BCD (binary-coded decimal) correction circuit

Note Although the CSI function is generally called SPI, it is also called CSI in this product, so it is referred to as such in this manual.

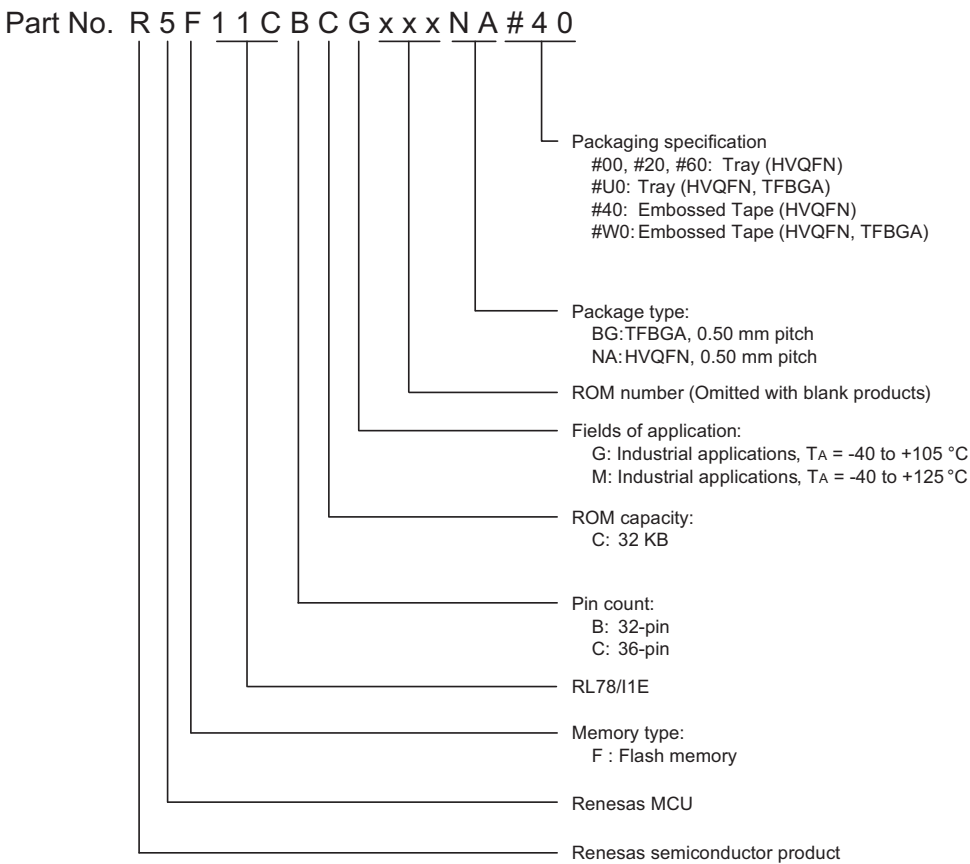
○ ROM, RAM capacities

| Flash ROM | Data flash | RAM | RL78/I1E | |
|-----------|------------|------|----------|----------|
| | | | 32 pins | 36 pins |
| 32 KB | 4 KB | 8 KB | R5F11CBC | R5F11CCC |

1.2 Ordering Information

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Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E



<R>

| Pin count | Package | Fields of Application Note | Ordering Part Number |
|-----------|--|-------------------------------|--|
| 32 pins | 32-pin plastic HVQFN (5 × 5 mm, 0.5 mm pitch) | G | R5F11CBCGNA#20 R5F11CBCGNA#40 R5F11CBCGNA#00 R5F11CBCGNA#60 |
| | | M | R5F11CBCMNA#U0 R5F11CBCMNA#W0 |
| 36 pins | 36-pin plastic TFBGA (4 × 4 mm, 0.5 mm pitch) | G | R5F11CCCGBG#U0 R5F11CCCGBG#W0 |
| | | M | R5F11CCCMBG#U0 R5F11CCCMBG#W0 |

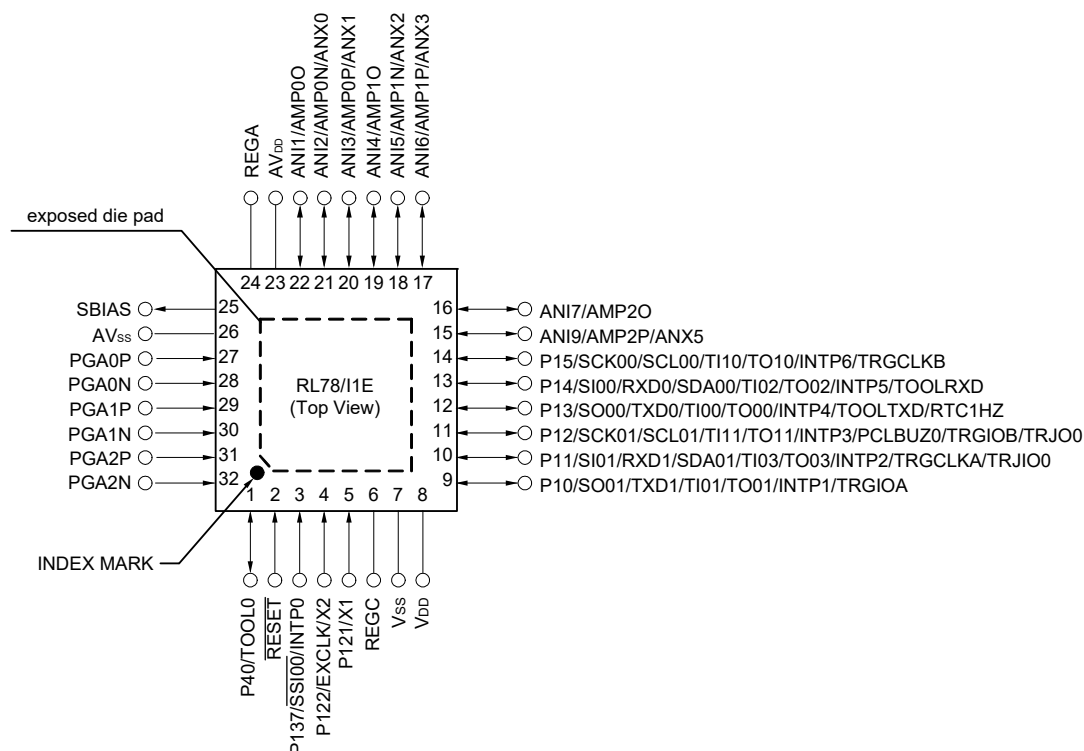
Note For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E**.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

1.3 Pin Configuration (Top View)

1.3.1 32-pin products

- 32-pin plastic HVQFN (5 × 5 mm, 0.5 mm pitch)



Caution 1. Connect the REGC pin to the V_{SS} pin via a capacitor (0.47 to 1 μF).

Caution 2. Connect the REGA pin to the AV_{SS} pin via a capacitor (0.22 μF).

Caution 3. Make the AV_{SS} pin the same potential as the V_{SS} pin.

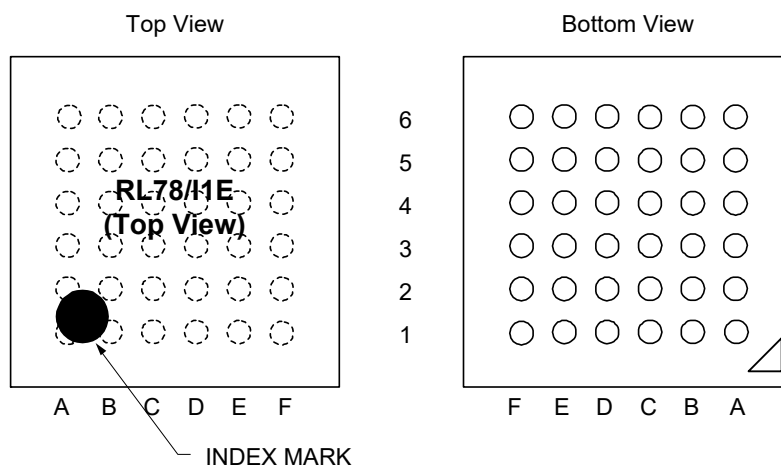
Caution 4. Make the AV_{DD} pin the same potential as the V_{DD} pin.

Caution 5. Connect the SBIAS pin to the AV_{SS} pin via a capacitor (0.22 μF).

Remark 1. It is recommended to connect an exposed die pad to V_{SS}.

1.3.2 36-pin products

- 36-pin plastic TFBGA (4 × 4 mm, 0.5 mm pitch)



| | A | B | C | D | E | F | |
|---|---------------|---|--|--|-------------------------|------------|---|
| 6 | PGA2P | PGA1N | PGA1P | PGA0P | PGA3P | AVss | 6 |
| 5 | PGA2N | P40/TOOL0 | PGA0N | PGA3N | REGA | SBIAS | 5 |
| 4 | RESET | P137/SSI00/ INTP0 | P11/SI01/RXD1/ SDA01/TI03/ TO03/INTP2/ TRGCLKA/ TRJIO0 | P12/SCK01/ SCL01/TI11/ TO11/INTP3/ PCLBUZ0/ TRGIOB/TRJO0 | ANI0 | AVDD | 4 |
| 3 | P122/EXCLK/X2 | P15/SCK00/ SCL00/TI10/ TO10/INTP6/ TRGCLKB | P10/SO01/TXD1/ TI01/TO01/ INTP1/TRGIOA | ANI3/AMP0P/ ANX1 | ANI2/AMP0N/ ANX0 | ANI1/AMP0O | 3 |
| 2 | P121/X1 | REGC | P14/SI00/RXD0/ SDA00/TI02/ TO02/INTP5/ TOOLRXD | P41/ANI6/ AMP1P/ANX3 | P42/ANI5/ AMP1N/ANX2 | ANI4/AMP1O | 2 |
| 1 | VDD | Vss | P13/SO00/TXD0/ TI00/TO00/INTP4/ TOOLTXD/ RTC1HZ | P16/INTP7/ANI9/ AMP2P/ANX5 | P17/ANI8/ AMP2N/ANX4 | ANI7/AMP2O | 1 |
| | A | B | C | D | E | F | |

Caution 1. Connect the REGC pin to the Vss pin via a capacitor (0.47 to 1 μF).

Caution 2. Connect the REGA pin to the AVss pin via a capacitor (0.22 μF).

Caution 3. Make the AVss pin the same potential as the Vss pin.

Caution 4. Make the AVDD pin the same potential as the VDD pin.

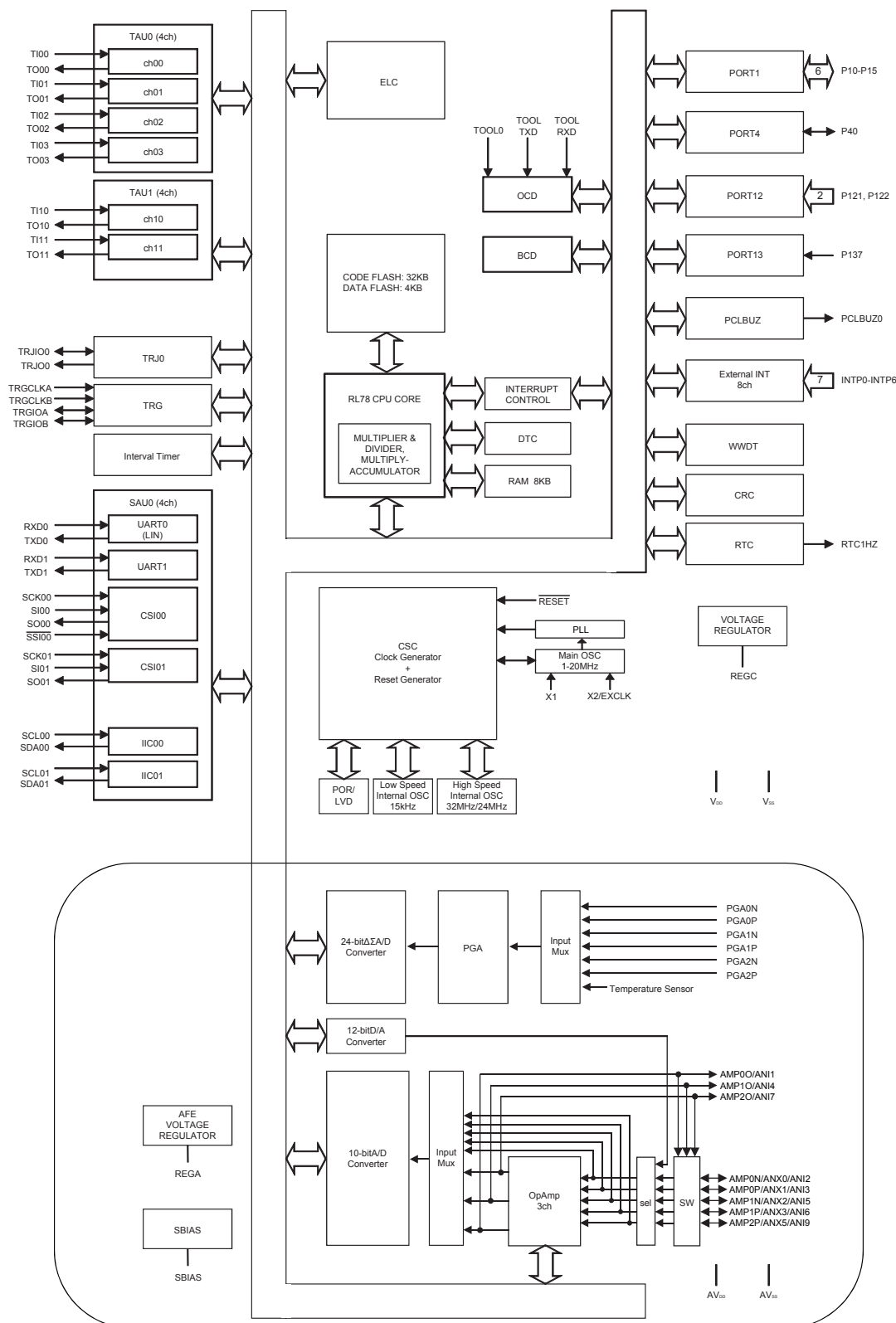
Caution 5. Connect the SBIAS pin to the AVss pin via a capacitor (0.22 μF).

1.4 Pin Identification

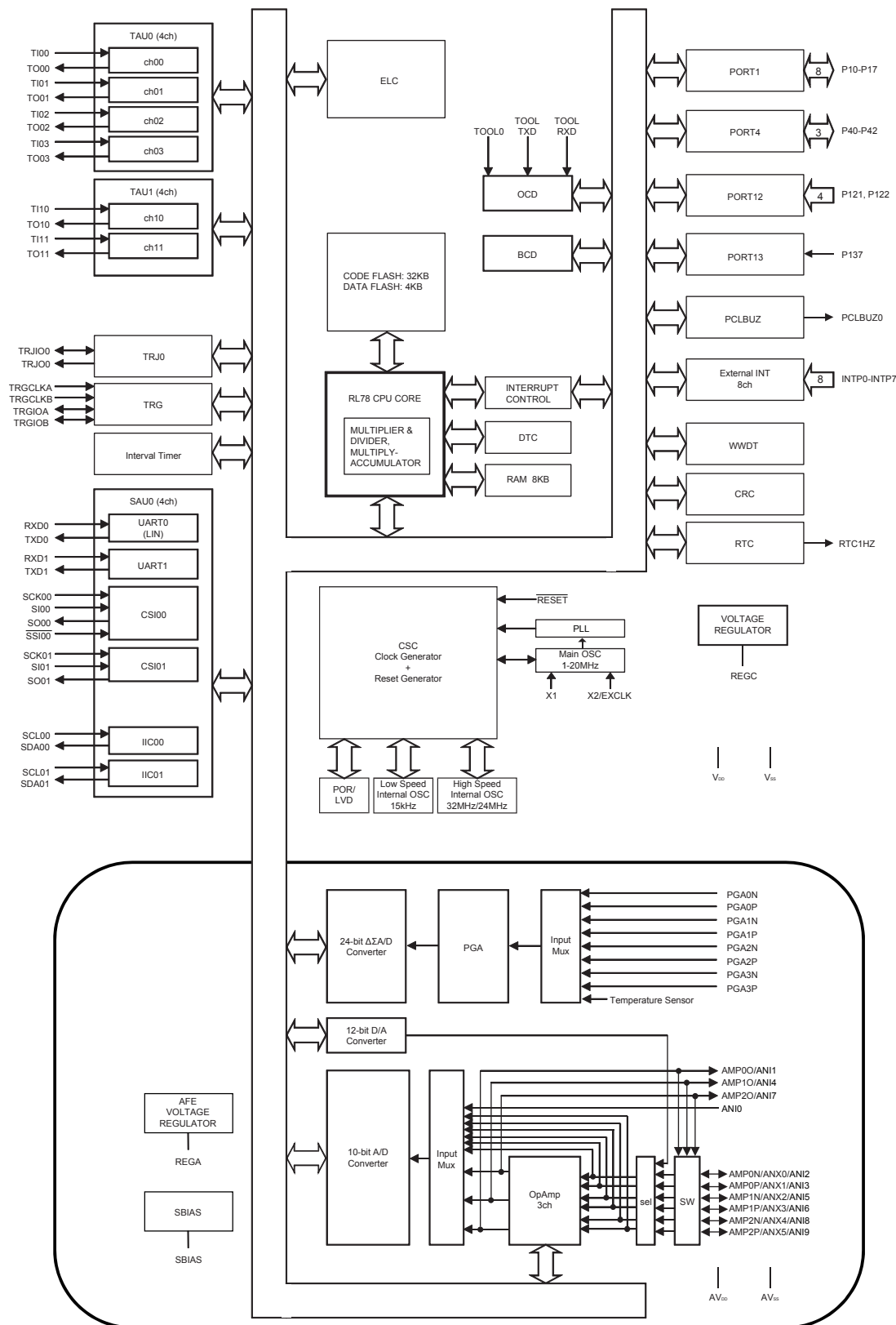
| | | | |
|-----------------|---|---------------------------|--|
| ANI0 to ANI9: | Analog input | <u>RESET</u> : | Reset |
| AMP0P to AMP2P: | Operational amplifier positive input | REGA: | Regulator capacitance for analog |
| AMP0N to AMP2N: | Operational amplifier negative input | REGC: | Regulator capacitance |
| AMP0O to AMP2O: | Operational amplifier output | RTC1HZ: | Real-time clock correction |
| ANX0 to ANX5: | General-purpose analog ports for operational amplifier | RxD0, RxD1: | Receive data |
| AVDD: | Power supply for analog | SBIAS: | Bias output for MEMS sensor |
| AVSS: | Ground for analog | SCK00, SCK01: | Serial clock input/output |
| EXCLK: | External clock input (main system clock) | SCL00, SCL01: | Serial clock output |
| INTP0 to INTP7: | External interrupt input | SI00, SI01: | Serial data input |
| P10 to P17: | Port 1 | SO00, SO01: | Serial data output |
| P40 to P42: | Port 4 | TI00 to TI03, TI10, TI11: | Timer input |
| P121, P122: | Port 12 | TO00 to TO03, TO10, TO11, | Timer output |
| P137: | Port 13 | TRJ00: | |
| PCLBUZ0: | Programmable clock output/ buzzer output | TOOL0: | Data input/output for tools |
| PGA0N to PGA3N: | PGA negative analog input | TOOLRxD, TOOLTxD: | Data input/output for external devices |
| PGA0P to PGA3P: | PGA positive analog input | TRGCLKA, TRGCLKB: | Timer external clock input |
| | | TRGIOA, TRGIOB, TRJIO0: | Timer input/output |
| | | TxD0, TxD1: | Transmit data |
| | | VDD: | Power supply |
| | | VSS: | Ground |
| | | X1, X2: | Crystal oscillator (main system clock) |

1.5 Block Diagram

1.5.1 32-pin products



1.5.2 36-pin products



1.6 Outline of Functions

[32-pin, 36-pin products]

(1/2)

| Item | | 32-pin | 36-pin |
|------------------------------------|--|--|-------------|
| | | R5F11CBC | R5F11CCC |
| Code flash memory | | 32 KB | |
| Data flash memory | | 4 KB | |
| RAM | | 8 KB | |
| Address space | | 1 MB | |
| Main system clock | High-speed system clock | X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) 1 to 20 MHz: $V_{DD} = 2.7$ to 5.5 V, 1 to 16 MHz: $V_{DD} = 2.4$ to 2.7 V | |
| | High-speed on-chip oscillator clock (f_{IH}) | 1 to 32 MHz ($V_{DD} = 2.7$ to 5.5 V) ^{Note 1} 1 to 16 MHz ($V_{DD} = 2.4$ to 5.5 V) | |
| | PLL clock (f_{PLL} divided by 2, 4, or 8) | 3 to 32 MHz ($V_{DD} = 2.7$ to 5.5 V) ^{Note 2} 3 to 16 MHz ($V_{DD} = 2.4$ to 5.5 V) | |
| General-purpose register | | 8 bits \times 32 registers (8 bits \times 8 registers \times 4 banks) | |
| Minimum instruction execution time | | 0.03125 μ s (high-speed on-chip oscillator clock: $f_{IH} = 32$ MHz operation) ^{Note 3} | |
| | | 0.03125 μ s (PLL clock: $f_{PLL} = 64$ MHz, $f_{IH} = 32$ MHz operation) ^{Note 4} | |
| | | 0.05 μ s (high-speed system clock: $f_{MX} = 20$ MHz operation) | |
| Instruction set | | <ul style="list-style-type: none"> • Data transfer (8/16 bits) • Adder and subtractor/logical operation (8/16 bits) • Multiplication (8 bits \times 8 bits, 16 bits \times 16 bits), division (16 bits \div 16 bits, 32 bits \div 32 bits) • Multiplication and Accumulation (16 bits \times 16 bits \div 32 bits) • Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc. | |
| I/O port | Total | 10 | 14 |
| | CMOS I/O | 7 | 11 |
| | CMOS input | 3 | 3 |
| Timer | 16-bit timer | 8 channels (TAU: 6 channels, Timer RJ: 1 channel, Timer RG: 1 channel) | |
| | Watchdog timer | 1 channel | |
| | Real-time clock (RTC) | 1 channel | |
| | Interval timer | 1 channel | |
| | Timer output | Timer outputs: 10 channels PWM outputs: 9 channels | |
| | RTC output | 1 | |
| Clock output/buzzer output | | 1 | |
| | | 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: $f_{MAIN} = 20$ MHz operation) | |
| 8/10-bit A/D converter | | 8 channels | 10 channels |
| Serial interface | | Simplified SPI(CSI): 2 channels/UART: 2 channels (UART supporting LIN-bus: 1 channel)/simplified I ² C: 2 channels | |

Note 1. 1 to 24 MHz ($V_{DD} = 2.7$ to 5.5 V) for M products (industrial applications, $T_A = -40$ to $+125^\circ\text{C}$)

Note 2. 3 to 24 MHz ($V_{DD} = 2.7$ to 5.5 V) for M products (industrial applications, $T_A = -40$ to $+125^\circ\text{C}$)

Note 3. 0.04167 μ s (high-speed on-chip oscillator clock: $f_{IH} = 24$ MHz operation) for M products (industrial applications, $T_A = -40$ to $+125^\circ\text{C}$)

Note 4. 0.04167 μ s (PLL clock: $f_{PLL} = 64$ MHz, $f_{IH} = 24$ MHz operation) for M products (industrial applications, $T_A = -40$ to $+125^\circ\text{C}$)

(2/2)

| Item | | 32-pin | 36-pin |
|--------------------------------|------------------------|---|------------|
| | | R5F11CBC | R5F11CCC |
| Data transfer controller (DTC) | | 22 sources | |
| Event link controller (ELC) | | Event input: 16 Event trigger output: 7 | |
| Vectored interrupt sources | Internal | 23 | 23 |
| | External | 7 | 8 |
| $\Delta\Sigma$ A/D converter | 24-bit | 3 channels | 4 channels |
| | AFE temperature sensor | 1 channel | |
| Operational amplifier | 3-pin | 3 channels <small>Note 1</small> | 3 channels |
| | General-purpose port | 5 channels | 6 channels |
| D/A converter | 12-bit | 1 channel | |
| Reset | | <ul style="list-style-type: none"> Reset by $\overline{\text{RESET}}$ pin Internal reset by watchdog timer Internal reset by power-on-reset Internal reset by voltage detector Internal reset by illegal instruction execution <small>Note 2</small> Internal reset by RAM parity error Internal reset by illegal-memory access | |
| Power-on-reset circuit | | <ul style="list-style-type: none"> Power-on-reset: 1.56 \pm 0.03 V Power-down-reset: 1.55 \pm 0.03 V | |
| Voltage detector | | <ul style="list-style-type: none"> At rise: 2.55 V to 4.64 V (7 steps) At fall: 2.61 V to 4.74 V (7 steps) | |
| On-chip debug function | | Provided | |
| Power supply voltage | | $V_{DD} = 2.4$ to 5.5 V | |
| Operating ambient temperature | | $T_A = -40$ to $+105^\circ\text{C}$ (G: Industrial applications), $T_A = -40$ to $+125^\circ\text{C}$ (M: Industrial applications) | |

Note 1. When each of the 3 channels is in use as an independent amplifier, at least one channel must be in a voltage follower configuration.

Note 2. The illegal instruction is generated when instruction code FFH is executed.
Reset by the illegal instruction execution not is issued by emulation with the in-circuit emulator or on-chip debug emulator.

2. ELECTRICAL SPECIFICATIONS (G: TA = -40 to +105°C)

This chapter describes the electrical specifications for the products “G: Industrial applications (TA = -40 to +105°C)”.

Caution 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

Caution 2. The pins mounted depend on the product.

Caution 3. Please contact Renesas Electronics sales office for derating of operation under TA = +85 to +105°C. Derating is the systematic reduction of load for the sake of improved reliability.

Remark The electrical characteristics of the products G: Industrial applications (TA = -40 to +105°C) are different from those of the products “M: Industrial applications”. For details, refer to **2.1** to **2.10**.

2.1 Absolute Maximum Ratings

Absolute Maximum Ratings

(1/2)

| Parameter | Symbol | Conditions | Ratings | Unit |
|---------------------------------------|---------------------|--|---|---------------------------------------|
| Supply voltage | V _{DD} | | -0.5 to +6.5 | V |
| | AV _{DD} | AV _{DD} = V _{DD} | -0.5 to +6.5 | V |
| | AV _{SS} | AV _{SS} = V _{SS} | -0.5 to +0.3 | V |
| REGC pin input voltage | V _I REGC | REGC | -0.3 to +2.8 and -0.3 to V _{DD} + 0.3 Note 1 | V |
| REGA pin input voltage | V _I REGA | REGA | -0.3 to +2.8 and -0.3 to AV _{DD} + 0.3 Note 2 | V |
| Input voltage | V _{I1} | P10 to P15, P40, P121, P122, P137, EXCLK, RESET | -0.3 to V _{DD} + 0.3 Note 3 | V |
| Alternate-function pin input voltage | V _{I2} | P16, P17, P41, P42 (36-pin products only) | Digital input voltage | -0.3 to V _{DD} + 0.3 Note 3 |
| | | | Analog input voltage | -0.3 to AV _{DD} + 0.3 Note 3 |
| Analog input voltage | V _{IA} | PGA0P to PGA3P, PGA0N to PGA3N, ANI0 to ANI9, ANX0 to ANX5 | -0.3 to AV _{DD} + 0.3 Note 3 | V |
| Output voltage | V _{O1} | P10 to P15, P40 | -0.3 to V _{DD} + 0.3 Note 3 | V |
| Alternate-function pin output voltage | V _{O2} | P16, P17, P41, P42 (36-pin products only) | Digital output voltage | -0.3 to V _{DD} + 0.3 Note 3 |
| | | | Analog output voltage | -0.3 to AV _{DD} + 0.3 Note 3 |
| Analog output voltage | V _{OA} | SBIAS, AMP0O to AMP2O, ANX0 to ANX5 | -0.3 to AV _{DD} + 0.3 Note 3 | V |

Note 1. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

Note 2. Connect the REGA pin to AV_{SS} via a capacitor (0.22 μF). This value regulates the absolute maximum rating of the REGA pin. Do not use this pin with voltage applied to it.

Note 3. Must be 6.5 V or lower.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Remark 2. V_{SS} is used as the reference voltage.

Absolute Maximum Ratings**(2/2)**

| Parameter | Symbol | Conditions | | Ratings | Unit |
|-------------------------------|------------------|----------------------------------|----------------------------------|-------------|------|
| Output current, high | IOH1 | Per pin | P10 to P17, P40 to P42 | -40 | mA |
| | | Total of all pins | P10 to P17, P41, P42 <i>Note</i> | -100 | mA |
| Analog output current, high | IOHA | Per pin | AMP00 to AMP20 | -12 | mA |
| | | | ANX0 to ANX5 | -0.12 | mA |
| | | Total of all pins | AMP00 to AMP20, ANX0 to ANX5 | -18 | mA |
| Output current, low | IOL1 | Per pin | P10 to P17, P40 to P42 | 40 | mA |
| | | Total of all pins | P10 to P17, P41, P42 <i>Note</i> | 100 | mA |
| Analog output current, low | IOLA | Per pin | AMP00 to AMP20 | 12 | mA |
| | | | ANX0 to ANX5 | 0.12 | mA |
| | | Total of all pins | AMP00 to AMP20, ANX0 to ANX5 | 18 | mA |
| Operating ambient temperature | TA | In normal operation mode | | -40 to +105 | °C |
| | | In flash memory programming mode | | | |
| Storage temperature | T _{stg} | | | -65 to +150 | °C |

Note This indicates the total current value when P16, P17, P41, and P42 are used as digital input pins.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Remark 2. V_{ss} is used as the reference voltage.

2.2 Oscillator Characteristics

2.2.1 X1 characteristics

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Resonator | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---|---------------------|------|------|------|------|
| X1 clock oscillation frequency (fx) ^{Note} | Ceramic resonator/ crystal resonator | 2.7 V ≤ VDD ≤ 5.5 V | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | 1.0 | | 16.0 | |

Note Indicates only permissible oscillator frequency ranges. Refer to **AC Characteristics** for instruction execution time.
Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

2.2.2 On-chip oscillator characteristics

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|---|-----------------|---------------------|---------------------|------|------|------|------|
| High-speed on-chip oscillator clock frequency Notes 1, 2 | f _{IH} | 2.7 V ≤ VDD ≤ 5.5 V | | 1 | | 32 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | | 1 | | 16 | MHz |
| High-speed on-chip oscillator clock frequency accuracy | | -40 to +105°C | 2.4 V ≤ VDD ≤ 5.5 V | -2.0 | | +2.0 | % |
| Low-speed on-chip oscillator clock frequency | f _{IL} | | | | 15 | | kHz |
| Low-speed on-chip oscillator clock frequency accuracy | | | | -15 | | +15 | % |

Note 1. High-speed on-chip oscillator frequency is selected with bits 0 to 3 of the option byte (000C2H) and bits 0 to 2 of the HOCODIV register.

Note 2. This only indicates the oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

2.2.3 PLL characteristics

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | | MIN. | TYP. | MAX. | Unit |
|---|------------------|---|-------------|----------|------|------|------|------|
| PLL output frequency ^{Notes 1, 2, 3} | f _{PLL} | f _{MX} = 8 MHz | DSFRDIV = 0 | DSCM = 0 | | 48 | | MHz |
| | | | | DSCM = 1 | | 64 | | MHz |
| | | | DSFRDIV = 1 | DSCM = 0 | | 24 | | MHz |
| | | | | DSCM = 1 | | 32 | | MHz |
| | | f _{MX} = 4 MHz | DSFRDIV = 0 | DSCM = 0 | | 24 | | MHz |
| | | | | DSCM = 1 | | 32 | | MHz |
| Lockup wait time | | Time from when PLL output is enabled to when the phase is locked | | | 40 | | | μs |
| Interval wait time | | Time from when the PLL stops operating to when the setting to start PLL operation is specified | | | 4 | | | μs |
| Setup wait time | | Time required from when the PLL input clock stabilizes and the PLL setting is determined to when the PLL is activated | | | 1 | | | μs |

Note 1. When using a PLL, input a clock of 4 MHz or 8 MHz to the PLL.

Note 2. Be sure to specify one of these settings when using a PLL.

Note 3. When using the PLL output as the CPU clock, f_{IH} is divided by 2, 4, or 8 according to the setting of the RDIV1 and RDIV0 bits.

2.3 DC Characteristics

2.3.1 Pin characteristics

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(1/3)

| Item | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|--------|--|---|------|----------------------------|------|
| Output current, high ^{Note 1} | IOH1 | Per pin for P10 to P17 and P40 to P42 ^{Note 2} | -40°C < TA ≤ +85°C | | -10.0 ^{Note 3} | mA |
| | | | 85°C < TA ≤ 105°C | | -3.0 ^{Note 3} | mA |
| | | Total of P10 to P17, P41, and P42 ^{Note 2} (When duty ≤ 70% ^{Note 4}) | 4.0 V ≤ VDD ≤ 5.5 V -40°C < TA ≤ +85°C | | -80.0 | mA |
| | | | 4.0 V ≤ VDD ≤ 5.5 V 85°C < TA ≤ 105°C | | -30.0 | mA |
| | | | 2.7 V ≤ VDD < 4.0 V | | -19.0 | mA |
| | | | 2.4 V ≤ VDD < 2.7 V | | -10.0 | mA |
| | | | | | | |
| Output current, low ^{Note 1} | IOL1 | Per pin for P10 to P17 and P40 to P42 ^{Note 2} | -40°C < TA ≤ +85°C | | 20.0 ^{Note 3} | mA |
| | | | 85°C < TA ≤ 105°C | | 8.5 ^{Note 3} | mA |
| | | Total of P10 to P17, P41, and P42 ^{Note 2} (When duty ≤ 70% ^{Note 4}) | 4.0 V ≤ VDD ≤ 5.5 V -40°C < TA ≤ +85°C | | 80.0 | mA |
| | | | 4.0 V ≤ VDD ≤ 5.5 V 85°C < TA ≤ 105°C | | 40.0 | mA |
| | | | 2.7 V ≤ VDD < 4.0 V | | 35.0 | mA |
| | | | 2.4 V ≤ VDD < 2.7 V | | 20.0 | mA |
| | | | | | | |

Note 1. Value of current at which the device operation is guaranteed even if the current flows from the VDD pin to an output pin.

Note 2. This indicates the total current value when P16, P17, P41, and P42 are used as digital I/O ports. When using these pins as analog function (AFE) pins, refer to **2.1 Absolute Maximum Ratings**.

Note 3. Do not exceed the total current value.

Note 4. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IOH × 0.7)/(n × 0.01)

Example: n = 80% when IOH = -10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \approx -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

A current higher than the absolute maximum rating must not flow into one pin.

Caution P10 to P15 do not output high level in N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(2/3)

| Item | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|----------------------|--------|--------------------------------|---|-----------|------|---------|------|
| Input voltage, high | VIH1 | P10 to P17 and P40 to P42 | Normal input buffer | 0.8 VDD | | VDD | V |
| | VIH2 | P11, P12, P14, P15 | TTL input buffer, 4.0 V ≤ VDD ≤ 5.5 V | 2.2 | | VDD | V |
| | | | TTL input buffer, 3.3 V ≤ VDD < 4.0 V | 2.0 | | VDD | V |
| | | | TTL input buffer, 2.4 V ≤ VDD < 3.3 V | 1.5 | | VDD | V |
| | VIH3 | P121, P122, P137, EXCLK, RESET | | 0.8 VDD | | VDD | V |
| Input voltage, low | VIL1 | P10 to P17 and P40 to P42 | Normal input buffer | 0 | | 0.2 VDD | V |
| | VIL2 | P11, P12, P14, P15 | TTL input buffer, 4.0 V ≤ VDD ≤ 5.5 V | 0 | | 0.8 | V |
| | | | TTL input buffer, 3.3 V ≤ VDD < 4.0 V | 0 | | 0.5 | V |
| | | | TTL input buffer, 2.4 V ≤ VDD < 3.3 V | 0 | | 0.32 | V |
| | VIL3 | P121, P122, P137, EXCLK, RESET | | 0 | | 0.2 VDD | V |
| Output voltage, high | VOH1 | P10 to P17 and P40 to P42 | 4.0 V ≤ VDD ≤ 5.5 V, TA = -40 to +85°C, IOH1 = -10.0 mA | VDD - 1.5 | | | V |
| | | | 4.0 V ≤ VDD ≤ 5.5 V, 85°C < TA ≤ 105°C, IOH1 = -3.0 mA | VDD - 0.7 | | | V |
| | | | 2.7 V ≤ VDD ≤ 5.5 V, IOH1 = -2.0 mA | VDD - 0.6 | | | V |
| | | | 2.4 V ≤ VDD ≤ 5.5 V, IOH1 = -1.5 mA | VDD - 0.5 | | | V |
| Output voltage, low | VOL1 | P10 to P17 and P40 to P42 | 4.0 V ≤ VDD ≤ 5.5 V, TA = -40 to +85°C, IOL1 = 20.0 mA | | | 1.3 | V |
| | | | 4.0 V ≤ VDD ≤ 5.5 V, 85°C < TA ≤ 105°C, IOL1 = 8.5 mA | | | 0.7 | V |
| | | | 2.7 V ≤ VDD ≤ 5.5 V, IOL1 = 3.0 mA | | | 0.6 | V |
| | | | 2.7 V ≤ VDD ≤ 5.5 V, IOL1 = 1.5 mA | | | 0.4 | V |
| | | | 2.4 V ≤ VDD ≤ 5.5 V, IOL1 = 0.6 mA | | | 0.4 | V |

Caution The maximum VIH value on P10 to P15 is VDD, even in the N-ch open-drain mode.**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(3/3)

| Item | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-----------------------------|-------------------|---------------------------------|---|---|------|------|------|
| Input leakage current, high | ILI _{H1} | P10 to P17, and P40 to P42 | V _I = V _{DD} | | | 1 | μA |
| | ILI _{H2} | P137, $\overline{\text{RESET}}$ | V _I = V _{DD} | | | 1 | μA |
| | ILI _{H3} | P121, P122 (X1, X2, EXCLK) | V _I = V _{DD} | In input port mode or when using external clock input | | 1 | μA |
| | | | | When a resonator is connected | | 10 | μA |
| Input leakage current, low | ILI _{L1} | P10 to P17, and P40 to P42 | V _I = V _{SS} | | | -1 | μA |
| | ILI _{L2} | P137, $\overline{\text{RESET}}$ | V _I = V _{SS} | | | -1 | μA |
| | ILI _{L3} | P121, P122 (X1, X2, EXCLK) | V _I = V _{SS} | In input port mode or when using external clock input | | -1 | μA |
| | | | | When a resonator is connected | | -10 | μA |
| On-chip pull-up resistance | R _U | P10 to P15, P40 | V _I = V _{SS} , in input port mode | 10 | 20 | 100 | kΩ |

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

2.3.2 Supply current characteristics

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(1/2)

| Parameter | Symbol | Conditions | | | | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------|--------------------------|--|------------------|----------------------|------|------|------|------|
| Supply current Note 1 | IDD1 | Operating mode Note 2 | fHOCO = 32 MHz, fMAIN = 32 MHz Note 3 | Basic operation | VDD = 5.0 V | | 2.1 | | mA |
| | | | | | VDD = 3.0 V | | 2.1 | | |
| | | | fHOCO = 32 MHz, fMAIN = 32 MHz Note 3 | Normal operation | VDD = 5.0 V | | 4.8 | 8.7 | mA |
| | | | | | VDD = 3.0 V | | 4.8 | 8.7 | |
| | | | fHOCO = 24 MHz, fMAIN = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 3.8 | 6.7 | |
| | | | | | VDD = 3.0 V | | 3.8 | 6.7 | |
| | | | fHOCO = 16 MHz, fMAIN = 16 MHz Note 3 | Normal operation | VDD = 5.0 V | | 2.8 | 4.9 | |
| | | | | | VDD = 3.0 V | | 2.8 | 4.9 | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 4, VDD = 5.0 V | Normal operation | Square wave input | | 3.3 | 5.7 | mA |
| | | | | | Resonator connection | | 3.5 | 5.8 | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 4, VDD = 3.0 V | Normal operation | Square wave input | | 3.3 | 5.7 | |
| | | | | | Resonator connection | | 3.5 | 5.8 | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 4, VDD = 5.0 V | Normal operation | Square wave input | | 2.0 | 3.4 | |
| | | | | | Resonator connection | | 2.1 | 3.5 | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 4, VDD = 3.0 V | Normal operation | Square wave input | | 2.0 | 3.4 | |
| | | | | | Resonator connection | | 2.1 | 3.5 | |
| | | | fMX = 8 MHz, fMAIN = 32 MHz Note 5, VDD = 5.0 V | Normal operation | Square wave input | | 5.2 | 9.2 | mA |
| | | | | | Resonator connection | | 5.3 | 9.3 | |
| | | | fMX = 8 MHz, fMAIN = 32 MHz Note 5, VDD = 3.0 V | Normal operation | Square wave input | | 5.2 | 9.2 | |
| | | | | | Resonator connection | | 5.3 | 9.3 | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 5, VDD = 5.0 V | Normal operation | Square wave input | | 5.1 | 9.1 | |
| | | | | | Resonator connection | | 5.2 | 9.2 | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 5, VDD = 3.0 V | Normal operation | Square wave input | | 5.1 | 9.1 | |
| | | | | | Resonator connection | | 5.2 | 9.2 | |

Note 1. Total current flowing into VDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or VSS. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

Note 2. The relationship between the operation voltage range and the CPU operating frequency is as below.

2.7 V ≤ VDD ≤ 5.5 V @ 1 MHz to 32 MHz

2.4 V ≤ VDD ≤ 5.5 V @ 1 MHz to 16 MHz

Note 3. When the high-speed system clock is stopped

Note 4. When the high-speed on-chip oscillator and the PLL are stopped

Note 5. When the high-speed on-chip oscillator is stopped and the PLL is operating

Remark 1. fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. fHOCO: High-speed on-chip oscillator clock frequency

Remark 3. fMAIN: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is TA = 25°C

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(2/2)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit | | |
|--------------------------|----------------|---------------------|--|----------------------|------|------|-------|----|--|
| Supply current Note 1 | IDD2 Note 2 | HALT mode Note 3 | fHOCO = 32 MHz, fMAIN = 32 MHz Note 4 | VDD = 5.0 V | | 0.54 | 3.67 | mA | |
| | | | | VDD = 3.0 V | | 0.54 | 3.67 | | |
| | | | fHOCO = 24 MHz, fMAIN = 24 MHz Note 4 | VDD = 5.0 V | | 0.44 | 2.85 | | |
| | | | | VDD = 3.0 V | | 0.44 | 2.85 | | |
| | | | fHOCO = 16 MHz, fMAIN = 16 MHz Note 4 | VDD = 5.0 V | | 0.40 | 2.08 | | |
| | | | | VDD = 3.0 V | | 0.40 | 2.08 | | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 5, VDD = 5.0 V | Square wave input | | 0.28 | 2.45 | | |
| | | | | Resonator connection | | 0.49 | 2.57 | | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 5, VDD = 3.0 V | Square wave input | | 0.28 | 2.45 | | |
| | | | | Resonator connection | | 0.49 | 2.57 | | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 5, VDD = 5.0 V | Square wave input | | 0.19 | 1.28 | | |
| | | | | Resonator connection | | 0.30 | 1.36 | | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 5, VDD = 3.0 V | Square wave input | | 0.19 | 1.28 | | |
| | | | | Resonator connection | | 0.30 | 1.36 | | |
| | | | fMX = 8 MHz, fMAIN = 32 MHz Note 6, VDD = 5.0 V | Square wave input | | 0.91 | 4.17 | | |
| | | | | Resonator connection | | 1.01 | 4.27 | | |
| | | | fMX = 8 MHz, fMAIN = 32 MHz Note 6, VDD = 3.0 V | Square wave input | | 0.91 | 4.17 | | |
| | | | | Resonator connection | | 1.01 | 4.27 | | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 6, VDD = 5.0 V | Square wave input | | 0.76 | 3.27 | | |
| | | | | Resonator connection | | 0.86 | 3.37 | | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 6, VDD = 3.0 V | Square wave input | | 0.76 | 3.27 | | |
| | | | | Resonator connection | | 0.86 | 3.37 | | |
| | IDD3 Note 7 | STOP mode | TA = -40°C | | | 0.38 | 1.14 | μA | |
| | | | TA = +25°C | | | 0.50 | 1.14 | | |
| | | | TA = +50°C | | | 0.66 | 4.52 | | |
| | | | TA = +70°C | | | 1.04 | 7.98 | | |
| | | | TA = +85°C | | | 2.92 | 16.0 | | |
| | | | TA = +105°C | | | 11.0 | 100.0 | | |

Note 1. Total current flowing into VDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or VSS. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during writing to the data flash.

Note 2. During HALT instruction execution from flash memory

Note 3. The relationship between the operation voltage range and the CPU operating frequency is as below.

2.7 V ≤ VDD ≤ 5.5 V @ 1 MHz to 32 MHz

2.4 V ≤ VDD ≤ 5.5 V @ 1 MHz to 16 MHz

Note 4. When the high-speed system clock is stopped

Note 5. When the high-speed on-chip oscillator and the PLL are stopped

Note 6. When high-speed on-chip oscillator is stopped and the PLL is operating

Note 7. The MAX. value includes the leakage current in STOP mode.

Remark 1. fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. fHOCO: High-speed on-chip oscillator clock frequency

Remark 3. fMAIN: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is TA = 25°C, except the operation in STOP mode.

• Peripheral functions

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|--------------------|------------------------------------|---|------|------|-------|------|
| Low-speed on-chip oscillator operating current | IFIL Note 1 | | | | 0.20 | | μA |
| RTC operating current | IRTC Notes 1, 2, 3 | fMX = 4 MHz, RTCCL = 00H (fMX/122) | | | 22 | | μA |
| Interval timer operating current | IIIT Notes 1, 2, 4 | fMX = 4 MHz, RTCCL = 00H (fMX/122) | | | 22 | | μA |
| Watchdog timer operating current | IWDT Notes 1, 5, 6 | fIL = 15 kHz | | | 0.22 | | μA |
| LVD operating current | ILVD Notes 1, 7 | | | | 0.08 | | μA |
| Self-programming operating current | IFSP Notes 1, 8 | | | | 2.50 | 12.20 | mA |
| BGO operating current | IBGO Notes 1, 9 | | | | 2.50 | 12.20 | mA |
| SNOOZE operating current | ISNOZ Note 1 | A/D converter operationNotes 10, | The mode is performed | | 0.50 | 1.10 | mA |
| | | | During A/D conversion, AVDD = VDD = 3.0 V | | 1.20 | 2.04 | |
| | | Simplified SPI(CSI)/UART operation | | | 0.70 | 1.54 | |
| | | DTC operation | | | 3.10 | | |

Note 1. Current flowing to VDD

Note 2. When the high-speed on-chip oscillator is stopped

Note 3. Current flowing only to the real-time clock (RTC). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock is operating in operation mode or HALT mode.

Note 4. Current flowing only to the interval timer. The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIIT, when the interval timer is operating in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, also add IFIL.

Note 5. When the high-speed on-chip oscillator and high-speed system clock are stopped.

Note 6. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and IWDT when the watchdog timer is operating.

Note 7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and ILVD when the LVD circuit is operating.

Note 8. Current flowing during self-programming

Note 9. Current flowing during writing to the data flash

Note 10. The current flowing into the AVDD is included.

Remark 1. fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. fIL: Low-speed on-chip oscillator clock frequency

Remark 3. The temperature condition for the TYP. value is TA = 25°C

• AFE functions

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------|---|------|------|------|------|
| 24-bit ΔΣ A/D converter operating current | IDSAD | Normal mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS IOUT = 0 mA | | 0.94 | 1.46 | mA |
| | | Low power mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS IOUT = 0 mA | | 0.60 | 0.91 | mA |
| 10-bit A/D converter operating current | IADC | During conversion at the highest speed Notes 1, 2 AVDD = 5.0 V | | 1.30 | 1.70 | mA |
| Configurable amplifier operating current | IAMP | Normal mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier IL = 0 mA Per channel | | 0.13 | 0.24 | mA |
| | | High-speed mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier IL = 0 mA Per channel | | 0.30 | 0.45 | mA |
| 12-bit D/A converter operating current | IDAC | When AVDD is selected as the reference voltage Notes 1, 2 Circuits that operate: ABGR and internal reference voltage (VREFDA) | | 0.61 | 0.97 | mA |

Note 1. Current flowing to AVDD**Note 2.** Current flowing only to the circuits that operate shown in the Conditions column.

2.4 AC Characteristics

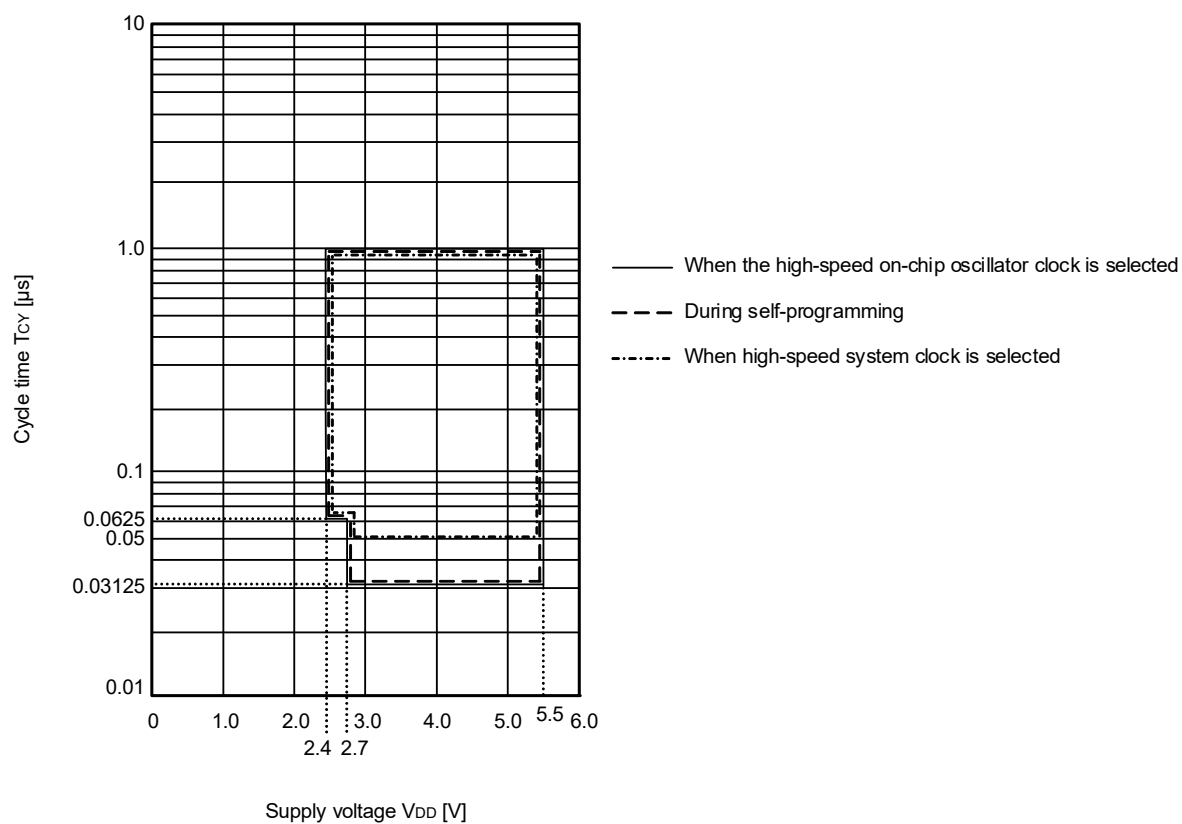
(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Items | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|-------------------|-------------------------------------|---------------------|-------------|------|------|------|
| Instruction cycle (minimum instruction execution time) | Tcy | Main system clock (fMAIN) operation | 2.7 V ≤ VDD ≤ 5.5 V | 0.03125 | | 1 | μs |
| | | | 2.4 V ≤ VDD < 2.7 V | 0.0625 | | 1 | μs |
| | | In the self-programming mode | 2.7 V ≤ VDD ≤ 5.5 V | 0.03125 | | 1 | μs |
| | | | 2.4 V ≤ VDD < 2.7 V | 0.0625 | | 1 | μs |
| External system clock frequency | fEX | 2.7 V ≤ VDD ≤ 5.5 V | | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | | 1.0 | | 16.0 | MHz |
| External system clock input high-level width, low-level width | tEXH, tEXL | 2.7 V ≤ VDD ≤ 5.5 V | | 24 | | | ns |
| | | 2.4 V ≤ VDD < 2.7 V | | 30 | | | ns |
| TI00 to TI03, TI10, TI11 input high-level width, low-level width | tTIIH, tTIL | | | 1/fMCK + 10 | | | ns |
| Timer RJ input cycle | fc | TRJIO0 | 2.7 V ≤ VDD ≤ 5.5 V | 100 | | | ns |
| | | | 2.4 V ≤ VDD < 2.7 V | 300 | | | ns |
| Timer RJ input high- level width, low-level width | tTJIH, tTJIL | TRJIO0 | 2.7 V ≤ VDD ≤ 5.5 V | 40 | | | ns |
| | | | 2.4 V ≤ VDD < 2.7 V | 120 | | | ns |
| Timer RG input high- level width, low-level width | tTRGIH, tTRGIL | TRGIOA, TRGIOB | | 2.5/fCLK | | | ns |
| TO00 to TO03, TO10, TO11, TRJIO0, TRJO0, TRGIOA, TRGIOB output frequency | fTO | | 4.0 V ≤ VDD ≤ 5.5 V | | | 16 | MHz |
| | | | 2.7 V ≤ VDD ≤ 4.0 V | | | 8 | MHz |
| | | | 2.4 V ≤ VDD < 2.7 V | | | 4 | MHz |
| PCLBUZ0 output frequency | fPCL | | 4.0 V ≤ VDD ≤ 5.5 V | | | 16 | MHz |
| | | | 2.7 V ≤ VDD ≤ 4.0 V | | | 8 | MHz |
| | | | 2.4 V ≤ VDD < 2.7 V | | | 4 | MHz |
| Interrupt input high- level width, low-level width | tINTH, tINTL | INTP1 to INTP7 | | 1 | | | μs |
| RESET low-level width | tRSL | | | 10 | | | μs |

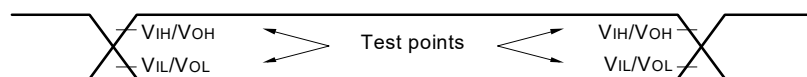
Remark fMCK: Timer array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3))

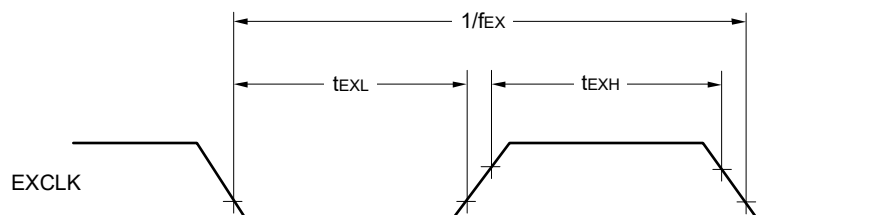
Minimum Instruction Execution Time During Main System Clock Operation

T_{CY} vs V_{DD}

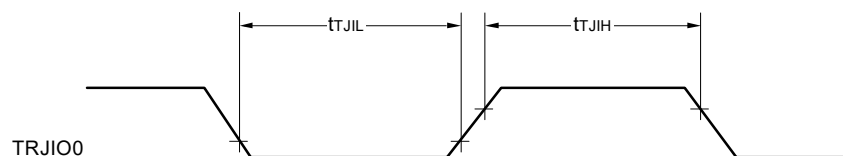
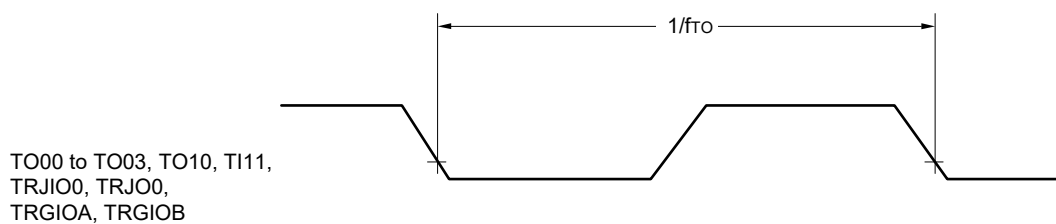
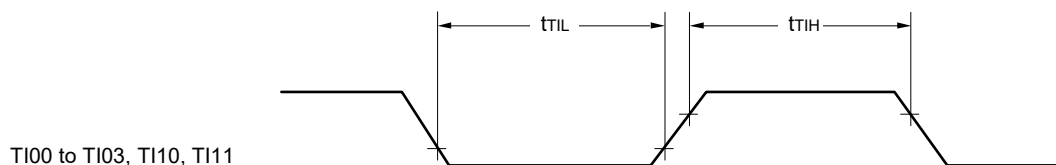
AC Timing Test Points

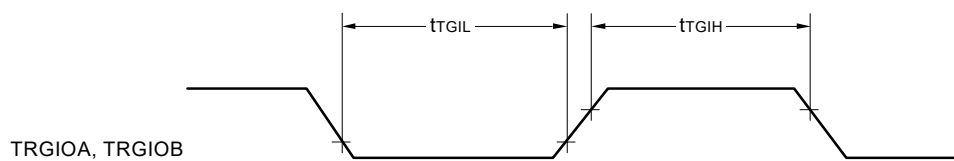


External System Clock Timing

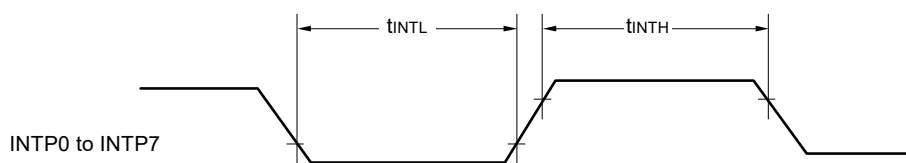
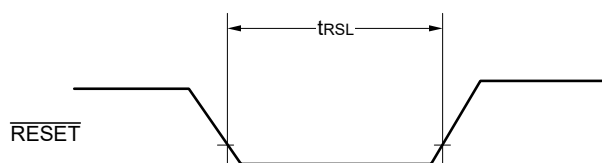


TI/TO Timing



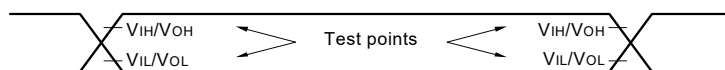


Interrupt Request Input Timing

 $\overline{\text{RESET}}$ Input Timing

2.5 Peripheral Functions Characteristics

AC Timing Test Points



2.5.1 Serial array unit

(1) During communication at same potential (UART mode)

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | HS (high-speed main) Mode | | Unit |
|----------------------|--------|--|---------------------------|---------|------|
| | | | MIN. | MAX. | |
| Transfer rate Note 1 | | | | fMCK/12 | bps |
| | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | | 2.6 | Mbps |

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

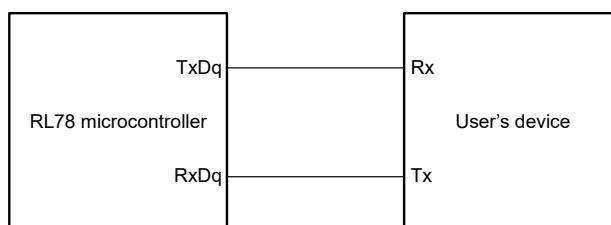
Note 2. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

32 MHz (2.7 V ≤ VDD ≤ 5.5 V)

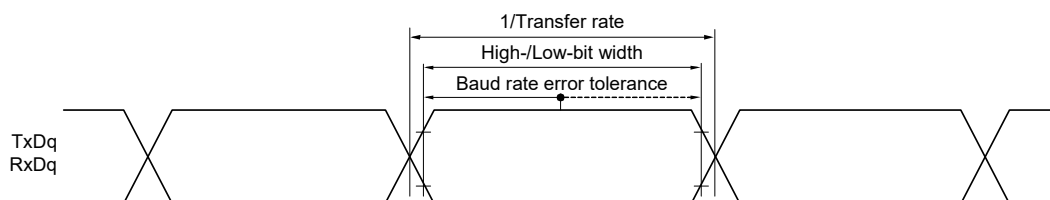
16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

UART mode connection diagram (during communication at same potential)



UART mode bit width (during communication at same potential) (reference)



Remark 1. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 2. fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03))

(2) During communication at same potential (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|--|-------------------------------------|--|---------------------------|------|------|
| | | | MIN. | MAX. | |
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} 2.7 V ≤ V _{DD} ≤ 5.5 V 2.4 V ≤ V _{DD} ≤ 5.5 V | 250 | | ns |
| | | | 500 | | ns |
| SCKp high-/low-level width | t _{KH1} , t _{KL1} | 4.0 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 24 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 36 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 76 | | ns |
| Slp setup time (to SCKp↑) Note 1 | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V | 66 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 66 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 113 | | ns |
| Slp hold time (from SCKp↑) Note 1 | t _{SIH1} | | 38 | | ns |
| Delay time from SCKp↓ to SOp output Note 2 | t _{KSO1} | C = 30 pF Note 3 | | 50 | ns |

Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)

Remark 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

(3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|--|-------------------------------------|---------------------------------|---------------------------------|------------------------------|--------------------------|------|
| | | | | MIN. | MAX. | |
| SCKp cycle time Note 1 | t _{KCY2} | 4.0 V ≤ V _{DD} ≤ 5.5 V | 20 MHz < f _{MCK} | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 20 MHz | 12/f _{MCK} | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 16 MHz < f _{MCK} | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 16 MHz | 12/f _{MCK} | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | 12/f _{MCK} and 1000 | | ns |
| SCKp high-/low-level width | t _{KH2} , t _{KL2} | 4.0 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 14 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 16 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 36 | | ns |
| Slp setup time (to SCKp↑) Note 2 | t _{SIK2} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1/f _{MCK} + 40 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | 1/f _{MCK} + 60 | | ns |
| Slp hold time (from SCKp↑) Note 2 | t _{KSJ2} | | | 1/f _{MCK} + 62 | | ns |
| Delay time from SCKp↓ to SOp output Note 3 | t _{KSO2} | C = 30 pF Note 4 | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 2/f _{MCK} + 66 | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | 2/f _{MCK} + 113 | ns |
| SSI00 setup time | t _{SSIK} | DAPmn = 0 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 400 | | ns |
| | | DAPmn = 1 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 400 | | ns |
| SSI00 hold time | t _{KSSI} | DAPmn = 0 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 400 | | ns |
| | | DAPmn = 1 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 400 | | ns |

Note 1. The maximum transfer rate in the SNOOZE mode is 1 Mbps.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

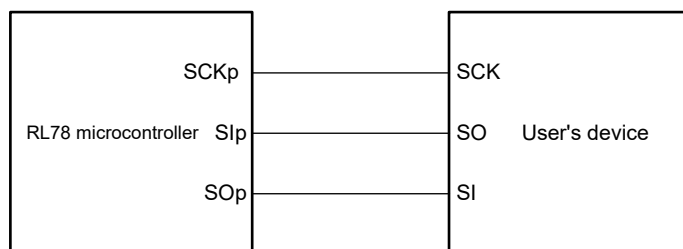
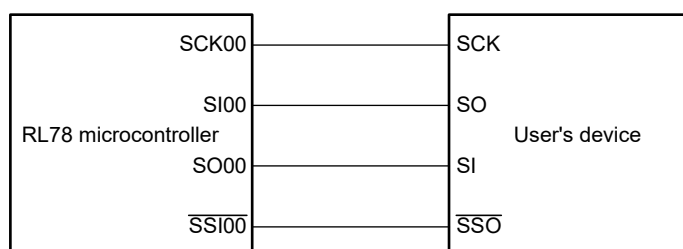
Note 3. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 4. C is the load capacitance of the SOp output lines.

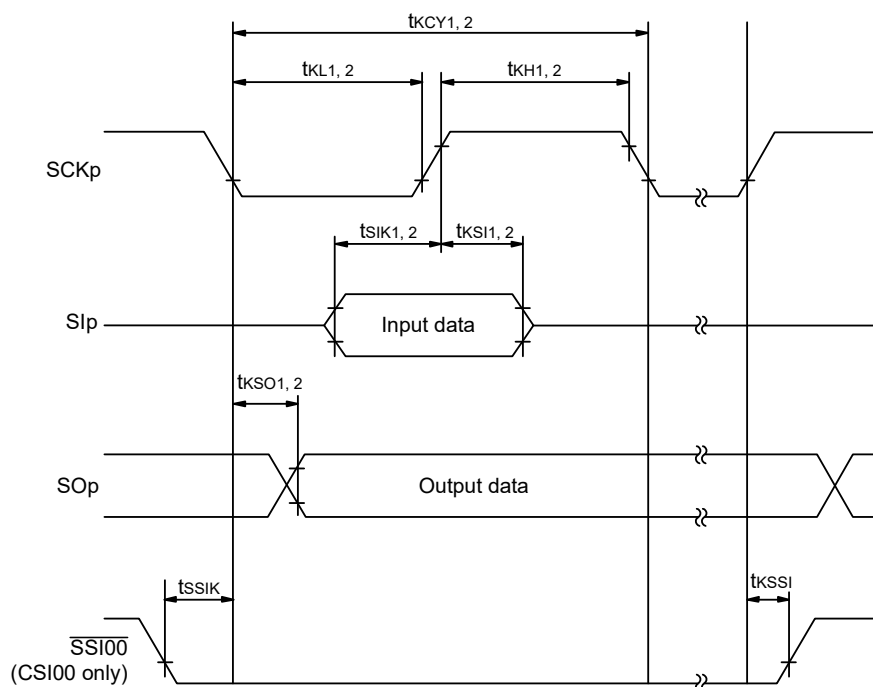
Caution Select the normal input buffer for the Slp and SCKp pins and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)

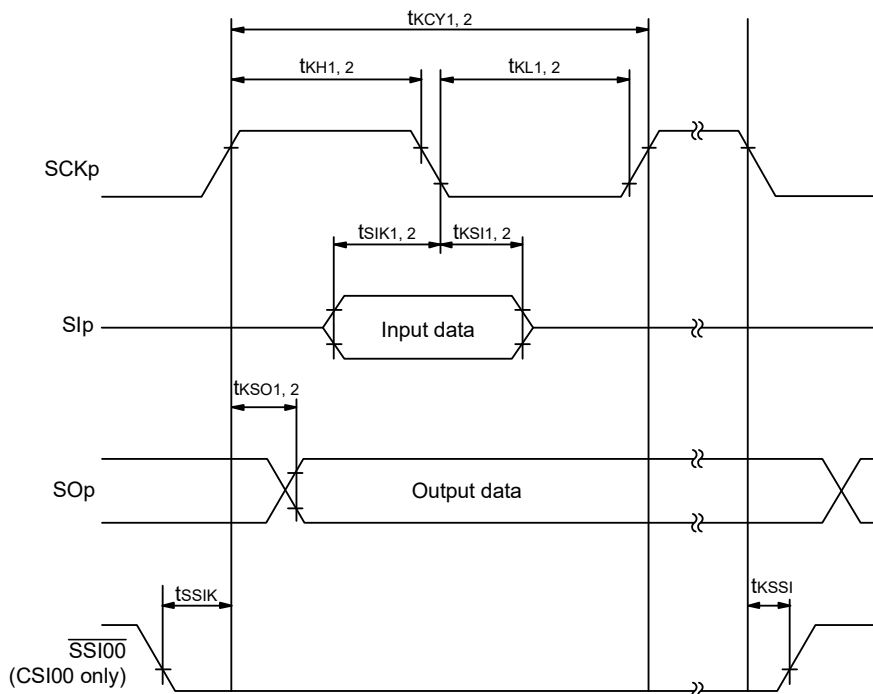
Remark 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

Simplified SPI(CSI) mode connection diagram (during communication at same potential)**Simplified SPI(CSI) mode connection diagram (during communication at same potential)
(Slave Transmission of slave select input function (CSI00))****Remark 1.** p: Simplified SPI(CSI) number (p = 00, 01)**Remark 2.** m: Unit number, n: Channel number (mn = 00, 01)

Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number (p = 00, 01)

Remark 2. m: Unit number, n: Channel number (mn = 00, 01)

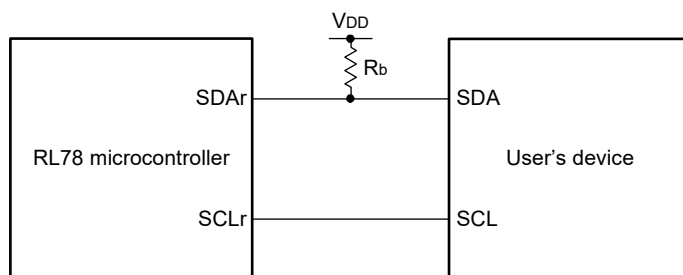
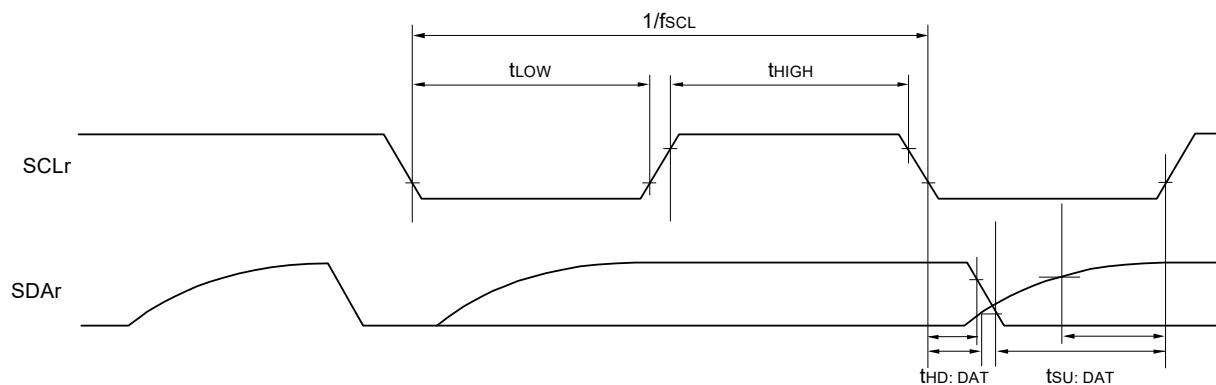
(4) During communication at same potential (simplified I²C mode)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|-------------------------------|----------------------|---|------------------------------------|------------|------|
| | | | MIN. | MAX. | |
| SCLr clock frequency | f _{SCL} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | | 400 Note 1 | kHz |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | | 100 Note 1 | kHz |
| Hold time when SCLr = "L" | t _{LOW} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 4600 | | ns |
| Hold time when SCLr = "H" | t _{HIGH} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 4600 | | ns |
| Data setup time (reception) | t _{SU: DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 220 Note 2 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 1/f _{MCK} + 580 Note 2 | | ns |
| Data hold time (transmission) | t _{HD: DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 770 | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 0 | 1420 | ns |

Note 1. The value must also be equal to or less than f_{MCK}/4.**Note 2.** Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the normal input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

Simplified I²C mode connection diagram (during communication at same potential)**Simplified I²C mode serial transfer timing (during communication at same potential)**

Remark 1. R_b [Ω]: Communication line (SDAr) pull-up resistance, C_b [F]: Communication line (SDAr, SCLr) load capacitance

Remark 2. r: IIC number (r = 00, 01), g: PIM number (g = 1), h: POM number (h = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0),

n: Channel number (n = 0, 1), mn = 00, 01)

(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(1/2)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|---------------|--------|------------|--|----------------|------|
| | | | MIN. | MAX. | |
| Transfer rate | | Reception | 4.0 V ≤ VDD ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V | fMCK/12 Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | 2.6 | Mbps |
| | | | 2.7 V ≤ VDD < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V | fMCK/12 Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | 2.6 | Mbps |
| | | | 2.4 V ≤ VDD < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V | fMCK/12 Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | 2.6 | Mbps |

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.**Note 2.** The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

32 MHz (2.7 V ≤ VDD ≤ 5.5 V)

16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

Remark 1. Vb [V]: Communication line voltage**Remark 2.** q: UART number (q = 0, 1), g: PIM or POM number (g = 1)**Remark 3.** fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00, 01)

(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(2/2)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|---------------|--------|--------------|---|---------------------------|-------------|------|
| | | | | MIN. | MAX. | |
| Transfer rate | | Transmission | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 1.4 kΩ, V _b = 2.7 V | | 2.6 Note 2 | Mbps |
| | | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | Note 3 | bps |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 2.7 kΩ, V _b = 2.3 V | | 1.2 Note 4 | Mbps |
| | | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | | Note 5 | bps |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 5.5 kΩ, V _b = 1.6 V | | 0.43 Note 6 | Mbps |

Note 1. The smaller maximum transfer rate derived by using fmck/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ VDD ≤ 5.5 V and 2.7 V ≤ Vb ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 2. This value as an example is calculated when the conditions described in the "Conditions" column are met.

Refer to **Note 1** above to calculate the maximum transfer rate under conditions of the customer.

Note 3. The smaller maximum transfer rate derived by using fmck/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ VDD < 4.0 V and 2.3 V ≤ Vb ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 4. This value as an example is calculated when the conditions described in the "Conditions" column are met.

Refer to **Note 3** above to calculate the maximum transfer rate under conditions of the customer.

Note 5. The smaller maximum transfer rate derived by using $f_{MCK}/12$ or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when $2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ and $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

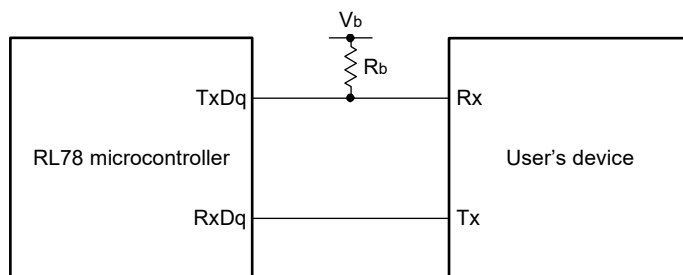
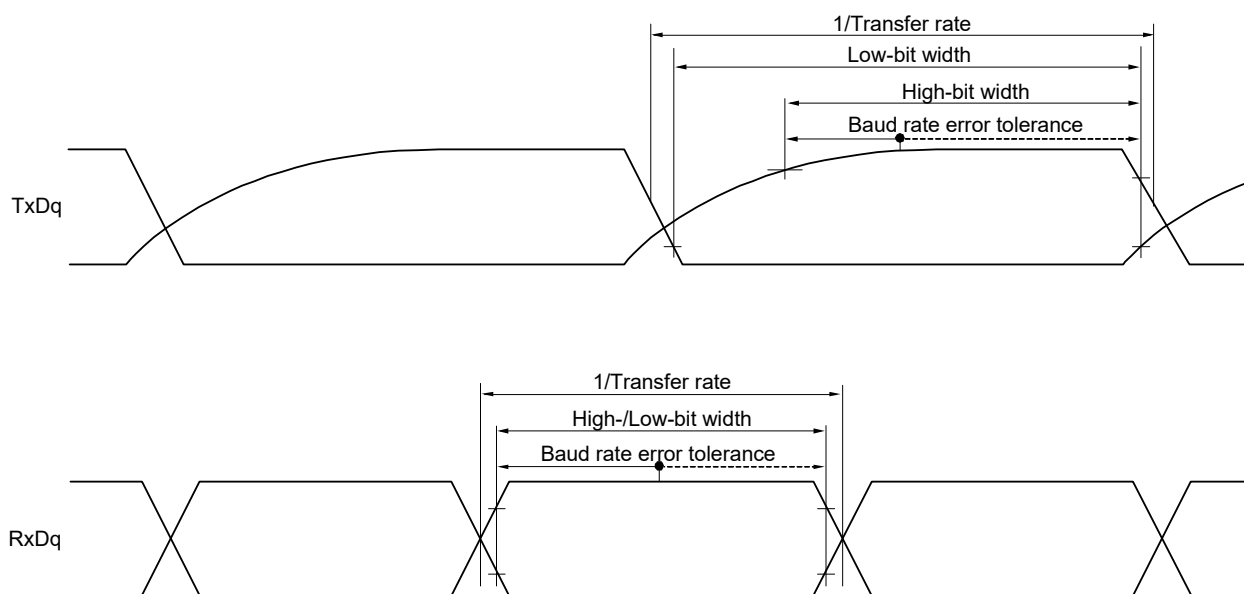
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 6. This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 5** above to calculate the maximum transfer rate under conditions of the customer.

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL} , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

UART mode connection diagram (during communication at different potential)**UART mode bit width (during communication at different potential) (reference)**

Remark 1. R_b [Ω]: Communication line (TxDq) pull-up resistance,
 C_b [F]: Communication line (TxDq) load capacitance, V_b [V]: Communication line voltage

Remark 2. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
 m: Unit number, n: Channel number (mn = 00, 01))

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(1/3)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|-----------------------|-------------------|--|----------------------------|------|------|
| | | | MIN. | MAX. | |
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 600 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 1000 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 2300 | | ns |
| SCKp high-level width | t _{KH1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 150 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 340 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | t _{KCY1} /2 - 916 | | ns |
| SCKp low-level width | t _{KL1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 24 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 36 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | t _{KCY1} /2 - 100 | | ns |

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(2/3)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|--|-------------------|--|---------------------------|------|------|
| | | | MIN. | MAX. | |
| Slp setup time (to SCKp↑) Note | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 162 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 354 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 958 | | ns |
| Slp hold time (from SCKp↑) Note | t _{KSI1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 38 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 38 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 38 | | ns |
| Delay time from SCKp↓ to SOp output Note | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | 200 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | 390 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | | 966 | ns |

Note When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

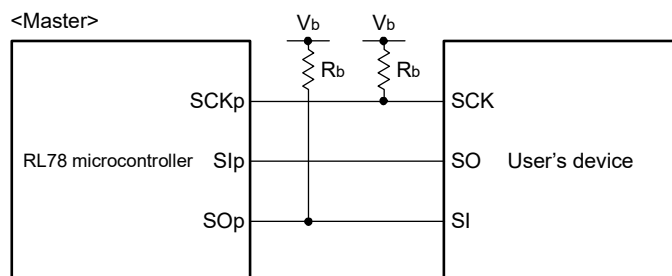
(Remarks are listed on the page after the next page.)

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(3/3)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|--|-------------------|--|---------------------------|------|------|
| | | | MIN. | MAX. | |
| Slp setup time (to SCKp↓) Note | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 88 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 88 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 220 | | ns |
| Slp hold time (from SCKp↓) Note | t _{KS1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 38 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 38 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 38 | | ns |
| Delay time from SCKp↑ to SOp output Note | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | 50 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | 50 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | | 50 | ns |

Note When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

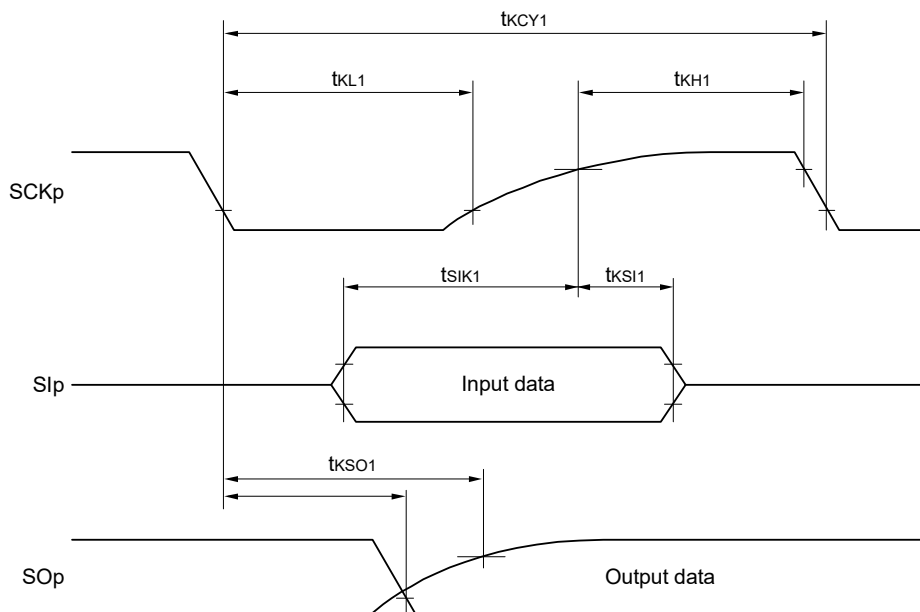
Simplified SPI(CSI) mode connection diagram (during communication at different potential

Remark 1. R_b [Ω]: Communication line (SCKp, SOp) pull-up resistance, C_b [F]: Communication line (SCKp, SOp) load capacitance, V_b [V]: Communication line voltage

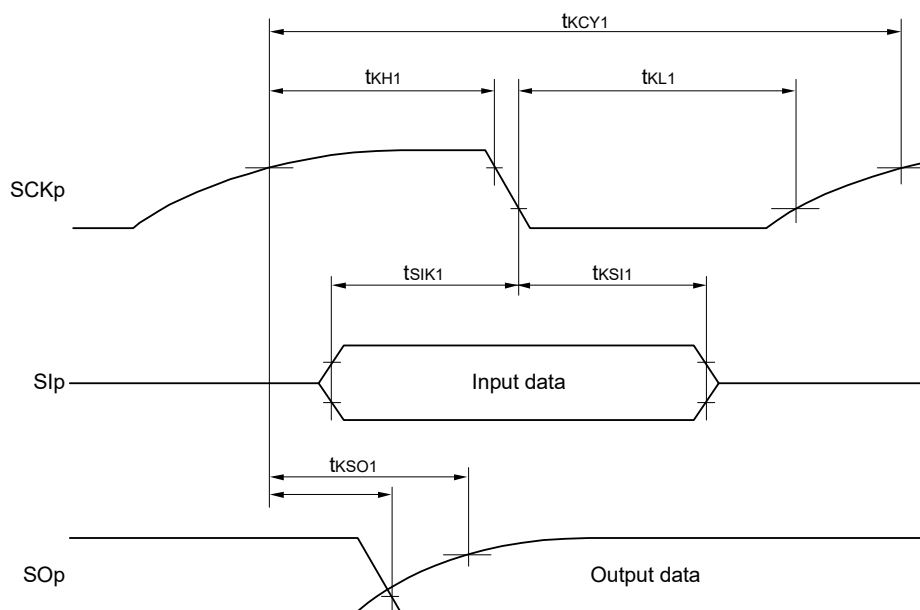
Remark 2. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

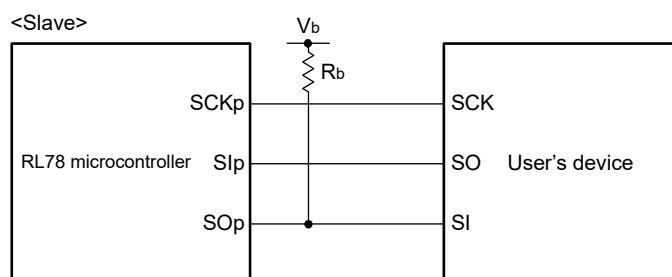
(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|---|-------------------------------------|---|------------------------------------|----------------------------|---------------------------|------|
| | | | | MIN. | MAX. | |
| SCKp cycle time ^{Note 1} | t _{KCY2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | 24 MHz < f _{MCK} | 28/f _{MCK} | | ns |
| | | | 20 MHz < f _{MCK} ≤ 24 MHz | 24/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 20 MHz | 20/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 4 MHz | 12/f _{MCK} | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | 24 MHz < f _{MCK} | 40/f _{MCK} | | ns |
| | | | 20 MHz < f _{MCK} ≤ 24 MHz | 32/f _{MCK} | | ns |
| | | | 16 MHz < f _{MCK} ≤ 20 MHz | 28/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 16 MHz | 24/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 4 MHz | 12/f _{MCK} | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | 24 MHz < f _{MCK} | 96/f _{MCK} | | ns |
| | | | 20 MHz < f _{MCK} ≤ 24 MHz | 72/f _{MCK} | | ns |
| | | | 16 MHz < f _{MCK} ≤ 20 MHz | 64/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 16 MHz | 52/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 32/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 4 MHz | 20/f _{MCK} | | ns |
| SCKp high-/low-level width | t _{KH2} , t _{KL2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | t _{KCY2} /2 - 24 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | t _{KCY2} /2 - 36 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | | t _{KCY2} /2 - 100 | | ns |
| Slp setup time (to SCKp↑) ^{Note 2} | t _{SIK2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | 1/f _{MCK} + 40 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | 1/f _{MCK} + 40 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | | 1/f _{MCK} + 60 | | ns |
| Slp hold time (from SCKp↑) ^{Note 2} | t _{KS2} | | | 1/f _{MCK} + 62 | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 3} | t _{KSO2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | | 2/f _{MCK} + 240 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | | 2/f _{MCK} + 428 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | | | 2/f _{MCK} + 1146 | ns |

(Notes, Cautions, and Remarks are listed on the next page.)

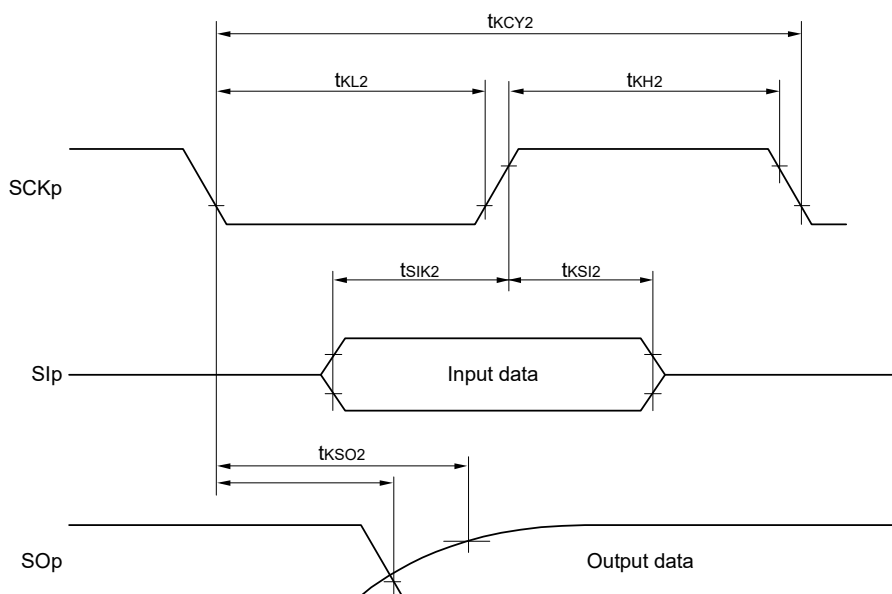
- Note 1.** Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Caution** Select the TTL input buffer for the SIp and SCKp pins, and the N-ch open drain output (VDD tolerance) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

Simplified SPI(CSI) mode connection diagram (during communication at different potential)

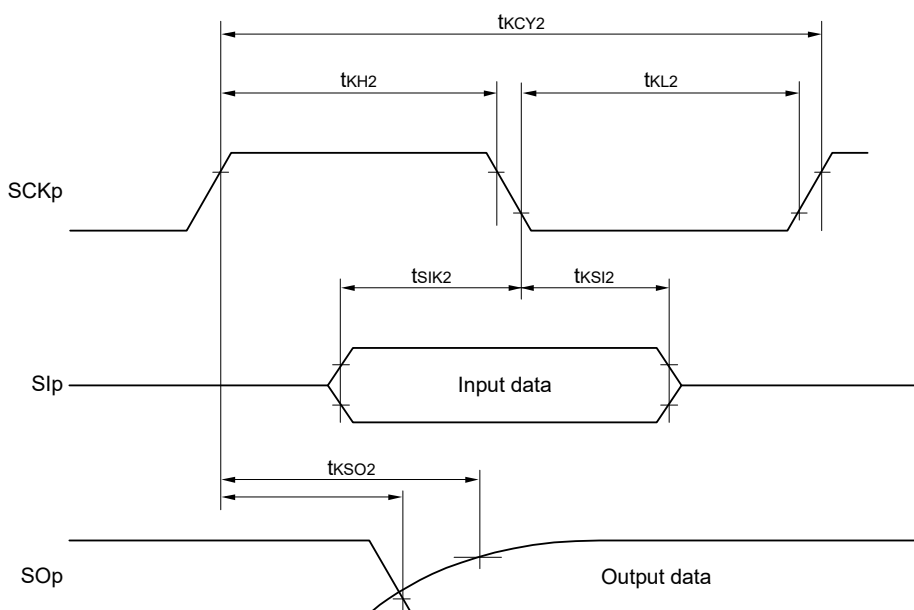


- Remark 1.** Rb [Ω]: Communication line (SOp) pull-up resistance, Cb [F]: Communication line (SOp) load capacitance, Vb [V]: Communication line voltage
- Remark 2.** p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)
- Remark 3.** fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00, 01))
- Remark 4.** Communication at different potential cannot be performed during clocked serial communication with the slave select function.

Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

Remark 2. Communication at different potential cannot be performed during clocked serial communication with the slave select function.

(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(1/2)

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|---------------------------|-------------------|---|---------------------------|------------|------|
| | | | MIN. | MAX. | |
| SCLr clock frequency | f _{SCL} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | | 400 Note 1 | kHz |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | | 400 Note 1 | kHz |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | | 100 Note 1 | kHz |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | | 100 Note 1 | kHz |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | | 100 Note 1 | kHz |
| Hold time when SCLr = "L" | t _{LOW} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 4600 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 4600 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 4600 | | ns |
| Hold time when SCLr = "H" | t _{HIGH} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 620 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 500 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 2700 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 2400 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 1830 | | ns |

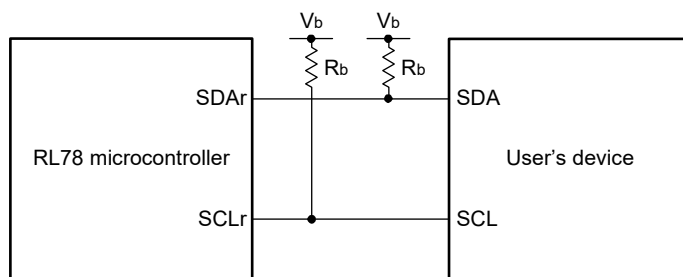
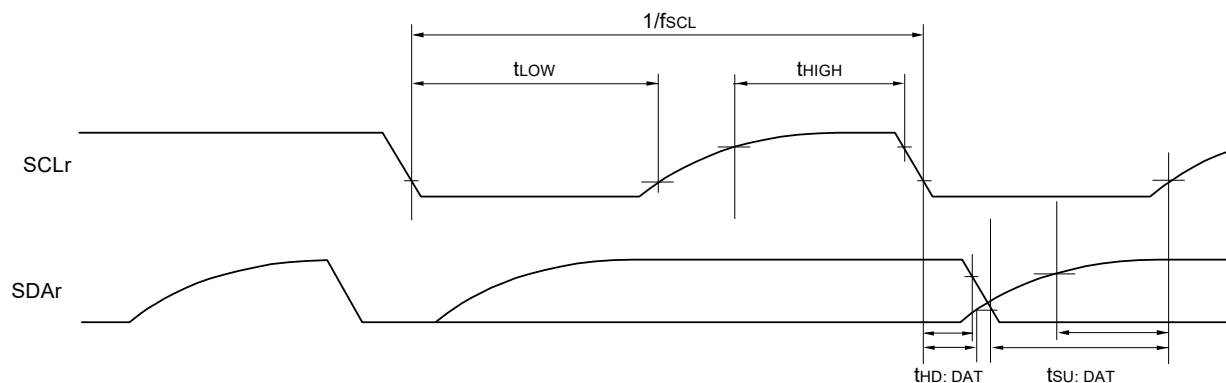
(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)**(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(2/2)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|-------------------------------|---------------------|---|---------------------------------|------|------|
| | | | MIN. | MAX. | |
| Data setup time (reception) | t _{SU:DAT} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 340 Note 2 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 340 Note 2 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 1/f _{MCK} + 760 Note 2 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 760 Note 2 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 1/f _{MCK} + 570 Note 2 | | ns |
| Data hold time (transmission) | t _{HD:DAT} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 770 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 770 | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 0 | 1420 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 0 | 1420 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 0 | 1215 | ns |

Note 1. The value must also be equal to or less than f_{MCK}/4.**Note 2.** Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the TTL input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the N-ch open drain output (V_{DD} tolerance) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

Simplified I²C mode connection diagram (during communication at different potential)**Simplified I²C mode serial transfer timing (during communication at different potential)**

Remark 1. R_b [Ω]: Communication line (SDAr, SCLr) pull-up resistance, C_b [F]: Communication line (SDAr, SCLr) load capacitance, V_b [V]: Communication line voltage

Remark 2. r: IIC number (r = 00, 01), g: PIM, POM number (g = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0), n: Channel number (n = 0), mn = 00, 01)

2.6 Analog Characteristics

2.6.1 Programmable gain instrumentation amplifier and 24-bit $\Delta\Sigma$ A/D converter

(1) Analog input in differential input mode

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---------------------|--|--|---------------------------|--|------|
| Full-scale differential input voltage range | V _{ID} | V _{ID} = (PGAxP - PGAxN) (x = 0 to 3) | | ± 800 /G _{TOTAL} | | mV |
| Input voltage range | V _I | Each of PGAxP and PGAxN pins (x = 0 to 3) | 0.2 | | 1.8 | V |
| Common mode input voltage | V _{COM} | doFR = 0 mV | 0.2+(V _{ID} x G _{SET1})/2 | | 1.8-(V _{ID} x G _{SET1})/2 | V |
| Input bias current | I _{IN} | V _I = 1.0 V | | | ±50 | nA |
| Input offset current | I _{INOFFR} | V _I = 1.0 V | | | ±20 | nA |

(2) Analog input in single-ended input mode

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------|-----------------|---|------|------|------|------|
| Input voltage range | V _I | Each of PGAxP and PGAxN pins (x = 0 to 3) G _{SET1} = 1, G _{SET2} = 1 | 0.2 | | 1.8 | V |
| Input bias current | I _{IN} | V _I = 1.0 V | | | ±50 | nA |

(3) Programmable gain instrumentation amplifier and 24-bit $\Delta\Sigma$ A/D converter

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used, in differential input mode) (1/2)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------|--------------------|--|------------------------|----------------------|------------------------|------|
| Resolution | RES | | | | 24 | bit |
| Sampling frequency | fs1 | Normal mode | | 1 | | MHz |
| | fs2 | Low power mode | | 0.125 | | MHz |
| Output data rate | f _{DATA1} | Normal mode | 0.48828 | | 15.625 | ksps |
| | f _{DATA2} | Low power mode | 61.03615 | | 1953.125 | sps |
| Gain setting range | G _{TOTAL} | G _{TOTAL} = G _{SET1} × G _{SET2} | 1 | | 64 | V/V |
| 1st gain setting range | G _{SET1} | In differential input mode only | | 1, 2, 3, 4, 8 | | V/V |
| 2nd gain setting range | G _{SET2} | In differential input mode only | | 1, 2, 4, 8 | | V/V |
| Offset adjustment bit range | doFFB | | | 5 | | bit |
| Offset adjustment range | doFR | Referred to input | -164/G _{SET1} | | +164/G _{SET1} | mV |
| Offset adjustment steps | doFS | Referred to input | | 11/G _{SET1} | | mV |

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used, in differential input mode) (2/2)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|--------|--|------|---------|---------|--------|
| Gain error | EG | TA = 25°C GSET1 = 1, GSET2 = 1 Excluding SBIAS error | | ±0.2 | ±2.7 | % |
| | | TA = 25°C GSET1 = 8, GSET2 = 4 Excluding SBIAS error | | ±0.1 | | % |
| Gain drift ^{Note} | dEG | GSET1 = 1, GSET2 = 1 Excluding SBIAS drift | | (5.6) | (22.0) | ppm/°C |
| | | GSET1 = 8, GSET2 = 4 Excluding SBIAS drift | | (9.1) | | ppm/°C |
| Offset error | Eos | TA = 25°C GSET1 = 1, GSET2 = 1 Referred to input | | ±0.32 | ±2.90 | mV |
| | | TA = 25°C GSET1 = 8, GSET2 = 4 Referred to input | | ±0.03 | | mV |
| Offset drift ^{Note} | dEos | GSET1 = 1, GSET2 = 1 Referred to input | | (±0.02) | (±6.00) | μV/°C |
| | | GSET1 = 8, GSET2 = 4 Referred to input | | (±0.02) | | μV/°C |
| SND ratio | SNDR | GSET1 = 1, GSET2 = 1, fin = 50 Hz Normal mode, pin = -1 dBFS | (82) | (85) | | dB |
| | | GSET1 = 8, GSET2 = 4, fin = 50 Hz Normal mode, pin = -1 dBFS | (73) | (80) | | dB |
| Noise | Vn | GSET1 = 1, GSET2 = 1, OSR = 2048 | | (13) | | μVRms |
| | | GSET1 = 8, GSET2 = 4, OSR = 2048 | | (0.6) | | μVRms |
| Integral non-linearity error | INL | GSET1 = 1, GSET2 = 1, OSR = 2048 | | (±10) | | ppmFS |
| Common mode rejection ratio | CMRR | VCOM = 1.0±0.8 V, fin = 50 Hz GSET1 = 1, GSET2 = 1 Differential input mode | (72) | (90) | | dB |
| Power supply rejection ratio | PSRR | AVDD = 2.7 to 5.5 V GSET1 = 1, GSET2 = 1 Differential input mode | | (85) | | dB |
| ΔΣ A/D converter input clock frequency | fADC | | 3.8 | 4 | 4.2 | MHz |

Note Calculate the gain drift and offset drift by using the following expression (for 105°C products):
 For gain drift: (MAX(EG(T(-40) to T(105))) - MIN(EG(T(-40) to T(105)))) / (105°C - (-40°C))
 For offset drift: (MAX(Eos(T(-40) to T(105))) - MIN(Eos(T(-40) to T(105)))) / (105°C - (-40°C))
 MAX(EG(T(-40) to T(105))): The maximum value of gain error when the temperature range is -40°C to 105°C
 MIN(EG(T(-40) to T(105))): The minimum value of gain error when the temperature range is -40°C to 105°C
 MAX(Eos(T(-40) to T(105))): The maximum value of offset error when the temperature range is -40°C to 105°C
 MIN(Eos(T(-40) to T(105))): The minimum value of offset error when the temperature range is -40°C to 105°C

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

2.6.2 Sensor power supply (SBIAS)

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, COUT = 0.22 μF, VOUT = 1.0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------|--------|--|------|------|------|------|
| Output voltage range | VOUT | | 0.5 | | 2.2 | V |
| Output voltage setting steps | VSTEP | | | 0.1 | | V |
| Output voltage precision | VA | IOUT = 1 mA | (-3) | | (+3) | % |
| Maximum output current | IOUT | | 5 | | | mA |
| Short circuit current | ISHORT | VOUT = 0 V | | 40 | 65 | mA |
| Load regulation | LR | 1 mA ≤ IOUT ≤ 5 mA | | | (15) | mV |
| Power supply rejection ratio | PSRR | AVDD = 5.0 V + 0.1 Vpp ripple f = 100 Hz, IOUT = 2.5 mA | (45) | (50) | | dB |

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

2.6.3 Temperature sensor

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------------|--------|------------|------|-------|------|-------|
| Temperature coefficient for sensor | TCSNS | | | (756) | | μV/°C |
| Sensor output voltage | VTEMP | TA = 25°C | | 226.4 | | mV |

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

2.6.4 A/D converter characteristics

- (1) When positive reference voltage (+) = AVDD (ADREFP1 = 0, ADREFP0 = 0), negative reference voltage (-) = AVss (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVss = Vss = 0 V, positive reference voltage (+) = AVDD, negative reference voltage (-) = AVss)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|--------|--|----------------------|--------|------|-------|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error Note 1 | AINL | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | 1.2 | ±6.5 | LSB |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | 1.2 | ±7.0 | LSB |
| Conversion time | tCONV | 10-bit resolution | 4.0 V ≤ AVDD ≤ 5.5 V | 2.125 | | 39 | μs |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | 3.1875 | | 39 | μs |
| Zero-scale error Notes 1, 2 | Ezs | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | | ±0.50 | %FSR |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±0.60 | %FSR |
| Full-scale error Notes 1, 2 | Efs | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | | ±0.50 | %FSR |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±0.60 | %FSR |
| Integral linearity error Note 1 | ILE | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | | ±3.5 | LSB |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±4.0 | LSB |
| Differential linearity error Note 1 | DLE | 10-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±2.0 | LSB |
| Analog input voltage | VAIN | ANI0 to ANI9 | | AVss | | AVDD | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Caution The number of pins depends on the product. For details, see a list of pin functions.

- (2) When positive reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), negative reference voltage (-) = AVss (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVss = Vss = 0 V, positive reference voltage (+) = VBGR, negative reference voltage (-) = AVss)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|--------|----------------------|----------------------|-------------|------|-------|------|
| Resolution | RES | | | 8 | | | bit |
| Conversion time | tCONV | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | 17 | | 39 | μs |
| Zero-scale error Notes 1, 2 | Ezs | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±0.60 | %FSR |
| Integral linearity error Note 1 | ILE | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±2.0 | LSB |
| Differential linearity error Note 1 | DLE | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±1.0 | LSB |
| Internal reference voltage (+) | VBGR | 2.7 V ≤ AVDD ≤ 5.5 V | | VBGR Note 3 | | | V |
| Analog input voltage | VAIN | ANI0 to ANI9 | | 0 | | VBGR | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Note 3. See the Internal reference voltage characteristics.

2.6.5 12-bit D/A converter

(1) When positive reference voltage (+) = AVDD (DACVRF = 0)

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, positive reference voltage (+) = AVDD)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|--------|---|------|------|-----------|------|
| Resolution | DARES | | | | (12) | bit |
| Output voltage range | DAOUT | 12-bit resolution | 0.35 | | AVDD-0.47 | V |
| Integral non-linearity error | DAILE | 12-bit resolution | | | ±4.0 | LSB |
| Differential non-linearity error | DADLE | 12-bit resolution | | | ±1.0 | LSB |
| Offset error | DAErr | 12-bit resolution | | | ±30 | mV |
| Gain error | DAEG | 12-bit resolution | | | ±20 | mV |
| Settling time | DAtset | 12-bit resolution, CL = 50 pF, RL = 10 kΩ | | | (60) | μs |

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.

(2) When positive reference voltage (+) = internal reference voltage (DACVRF = 1)

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, positive reference voltage (+) = VREFDA)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|--------|--|------|------|--------|------|
| Resolution | DARES | | | | (8) | bit |
| Internal reference voltage | VREFDA | 8-bit resolution | 1.34 | 1.45 | 1.54 | V |
| Output voltage range | DAOUT | 8-bit resolution | 0.35 | | VREFDA | V |
| Integral non-linearity error | DAILE | 8-bit resolution | | | ±1.0 | LSB |
| Differential non-linearity error | DADLE | 8-bit resolution | | | ±1.0 | LSB |
| Offset error | DAErr | 8-bit resolution | | | ±30 | mV |
| Gain error | DAEG | 8-bit resolution | | | ±20 | mV |
| Settling time | DAtset | 8-bit resolution, CL = 50 pF, RL = 10 kΩ | | | (60) | μs |

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.

Remark 3. Offset error and gain error do not include error in the internal reference voltage.

2.6.6 Configurable amplifier

(TA = -40 to +105°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, VCOM = 1/2 AVDD, internally connected voltage follower)

AMP0 configuration SW setting: Positive (+) pin = ANX1, negative (-) pin = ANX0

AMP1 configuration SW setting: Positive (+) pin = ANX3, negative (-) pin = ANX2

AMP2 configuration SW setting: Positive (+) pin = ANX5, negative (-) pin = ANX4

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------|---|---------------|---------------|---------------|--------|
| Input voltage | VIN | | AVSS | | AVDD | V |
| Output voltage | VOL | IL = -1 mA, AVDD = 2.7 to 5.5 V | | AVSS +0.02 | AVSS +0.07 | V |
| | VOH | IL = 1 mA, AVDD = 2.7 to 5.5 V | AVDD -0.15 | AVDD -0.02 | | V |
| Maximum output current | IOUT | 4.5 V ≤ AVDD ≤ 5.5 V | ±10 | | | mA |
| | | 2.7 V ≤ AVDD ≤ 5.5 V | ±5 | | | mA |
| Input-referred offset voltage | VOFF | TA = 25°C without trimming IL = 0 mA, VCOM = 1.0 V | | ±1 | ±4 | mV |
| | | TA = 25°C with trimming IL = 0 mA, VCOM = 1.0 V | | | ±0.35 | mV |
| Temperature coefficient for input-referred offset voltage | VOTC | IL = 0 mA | | (±2) | (±8) | μV/°C |
| Slew rate | SR1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (0.1) | | V/μs |
| | SR2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (0.8) | | V/μs |
| Gain bandwidth | GBW1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (350) | | kHz |
| | GBW2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (1.8) | | MHz |
| Phase margin | θM1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (70) | | deg |
| | θM2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (60) | | deg |
| Settling time | tset1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (20) | | μs |
| | tset2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (10) | | μs |
| Peak-to-peak voltage noise | Enb | 0.1 to 10 Hz Normal mode CL = 50 pF, RL = 10 kΩ | | (2.0) | | μVrms |
| Input-referred noise | En | f = 1 kHz, Normal mode CL = 50 pF, RL = 10 kΩ | | (70) | | nV/√Hz |
| Common mode rejection ratio | CMRR | f = 1 kHz, CL = 50 pF, RL = 10 kΩ | | (70) | | dB |
| Power supply rejection ratio | PSRR | 2.7 V ≤ AVDD ≤ 5.5 V f = 1 kHz, CL = 50 pF, RL = 10 kΩ | | (62) | | dB |

(Remarks are listed on the next page.)

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

Remark 2. The TYP. conditions are the conditions when TA = 25°C and AVDD = 5.0 V.

Remark 3. Unless otherwise specified, offset trimming has proceeded.

Remark 4. Unless otherwise specified, values are for operation in normal mode.

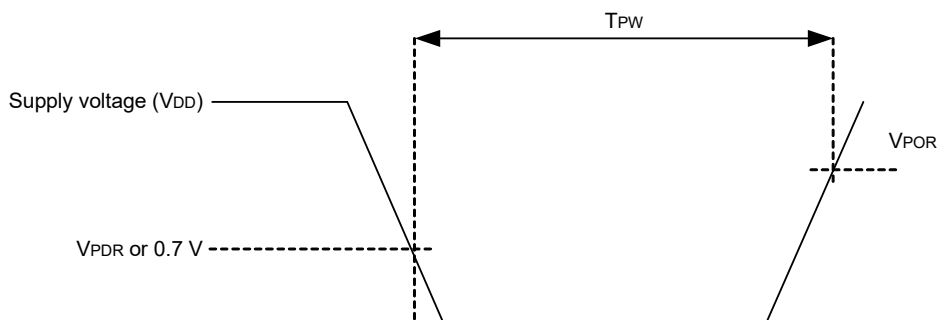
2.6.7 POR characteristics

(TA = -40 to +105°C, VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------------|--------|--|------|------|------|------|
| Power on/down reset threshold | VPOR | Voltage threshold on VDD rising | 1.48 | 1.56 | 1.62 | V |
| | VPDR | Voltage threshold on VDD falling ^{Note 1} | 1.47 | 1.55 | 1.61 | V |
| Minimum pulse width ^{Note 2} | TPW | | 300 | | | μs |

Note 1. However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 2.4 AC Characteristics.

Note 2. Minimum time required for a POR reset when VDD exceeds below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HISTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



2.6.8 LVD characteristics

(1) LVD detection voltage in reset mode and interrupt mode

(TA = -40 to +105°C, VPDR ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------|--------|--------------|------|------|------|------|
| Voltage detection threshold | VLVD0 | Rising edge | 4.62 | 4.74 | 4.84 | V |
| | | Falling edge | 4.52 | 4.64 | 4.74 | V |
| | VLVD1 | Rising edge | 4.50 | 4.62 | 4.72 | V |
| | | Falling edge | 4.40 | 4.52 | 4.62 | V |
| | VLVD2 | Rising edge | 4.30 | 4.42 | 4.51 | V |
| | | Falling edge | 4.21 | 4.32 | 4.41 | V |
| | VLVD3 | Rising edge | 3.13 | 3.22 | 3.29 | V |
| | | Falling edge | 3.07 | 3.15 | 3.22 | V |
| | VLVD4 | Rising edge | 2.95 | 3.02 | 3.09 | V |
| | | Falling edge | 2.89 | 2.96 | 3.02 | V |
| | VLVD5 | Rising edge | 2.74 | 2.81 | 2.87 | V |
| | | Falling edge | 2.68 | 2.75 | 2.81 | V |
| | VLVD6 | Rising edge | 2.55 | 2.61 | 2.67 | V |
| | | Falling edge | 2.49 | 2.55 | 2.61 | V |
| Minimum pulse width | tlw | | 300 | | | μs |
| Detection delay time | | | | | 300 | μs |

(2) LVD detection voltage in interrupt & reset mode

(TA = -40 to +105°C, VPDR ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--------------------------------|--------|--|------------------------------|------|------|------|------|
| Voltage detection threshold | VLVDD6 | VPOC2, VPOC1, VPOC0 = 0, 0, 0, falling reset voltage | | 2.49 | 2.55 | 2.61 | V |
| | VLVDD4 | LVIS1, LVIS0 = 0, 1 | Rising release reset voltage | 2.95 | 3.02 | 3.09 | V |
| | | | Falling interrupt voltage | 2.89 | 2.96 | 3.02 | V |
| | VLVDD3 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 3.13 | 3.22 | 3.29 | V |
| | | | Falling interrupt voltage | 3.07 | 3.15 | 3.22 | V |
| | VLVDD5 | VPOC2, VPOC1, VPOC0 = 0, 0, 1, falling reset voltage | | 2.68 | 2.75 | 2.81 | V |
| | VLVDD2 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 4.30 | 4.42 | 4.51 | V |
| | | | Falling interrupt voltage | 4.21 | 4.32 | 4.41 | V |
| | VLVDD5 | VPOC2, VPOC1, VPOC0 = 0, 1, 0, falling reset voltage | | 2.68 | 2.75 | 2.81 | V |
| | VLVDD1 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 4.50 | 4.62 | 4.72 | V |
| | | | Falling interrupt voltage | 4.40 | 4.52 | 4.62 | V |
| | VLVDD5 | VPOC2, VPOC1, VPOC0 = 0, 1, 1, falling reset voltage | | 2.68 | 2.75 | 2.81 | V |
| | VLVDD3 | LVIS1, LVIS0 = 0, 1 | Rising release reset voltage | 3.13 | 3.22 | 3.29 | V |
| | | | Falling interrupt voltage | 3.07 | 3.15 | 3.22 | V |
| | VLVDD0 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 4.62 | 4.74 | 4.84 | V |
| | | | Falling interrupt voltage | 4.52 | 4.64 | 4.74 | V |

2.6.9 Power supply voltage rising slope characteristics

(TA = -40 to +105°C, Vss = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------------|--------|------------|------|------|------|------|
| Power supply voltage rising slope | SVDD | | | | 50 | V/ms |

Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until VDD reaches the operating voltage range shown in 2.4 AC Characteristics.

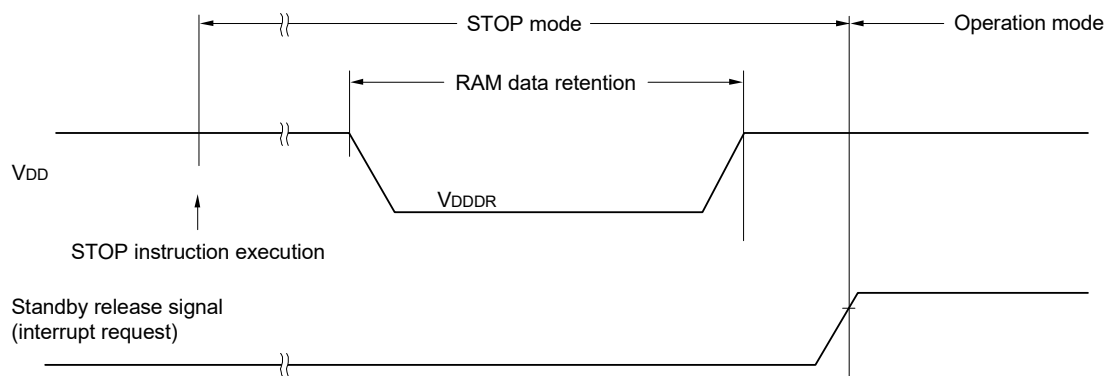
2.7 RAM Data Retention Characteristics

(TA = -40 to +105°C, Vss = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------|--------|------------|-----------------|------|------|------|
| Data retention supply voltage | VDDDR | | 1.47 Notes 1, 2 | | 5.5 | V |

Note 1. The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.

Note 2. Enter STOP mode before the supply voltage falls below the recommended operating voltage.



2.8 Flash Memory Programming Characteristics

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVss = Vss = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|-------------------|--|---------|-----------|------|-------|
| System clock frequency | fCLK | 2.4 V ≤ VDD ≤ 5.5 V | 1 | | 32 | MHz |
| Number of code flash rewrites Notes 1, 2, 3 | C _{erwr} | Retained for 20 years TA = 85°C ^{Note 4} | 1,000 | | | Times |
| Number of data flash rewrites Notes 1, 2, 3 | | Retained for 1 year TA = 25°C ^{Note 4} | | 1,000,000 | | |
| | | Retained for 5 years TA = 85°C ^{Note 4} | 100,000 | | | |
| | | Retained for 20 years TA = 85°C ^{Note 4} | 10,000 | | | |

Note 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

Note 2. When using flash memory programmer and Renesas Electronics self-programming library

Note 3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

Note 4. This temperature is the average value at which data are retained.

2.9 Dedicated Flash Memory Programmer Communication (UART)

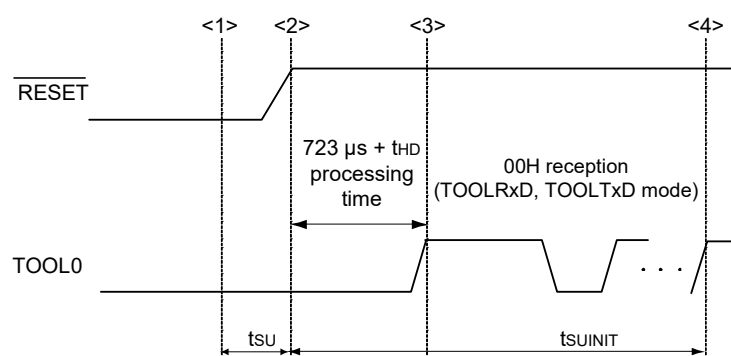
(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------|--------|---------------------------|---------|------|-----------|------|
| Transfer rate | | During serial programming | 115,200 | | 1,000,000 | bps |

2.10 Timing for Switching Flash Memory Programming Modes

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---------|--|------|------|------|------|
| How long from when an external reset ends until the initial communication settings are specified | tsuINIT | POR and LVD reset must end before the external reset ends. | | | 100 | ms |
| How long from when the TOOL0 pin is placed at the low level until an external reset ends | tsu | POR and LVD reset must end before the external reset ends. | 10 | | | μs |
| How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory) | tHD | POR and LVD reset must end before the external reset ends. | 1 | | | ms |



<1> The low level is input to the TOOL0 pin.

<2> The external reset ends (POR and LVD reset must end before the external reset ends).

<3> The TOOL0 pin is set to the high level.

<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark tsuINIT: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.

tsu: How long from when the TOOL0 pin is placed at the low level until a pin reset ends

tHD: How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

3. ELECTRICAL SPECIFICATIONS (M: T_A = -40 to +125°C)

This chapter describes the electrical specifications for the products “M: Industrial applications (T_A = -40 to +125°C)”.

Caution 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

Caution 2. The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Alternate functions other than AFE in the RL78/I1E User's Manual.

Caution 3. Please contact Renesas Electronics sales office for derating of operation under T_A = +85 to +125°C. Derating is the systematic reduction of load for the sake of improved reliability.

Remark The electrical characteristics of the products M: Industrial applications (T_A = -40 to +125°C) are different from those of the products “G: Industrial applications”. For details, refer to 3.1 to 3.10.

3.1 Absolute Maximum Ratings

Absolute Maximum Ratings

(1/2)

| Parameter | Symbol | Conditions | Ratings | Unit |
|---------------------------------------|---------------------|--|---|---------------------------------------|
| Supply voltage | V _{DD} | | -0.5 to +6.5 | V |
| | AV _{DD} | AV _{DD} = V _{DD} | -0.5 to +6.5 | V |
| | AV _{SS} | AV _{SS} = V _{SS} | -0.5 to +0.3 | V |
| REGC pin input voltage | V _I REGC | REGC | -0.3 to +2.8 and -0.3 to V _{DD} + 0.3 Note 1 | V |
| REGA pin input voltage | V _I REGA | REGA | -0.3 to +2.8 and -0.3 to AV _{DD} + 0.3 Note 2 | V |
| Input voltage | V _{I1} | P10 to P15, P40, P121, P122, P137, EXCLK, RESET | -0.3 to V _{DD} + 0.3 Note 3 | V |
| Alternate-function pin input voltage | V _{I2} | P16, P17, P41, P42 (36-pin products only) | Digital input voltage | -0.3 to V _{DD} + 0.3 Note 3 |
| | | | Analog input voltage | -0.3 to AV _{DD} + 0.3 Note 3 |
| Analog input voltage | V _{IA} | PGA0P to PGA3P, PGA0N to PGA3N, ANI0 to ANI9, ANX0 to ANX5 | -0.3 to AV _{DD} + 0.3 Note 3 | V |
| Output voltage | V _{O1} | P10 to P15, P40 | -0.3 to V _{DD} + 0.3 Note 3 | V |
| Alternate-function pin output voltage | V _{O2} | P16, P17, P41, P42 (36-pin products only) | Digital output voltage | -0.3 to V _{DD} + 0.3 Note 3 |
| | | | Analog output voltage | -0.3 to AV _{DD} + 0.3 Note 3 |
| Analog output voltage | V _{OA} | SBIAS, AMP0O to AMP2O, ANX0 to ANX5 | -0.3 to AV _{DD} + 0.3 Note 3 | V |

Note 1. Connect the REGC pin to V_{SS} via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

Note 2. Connect the REGA pin to AV_{SS} via a capacitor (0.22 μF). This value regulates the absolute maximum rating of the REGA pin. Do not use this pin with voltage applied to it.

Note 3. Must be 6.5 V or lower.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Remark 2. V_{SS} is used as the reference voltage.

Absolute Maximum Ratings**(2/2)**

| Parameter | Symbol | Conditions | | Ratings | Unit |
|-------------------------------|------------------|----------------------------------|----------------------------------|-------------|------|
| Output current, high | IOH1 | Per pin | P10 to P17, P40 to P42 | -40 | mA |
| | | Total of all pins | P10 to P17, P41, P42 <i>Note</i> | -100 | mA |
| Analog output current, high | IOHA | Per pin | AMP00 to AMP20 | -12 | mA |
| | | | ANX0 to ANX5 | -0.12 | mA |
| | | Total of all pins | AMP00 to AMP20, ANX0 to ANX5 | -18 | mA |
| Output current, low | IOL1 | Per pin | P10 to P17, P40 to P42 | 40 | mA |
| | | Total of all pins | P10 to P17, P41, P42 <i>Note</i> | 100 | mA |
| Analog output current, low | IOLA | Per pin | AMP00 to AMP20 | 12 | mA |
| | | | ANX0 to ANX5 | 0.12 | mA |
| | | Total of all pins | AMP00 to AMP20, ANX0 to ANX5 | 18 | mA |
| Operating ambient temperature | TA | In normal operation mode | | -40 to +125 | °C |
| | | In flash memory programming mode | | | |
| Storage temperature | T _{stg} | | | -65 to +150 | °C |

Note This indicates the total current value when P16, P17, P41, and P42 are used as digital input pins.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

Remark 1. Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

Remark 2. V_{ss} is used as the reference voltage.

3.2 Oscillator Characteristics

3.2.1 X1 characteristics

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Resonator | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---|---------------------|------|------|------|------|
| X1 clock oscillation frequency (fx) ^{Note} | Ceramic resonator/ crystal resonator | 2.7 V ≤ VDD ≤ 5.5 V | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | 1.0 | | 16.0 | |

Note Indicates only permissible oscillator frequency ranges. Refer to **AC Characteristics** for instruction execution time.
Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

Caution Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

Remark When using the X1 oscillator, refer to **5.4 System Clock Oscillator** in the RL78/I1E User's Manual..

3.2.2 On-chip oscillator characteristics

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|-----------------|---------------------|------|------|------|------|
| High-speed on-chip oscillator clock frequency Notes 1, 2 | f _{IH} | 2.7 V ≤ VDD ≤ 5.5 V | 1 | | 24 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | 1 | | 16 | MHz |
| High-speed on-chip oscillator clock frequency accuracy | | -40 to +105°C | -2.0 | | +2.0 | % |
| | | +105 to +125°C | -3.0 | | +3.0 | % |
| Low-speed on-chip oscillator clock frequency | f _{IL} | | | 15 | | kHz |
| Low-speed on-chip oscillator clock frequency accuracy | | | -15 | | +15 | % |

Note 1. High-speed on-chip oscillator frequency is selected with bits 0 to 3 of the option byte (000C2H) and bits 0 to 2 of the HOCODIV register.

Note 2. This only indicates the oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

3.2.3 PLL characteristics

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | | MIN. | TYP. | MAX. | Unit |
|---|------------------|---|-------------|----------|------|------|------|------|
| PLL output frequency ^{Notes 1, 2, 3} | f _{PLL} | f _{MX} = 8 MHz | DSFRDIV = 0 | DSCM = 0 | | 48 | | MHz |
| | | | DSFRDIV = 1 | DSCM = 0 | | 24 | | MHz |
| | | | | DSCM = 1 | | 32 | | MHz |
| | | f _{MX} = 4 MHz | DSFRDIV = 0 | DSCM = 0 | | 24 | | MHz |
| | | | | DSCM = 1 | | 32 | | MHz |
| Lockup wait time | | Time from when PLL output is enabled to when the phase is locked | | | 40 | | | μs |
| Interval wait time | | Time from when the PLL stops operating to when the setting to start PLL operation is specified | | | 4 | | | μs |
| Setup wait time | | Time required from when the PLL input clock stabilizes and the PLL setting is determined to when the PLL is activated | | | 1 | | | μs |

Note 1. When using a PLL, input a clock of 4 MHz or 8 MHz to the PLL.

Note 2. Be sure to specify one of these settings when using a PLL.

Note 3. When using the PLL output as the CPU clock, f_{IH} is divided by 2, 4, or 8 according to the setting of the RDIV1 and RDIV0 bits.

3.3 DC Characteristics

3.3.1 Pin characteristics

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(1/3)

| Item | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|--------|---|---------------------|------|------------------------|------|
| Output current, high ^{Note 1} | IOH1 | Per pin for P10 to P17 and P40 to P42 ^{Note 2} | 4.0 V ≤ VDD ≤ 5.5 V | | -3.0 ^{Note 3} | mA |
| | | | 2.4 V ≤ VDD < 4.0 V | | -1.0 ^{Note 3} | mA |
| | | Total of P10 to P17, P41, and P42 ^{Note 3} (When duty ≤ 70% ^{Note 4}) | 4.0 V ≤ VDD ≤ 5.5 V | | -30.0 | mA |
| | | | 2.7 V ≤ VDD < 4.0 V | | -19.0 | mA |
| | | | 2.4 V ≤ VDD < 2.7 V | | -10.0 | mA |
| Output current, low ^{Note 1} | IOL1 | Per pin for P10 to P17 and P40 to P42 ^{Note 2} | 4.0 V ≤ VDD ≤ 5.5 V | | 8.5 ^{Note 3} | mA |
| | | | 2.7 V ≤ VDD < 4.0 V | | 1.5 ^{Note 3} | mA |
| | | | 2.4 V ≤ VDD < 2.7 V | | 0.6 ^{Note 3} | mA |
| | | Total of P10 to P17, P41, and P42 ^{Note 2} (When duty ≤ 70% ^{Note 4}) | 4.0 V ≤ VDD ≤ 5.5 V | | 40.0 | mA |
| | | | 2.7 V ≤ VDD < 4.0 V | | 35.0 | mA |
| | | | 2.4 V ≤ VDD < 2.7 V | | 20.0 | mA |

Note 1. Value of current at which the device operation is guaranteed even if the current flows from the VDD pin to an output pin.

Note 2. This indicates the total current value when P16, P17, P41, and P42 are used as digital I/O ports. When using these pins as analog function (AFE) pins, refer to **3.1 Absolute Maximum Ratings**.

Note 3. Do not exceed the total current value.

Note 4. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IOH × 0.7)/(n × 0.01)

Example: n = 80% when IOH = -10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \approx -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

A current higher than the absolute maximum rating must not flow into one pin.

Caution P10 to P15 do not output high level in N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(2/3)

| Item | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|----------------------|--------|--------------------------------|---------------------------------------|-----------|------|---------|------|
| Input voltage, high | VIH1 | P10 to P17 and P40 to P42 | Normal input buffer | 0.8 VDD | | VDD | V |
| | VIH2 | P11, P12, P14, P15 | TTL input buffer, 4.0 V ≤ VDD ≤ 5.5 V | 2.2 | | VDD | V |
| | | | TTL input buffer, 3.3 V ≤ VDD < 4.0 V | 2.0 | | VDD | V |
| | | | TTL input buffer, 2.4 V ≤ VDD < 3.3 V | 1.28 | | VDD | V |
| | VIH3 | P121, P122, P137, EXCLK, RESET | | 0.8 VDD | | VDD | V |
| Input voltage, low | VIL1 | P10 to P17 and P40 to P42 | Normal input buffer | 0 | | 0.2 VDD | V |
| | VIL2 | P11, P12, P14, P15 | TTL input buffer, 4.0 V ≤ VDD ≤ 5.5 V | 0 | | 0.8 | V |
| | | | TTL input buffer, 3.3 V ≤ VDD < 4.0 V | 0 | | 0.5 | V |
| | | | TTL input buffer, 2.4 V ≤ VDD < 3.3 V | 0 | | 0.32 | V |
| | VIL3 | P121, P122, P137, EXCLK, RESET | | 0 | | 0.2 VDD | V |
| Output voltage, high | VOH1 | P10 to P17 and P40 to P42 | 4.0 V ≤ VDD ≤ 5.5 V, IOH1 = -3.0 mA | VDD - 0.7 | | | V |
| | | | 2.4 V ≤ VDD ≤ 5.5 V, IOH1 = -1.0 mA | VDD - 0.5 | | | V |
| Output voltage, low | VOL1 | P10 to P17 and P40 to P42 | 4.0 V ≤ VDD ≤ 5.5 V, IOL1 = 8.5 mA | | | 0.7 | V |
| | | | 2.7 V ≤ VDD ≤ 5.5 V, IOL1 = 1.5 mA | | | 0.5 | V |
| | | | 2.4 V ≤ VDD ≤ 5.5 V, IOL1 = 0.6 mA | | | 0.4 | V |

Caution The maximum VIH value on P10 to P15 is VDD, even in the N-ch open-drain mode.

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(3/3)

| Item | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-----------------------------|-------------------|---------------------------------|---|---|------|------|------|
| Input leakage current, high | ILI _{H1} | P10 to P17, and P40 to P42 | V _I = V _{DD} | | | 1 | μA |
| | ILI _{H2} | P137, $\overline{\text{RESET}}$ | V _I = V _{DD} | | | 1 | μA |
| | ILI _{H3} | P121, P122 (X1, X2, EXCLK) | V _I = V _{DD} | In input port mode or when using external clock input | | 1 | μA |
| | | | | When a resonator is connected | | 10 | μA |
| Input leakage current, low | ILI _{L1} | P10 to P17, and P40 to P42 | V _I = V _{SS} | | | -1 | μA |
| | ILI _{L2} | P137, $\overline{\text{RESET}}$ | V _I = V _{SS} | | | -1 | μA |
| | ILI _{L3} | P121, P122 (X1, X2, EXCLK) | V _I = V _{SS} | In input port mode or when using external clock input | | -1 | μA |
| | | | | When a resonator is connected | | -10 | μA |
| On-chip pull-up resistance | R _U | P10 to P15, P40 | V _I = V _{SS} , in input port mode | 10 | 20 | 100 | kΩ |

Remark Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

3.3.2 Supply current characteristics

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(1/2)

| Parameter | Symbol | Conditions | | | | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------|--------------------------|--|------------------|----------------------|------|------|------|------|
| Supply current Note 1 | IDD1 | Operating mode Note 2 | fHOCO = 24 MHz, fMAIN = 24 MHz Note 3 | Basic operation | VDD = 5.0 V | | 1.7 | | mA |
| | | | | | VDD = 3.0 V | | 1.7 | | |
| | | | fHOCO = 24 MHz, fMAIN = 24 MHz Note 3 | Normal operation | VDD = 5.0 V | | 3.8 | 7.6 | mA |
| | | | | | VDD = 3.0 V | | 3.8 | 7.6 | |
| | | | fHOCO = 16 MHz, fMAIN = 16 MHz Note 3 | Normal operation | VDD = 5.0 V | | 2.8 | 5.6 | |
| | | | | | VDD = 3.0 V | | 2.8 | 5.6 | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 4, VDD = 5.0 V | Normal operation | Square wave input | | 3.3 | 6.5 | mA |
| | | | | | Resonator connection | | 3.5 | 6.6 | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 4, VDD = 3.0 V | Normal operation | Square wave input | | 3.3 | 6.5 | |
| | | | | | Resonator connection | | 3.5 | 6.6 | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 4, VDD = 5.0 V | Normal operation | Square wave input | | 2.0 | 3.9 | |
| | | | | | Resonator connection | | 2.1 | 4.0 | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 4, VDD = 3.0 V | Normal operation | Square wave input | | 2.0 | 3.9 | |
| | | | | | Resonator connection | | 2.1 | 4.0 | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 5, VDD = 5.0 V | Normal operation | Square wave input | | 5.1 | 10.4 | mA |
| | | | | | Resonator connection | | 5.2 | 10.5 | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 5, VDD = 3.0 V | Normal operation | Square wave input | | 5.1 | 10.4 | |
| | | | | | Resonator connection | | 5.2 | 10.5 | |

Note 1. Total current flowing into VDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or VSS. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

Note 2. The relationship between the operation voltage range and the CPU operating frequency is as below.

2.7 V ≤ VDD ≤ 5.5 V @ 1 MHz to 24 MHz

2.4 V ≤ VDD ≤ 5.5 V @ 1 MHz to 16 MHz

Note 3. When the high-speed system clock is stopped

Note 4. When the high-speed on-chip oscillator and the PLL are stopped

Note 5. When the high-speed on-chip oscillator is stopped and the PLL is operating

Remark 1. fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. fHOCO: High-speed on-chip oscillator clock frequency

Remark 3. fMAIN: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is TA = 25°C

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

(2/2)

| Parameter | Symbol | Conditions | | | MIN. | TYP. | MAX. | Unit | |
|--------------------------|----------------|---------------------|--|----------------------|------|------|------|-------|----|
| Supply current Note 1 | IDD2 Note 2 | HALT mode Note 3 | fHOCO = 24 MHz, fMAIN = 24 MHz Note 4 | VDD = 5.0 V | | 0.44 | 3.42 | mA | |
| | | | | VDD = 3.0 V | | 0.44 | 3.42 | | |
| | | | fHOCO = 16 MHz, fMAIN = 16 MHz Note 4 | VDD = 5.0 V | | 0.40 | 2.50 | | |
| | | | | VDD = 3.0 V | | 0.40 | 2.50 | | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 5, VDD = 5.0 V | Square wave input | | 0.28 | 2.94 | mA | |
| | | | | Resonator connection | | 0.49 | 3.08 | | |
| | | | fMX = 20 MHz, fMAIN = 20 MHz Note 5, VDD = 3.0 V | Square wave input | | 0.28 | 2.94 | | |
| | | | | Resonator connection | | 0.49 | 3.08 | | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 5, VDD = 5.0 V | Square wave input | | 0.19 | 1.54 | | |
| | | | | Resonator connection | | 0.30 | 1.63 | | |
| | | | fMX = 10 MHz, fMAIN = 10 MHz Note 5, VDD = 3.0 V | Square wave input | | 0.19 | 1.54 | | |
| | | | | Resonator connection | | 0.30 | 1.63 | | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 6, VDD = 5.0 V | Square wave input | | 0.76 | 3.92 | mA | |
| | | | | Resonator connection | | 0.86 | 4.04 | | |
| | | | fMX = 8 MHz, fMAIN = 24 MHz Note 6, VDD = 3.0 V | Square wave input | | 0.76 | 3.92 | | |
| | | | | Resonator connection | | 0.86 | 4.04 | | |
| | IDD3 Note 7 | STOP mode | TA = -40°C | | | | 0.38 | 1.14 | μA |
| | | | TA = +25°C | | | | 0.50 | 1.14 | |
| | | | TA = +50°C | | | | 0.66 | 4.52 | |
| | | | TA = +70°C | | | | 1.04 | 7.98 | |
| | | | TA = +85°C | | | | 2.92 | 16.0 | |
| | | | TA = +105°C | | | | 11.0 | 100.0 | |
| | | | TA = +125°C | | | | 22.0 | 200.0 | |

Note 1. Total current flowing into VDD, including the input leakage current flowing when the level of the input pin is fixed to VDD or VSS. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the RTC, interval timer, watchdog timer, LVD circuit, AFE, I/O ports, and on-chip pull-up/pull-down resistors and the current flowing during writing to the data flash.

Note 2. During HALT instruction execution from flash memory

Note 3. The relationship between the operation voltage range and the CPU operating frequency is as below.

2.7 V ≤ VDD ≤ 5.5 V @ 1 MHz to 24 MHz

2.4 V ≤ VDD ≤ 5.5 V @ 1 MHz to 16 MHz

Note 4. When the high-speed system clock is stopped

Note 5. When the high-speed on-chip oscillator and the PLL are stopped

Note 6. When high-speed on-chip oscillator is stopped and the PLL is operating

Note 7. The MAX. value includes the leakage current in STOP mode.

Remark 1. fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. fHOCO: High-speed on-chip oscillator clock frequency

Remark 3. fMAIN: Main system clock frequency

Remark 4. The temperature condition for the TYP. value is TA = 25°C, except the operation in STOP mode.

• Peripheral functions

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|--------------------|--------------------------------------|--|------|------|-------|------|
| Low-speed on-chip oscillator operating current | IFIL Note 1 | | | | 0.20 | | μA |
| RTC operating current | IRTC Notes 1, 2, 3 | fMX = 4 MHz, RTCCL = 00H (fMX/122) | | | 22 | | μA |
| Interval timer operating current | IIIT Notes 1, 2, 4 | fMX = 4 MHz, RTCCL = 00H (fMX/122) | | | 22 | | μA |
| Watchdog timer operating current | IWDT Notes 1, 5, 6 | fIL = 15 kHz | | | 0.22 | | μA |
| LVD operating current | ILVD Notes 1, 7 | | | | 0.08 | | μA |
| Self-programming operating current | IFSP Notes 1, 8 | | | | 2.00 | 12.20 | mA |
| BGO operating current | IBGO Notes 1, 9 | | | | 2.00 | 12.20 | mA |
| SNOOZE operating current | ISNOZ Note 1 | A/D converter operation Notes 10, | The mode is performed | | 0.50 | 1.10 | mA |
| | | | During A/D conversion, AVDD = VDD = 3.0 V | | 1.20 | 2.04 | |
| | | Simplified SPI(CSI)/UART operation | | | 0.70 | 1.54 | |
| | | DTC operation | | | 3.10 | | |

Note 1. Current flowing to VDD

Note 2. When the high-speed on-chip oscillator is stopped

Note 3. Current flowing only to the real-time clock (RTC). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock is operating in operation mode or HALT mode.

Note 4. Current flowing only to the interval timer. The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIIT, when the interval timer is operating in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, also add IFIL.

Note 5. When the high-speed on-chip oscillator and high-speed system clock are stopped.

Note 6. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and IWDT when the watchdog timer is operating.

Note 7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of IDD1, IDD2 or IDD3 and ILVD when the LVD circuit is operating.

Note 8. Current flowing during self-programming

Note 9. Current flowing during writing to the data flash

Note 10. The current flowing into the AVDD is included.

Remark 1. fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

Remark 2. fIL: Low-speed on-chip oscillator clock frequency

Remark 3. The temperature condition for the TYP. value is TA = 25°C

• AFE functions

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------|---|------|------|------|------|
| 24-bit ΔΣ A/D converter operating current | IDSAD | Normal mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS IOUT = 0 mA | | 0.94 | 1.46 | mA |
| | | Low power mode Notes 1, 2 Circuits that operate: ABGR, REGA, SBIAS, VREFAMP, PGA, 24-bit ΔΣ A/D converter, and digital filter Differential input mode OSR = 256 SBIAS IOUT = 0 mA | | 0.60 | 0.91 | mA |
| 10-bit A/D converter operating current | IADC | During conversion at the highest speed Notes 1, 2 AVDD = 5.0 V | | 1.30 | 1.70 | mA |
| Configurable amplifier operating current | IAMP | Normal mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier IL = 0 mA Per channel | | 0.13 | 0.24 | mA |
| | | High-speed mode Notes 1, 2 Circuits that operate: ABGR and configurable amplifier IL = 0 mA Per channel | | 0.30 | 0.45 | mA |
| 12-bit D/A converter operating current | IDAC | When AVDD and AVSS are selected as the reference voltage Notes 1, 2 Circuits that operate: ABGR and internal reference voltage (VREFDA) | | 0.61 | 0.97 | mA |

Note 1. Current flowing to AVDD**Note 2.** Current flowing only to the circuits that operate shown in the Conditions column.

3.4 AC Characteristics

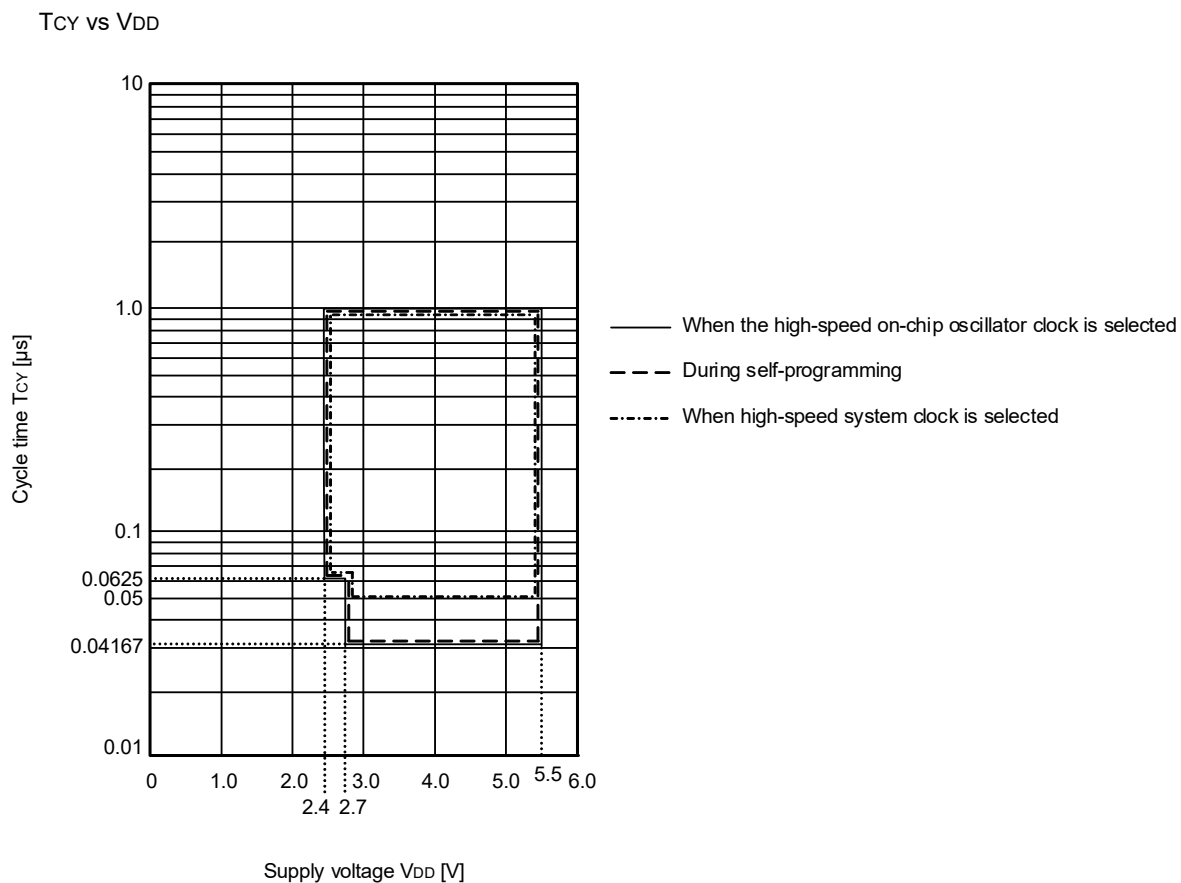
(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Items | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|--|-------------------|-------------------------------------|---------------------|-------------|------|------|------|
| Instruction cycle (minimum instruction execution time) | Tcy | Main system clock (fMAIN) operation | 2.7 V ≤ VDD ≤ 5.5 V | 0.04167 | | 1 | μs |
| | | | 2.4 V ≤ VDD < 2.7 V | 0.0625 | | 1 | μs |
| | | In the self-programming mode | 2.7 V ≤ VDD ≤ 5.5 V | 0.04167 | | 1 | μs |
| | | | 2.4 V ≤ VDD < 2.7 V | 0.0625 | | 1 | μs |
| External system clock frequency | fEX | 2.7 V ≤ VDD ≤ 5.5 V | | 1.0 | | 20.0 | MHz |
| | | 2.4 V ≤ VDD < 2.7 V | | 1.0 | | 8.0 | MHz |
| External system clock input high-level width, low-level width | tEXH, tEXL | 2.7 V ≤ VDD ≤ 5.5 V | | 24 | | | ns |
| | | 2.4 V ≤ VDD < 2.7 V | | 60 | | | ns |
| TI00 to TI03, TI10, TI11 input high-level width, low-level width | tTIIH, tTIL | | | 1/fMCK + 10 | | | ns |
| Timer RJ input cycle | fc | TRJIO0 | 2.7 V ≤ VDD ≤ 5.5 V | 100 | | | ns |
| | | | 2.4 V ≤ VDD < 2.7 V | 300 | | | ns |
| Timer RJ input high- level width, low-level width | tTJIH, tTJIL | TRJIO0 | 2.7 V ≤ VDD ≤ 5.5 V | 40 | | | ns |
| | | | 2.4 V ≤ VDD < 2.7 V | 120 | | | ns |
| Timer RG input high- level width, low-level width | tTRGIH, tTRGIL | TRGIOA, TRGIOB | | 2.5/fCLK | | | ns |
| TO00 to TO03, TO10, TO11, TRJIO0, TRJO0, TRGIOA, TRGIOB output frequency | fTO | | 4.0 V ≤ VDD ≤ 5.5 V | | | 12 | MHz |
| | | | 2.7 V ≤ VDD ≤ 4.0 V | | | 6 | MHz |
| | | | 2.4 V ≤ VDD < 2.7 V | | | 3 | MHz |
| PCLBUZ0 output frequency | fPCL | | 4.0 V ≤ VDD ≤ 5.5 V | | | 12 | MHz |
| | | | 2.7 V ≤ VDD ≤ 4.0 V | | | 6 | MHz |
| | | | 2.4 V ≤ VDD < 2.7 V | | | 3 | MHz |
| Interrupt input high- level width, low-level width | tINTH, tINTL | INTP1 to INTP7 | | 1 | | | μs |
| RESET low-level width | tRSL | | | 10 | | | μs |

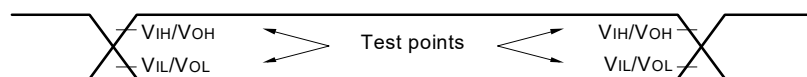
Remark fMCK: Timer array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3))

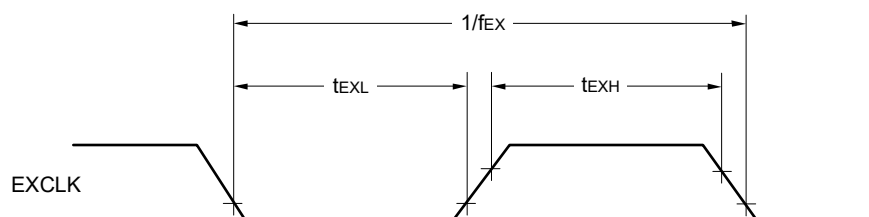
Minimum Instruction Execution Time During Main System Clock Operation



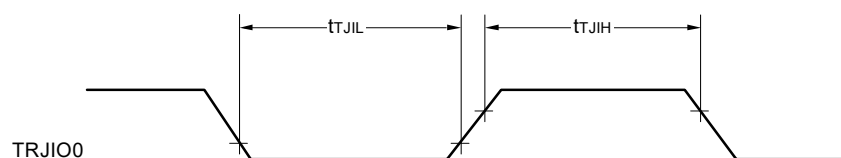
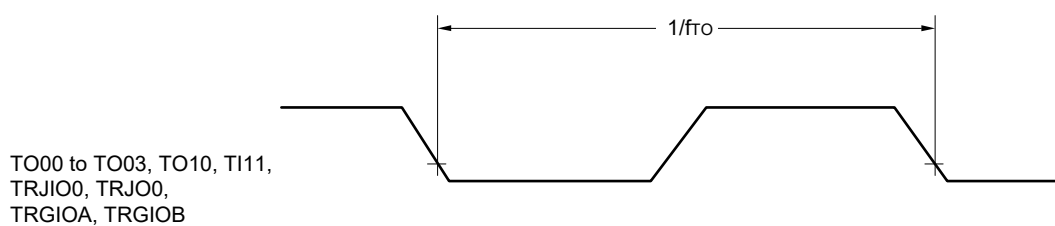
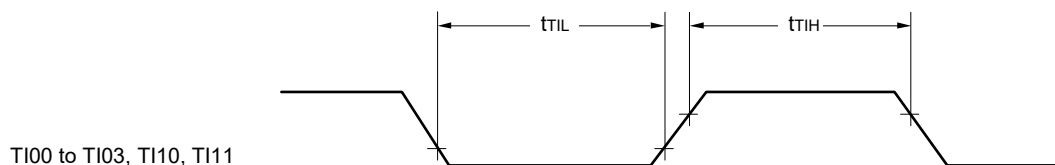
AC Timing Test Points

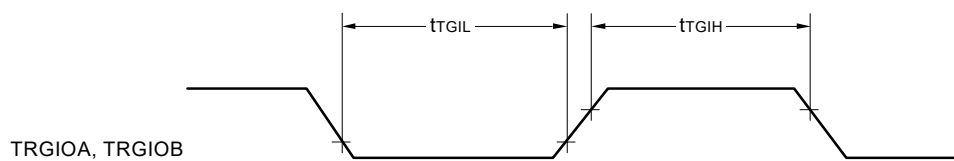


External System Clock Timing

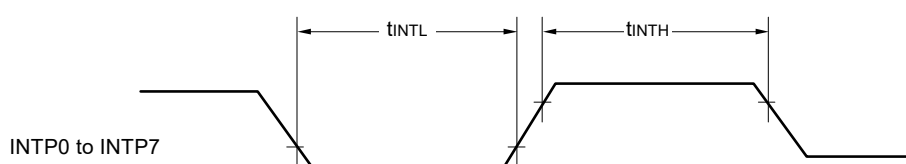
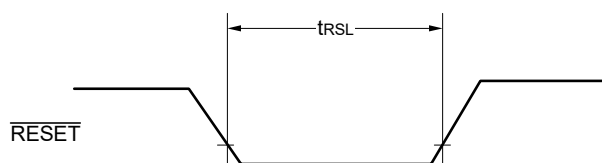


TI/TO Timing



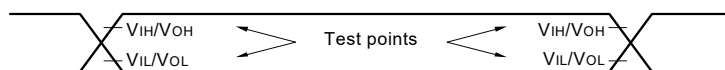


Interrupt Request Input Timing

 $\overline{\text{RESET}}$ Input Timing

3.5 Peripheral Functions Characteristics

AC Timing Test Points



3.5.1 Serial array unit

(1) During communication at same potential (UART mode)

(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | HS (high-speed main) Mode | | Unit |
|----------------------|--------|--|---------------------------|---------|------|
| | | | MIN. | MAX. | |
| Transfer rate Note 1 | | | | fMCK/12 | bps |
| | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | | 2.0 | Mbps |

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.

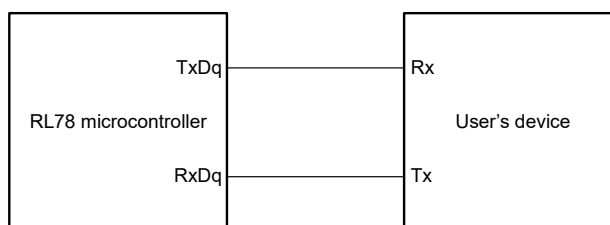
Note 2. The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

24 MHz (2.7 V ≤ VDD ≤ 5.5 V)

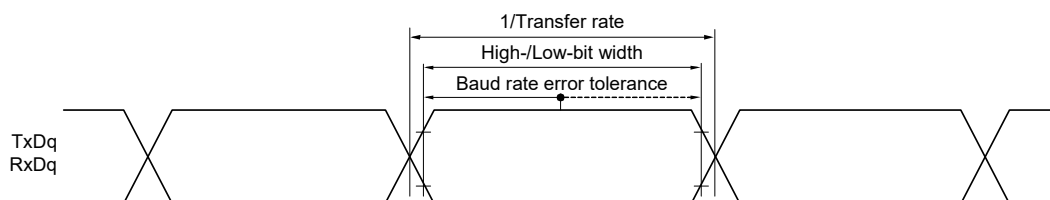
16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

Caution Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

UART mode connection diagram (during communication at same potential)



UART mode bit width (during communication at same potential) (reference)



Remark 1. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 2. fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03))

(2) During communication at same potential (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|--|-------------------------------------|---|---------------------------|------|------|
| | | | MIN. | MAX. | |
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} 2.7 V ≤ V _{DD} ≤ 5.5 V | 333 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 666 | | ns |
| SCKp high-/low-level width | t _{KH1} , t _{KL1} | 4.0 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 24 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 36 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | t _{KCY1} /2 - 76 | | ns |
| Slp setup time (to SCKp↑) Note 1 | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V | 66 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 66 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 113 | | ns |
| Slp hold time (from SCKp↑) Note 1 | t _{SIH1} | | 38 | | ns |
| Delay time from SCKp↓ to SOp output Note 2 | t _{KSO1} | C = 30 pF Note 3 | | 66.6 | ns |

Note 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

Note 3. C is the load capacitance of the SCKp and SOp output lines.

Caution Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

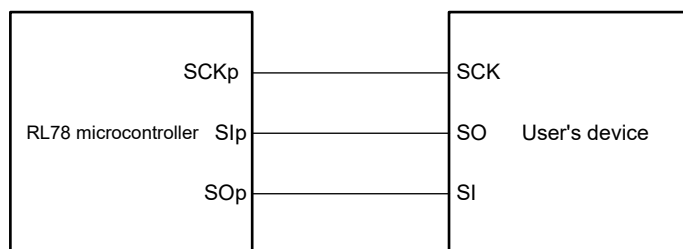
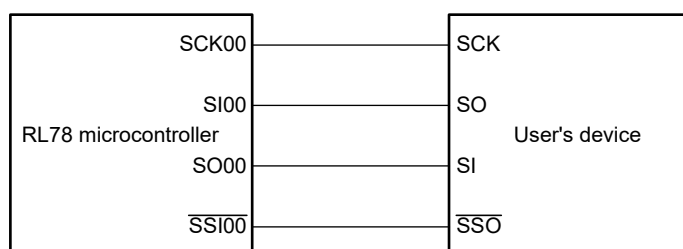
Remark 1. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)

Remark 2. f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

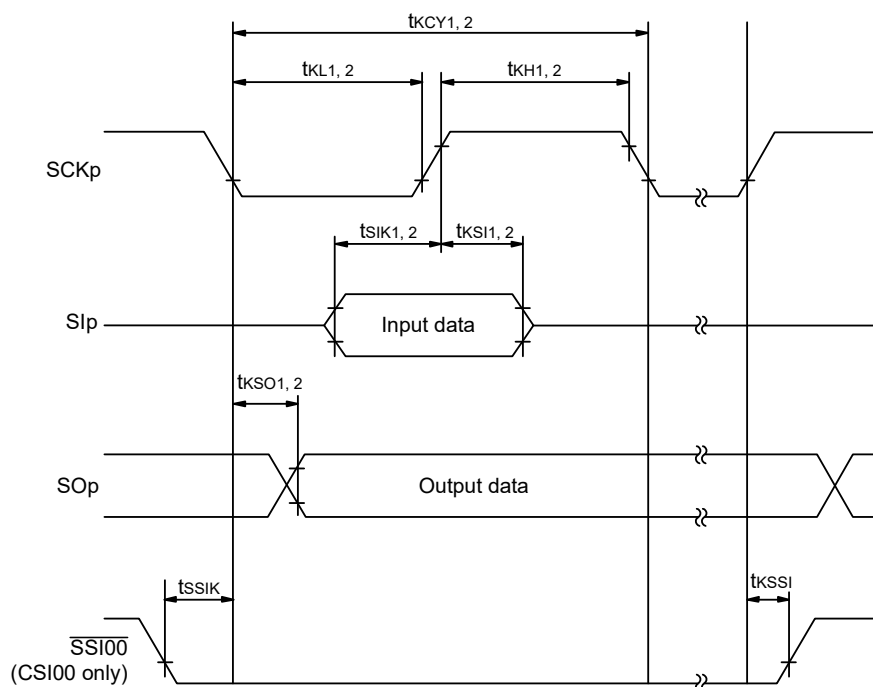
(3) During communication at same potential (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|---|-------------------------------------|---------------------------------|---------------------------------|------------------------------|--------------------------|------|
| | | | | MIN. | MAX. | |
| SCKp cycle time ^{Note 1} | t _{KCY2} | 4.0 V ≤ V _{DD} ≤ 5.5 V | 20 MHz < f _{MCK} | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 20 MHz | 12/f _{MCK} | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | 16 MHz < f _{MCK} | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 16 MHz | 12/f _{MCK} | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | 12/f _{MCK} and 1000 | | ns |
| SCKp high-/low-level width | t _{KH2} , t _{KL2} | 4.0 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 14 | | ns |
| | | 2.7 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 16 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | t _{KCY2} /2 - 36 | | ns |
| Slp setup time (to SCKp↑) ^{Note 2} | t _{SIK2} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 1/f _{MCK} + 40 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | 1/f _{MCK} + 60 | | ns |
| Slp hold time (from SCKp↑) ^{Note 2} | t _{SI2} | | | 1/f _{MCK} + 62 | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 3} | t _{SO2} | C = 30 pF ^{Note 4} | 2.7 V ≤ V _{DD} ≤ 5.5 V | | 2/f _{MCK} + 66 | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | | 2/f _{MCK} + 113 | ns |
| SSI00 setup time | t _{SSI} | DAPmn = 0 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 400 | | ns |
| | | DAPmn = 1 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 400 | | ns |
| SSI00 hold time | t _{SSI} | DAPmn = 0 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 1/f _{MCK} + 400 | | ns |
| | | DAPmn = 1 | 2.7 V ≤ V _{DD} ≤ 5.5 V | 240 | | ns |
| | | | 2.4 V ≤ V _{DD} ≤ 5.5 V | 400 | | ns |

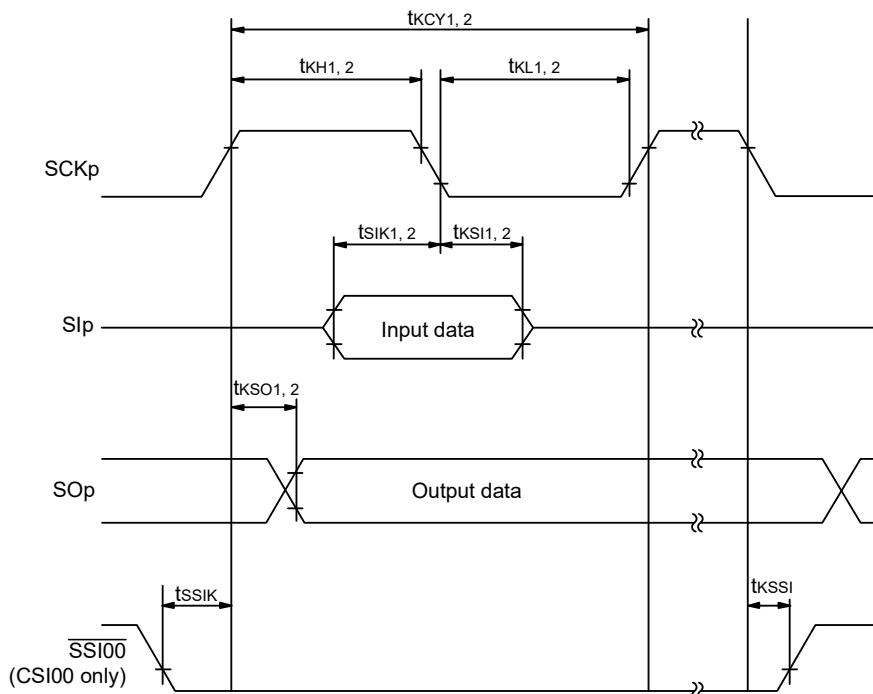
Note 1. The maximum transfer rate in the SNOOZE mode is 1 Mbps.**Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.**Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.**Note 4.** C is the load capacitance of the SOp output lines.**Caution** Select the normal input buffer for the Slp and SCKp pins and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).**Remark 1.** p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM number (g = 1)**Remark 2.** f_{MCK}: Serial array unit operation clock frequency
(Operation clock to be set by the CKS_{mn} bit of serial mode register mn (SMR_{mn}). m: Unit number, n: Channel number (mn = 00, 01))

Simplified SPI(CSI) mode connection diagram (during communication at same potential)**Simplified SPI(CSI) mode connection diagram (during communication at same potential)
(Slave Transmission of slave select input function (CSI00))****Remark 1.** p: Simplified SPI(CSI) number (p = 00, 01)**Remark 2.** m: Unit number, n: Channel number (mn = 00, 01)

Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (during communication at same potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number (p = 00, 01)

Remark 2. m: Unit number, n: Channel number (mn = 00, 01)

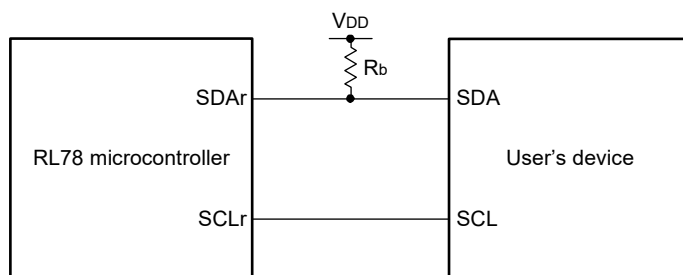
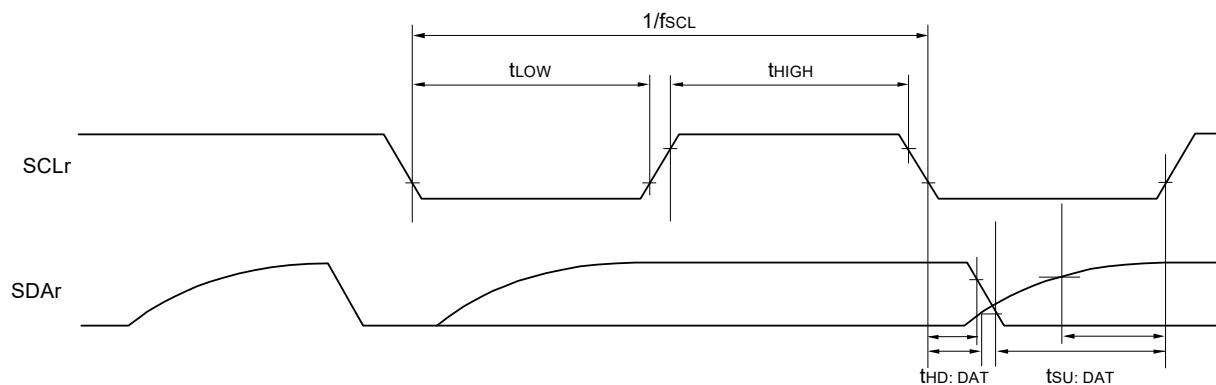
(4) During communication at same potential (simplified I²C mode)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|-------------------------------|----------------------|---|------------------------------------|------------|------|
| | | | MIN. | MAX. | |
| SCLr clock frequency | f _{SCL} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | | 400 Note 1 | kHz |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | | 100 Note 1 | kHz |
| Hold time when SCLr = "L" | t _{LOW} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 4600 | | ns |
| Hold time when SCLr = "H" | t _{HIGH} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 4600 | | ns |
| Data setup time (reception) | t _{SU: DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 220 Note 2 | | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 1/f _{MCK} + 580 Note 2 | | ns |
| Data hold time (transmission) | t _{HD: DAT} | 2.7 V ≤ V _{DD} ≤ 5.5 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 770 | ns |
| | | 2.4 V ≤ V _{DD} ≤ 5.5 V, C _b = 100 pF, R _b = 3 kΩ | 0 | 1420 | ns |

Note 1. The value must also be equal to or less than f_{MCK}/4.**Note 2.** Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the normal input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

Simplified I²C mode connection diagram (during communication at same potential)**Simplified I²C mode serial transfer timing (during communication at same potential)**

Remark 1. R_b [Ω]: Communication line (SDAr) pull-up resistance, C_b [F]: Communication line (SDAr, SCLr) load capacitance

Remark 2. r: IIC number (r = 00, 01), g: PIM number (g = 1), h: POM number (h = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0),

n: Channel number (n = 0, 1), mn = 00, 01)

(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(1/2)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|---------------|--------|------------|--|----------------|------|
| | | | MIN. | MAX. | |
| Transfer rate | | Reception | 4.0 V ≤ VDD ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V | fMCK/12 Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | 2.0 | Mbps |
| | | | 2.7 V ≤ VDD < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V | fMCK/12 Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | 2.0 | Mbps |
| | | | 2.4 V ≤ VDD < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V | fMCK/12 Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate fMCK = fCLK Note 2 | 2.0 | Mbps |

Note 1. Transfer rate in the SNOOZE mode is 4800 bps only.**Note 2.** The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

24 MHz (2.7 V ≤ VDD ≤ 5.5 V)

16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

Remark 1. Vb [V]: Communication line voltage**Remark 2.** q: UART number (q = 0, 1), g: PIM or POM number (g = 1)**Remark 3.** fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00, 01)

(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(2/2)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|---------------|--------|--------------|---|---------------------------|-------------|------|
| | | | | MIN. | MAX. | |
| Transfer rate | | Transmission | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | Note 1 | bps |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 1.4 kΩ, V _b = 2.7 V | | 2.0 Note 2 | Mbps |
| | | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | Note 3 | bps |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 2.7 kΩ, V _b = 2.3 V | | 1.2 Note 4 | Mbps |
| | | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | | Note 5 | bps |
| | | | Theoretical value of the maximum transfer rate C _b = 50 pF, R _b = 5.5 kΩ, V _b = 1.6 V | | 0.43 Note 6 | Mbps |

Note 1. The smaller maximum transfer rate derived by using fmck/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ VDD ≤ 5.5 V and 2.7 V ≤ Vb ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 2. This value as an example is calculated when the conditions described in the "Conditions" column are met.

Refer to **Note 1** above to calculate the maximum transfer rate under conditions of the customer.

Note 3. The smaller maximum transfer rate derived by using fmck/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ VDD < 4.0 V and 2.3 V ≤ Vb ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 4. This value as an example is calculated when the conditions described in the "Conditions" column are met.

Refer to **Note 3** above to calculate the maximum transfer rate under conditions of the customer.

Note 5. The smaller maximum transfer rate derived by using $f_{MCK}/12$ or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when $2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ and $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

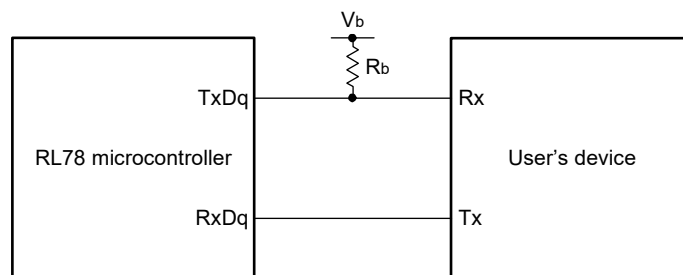
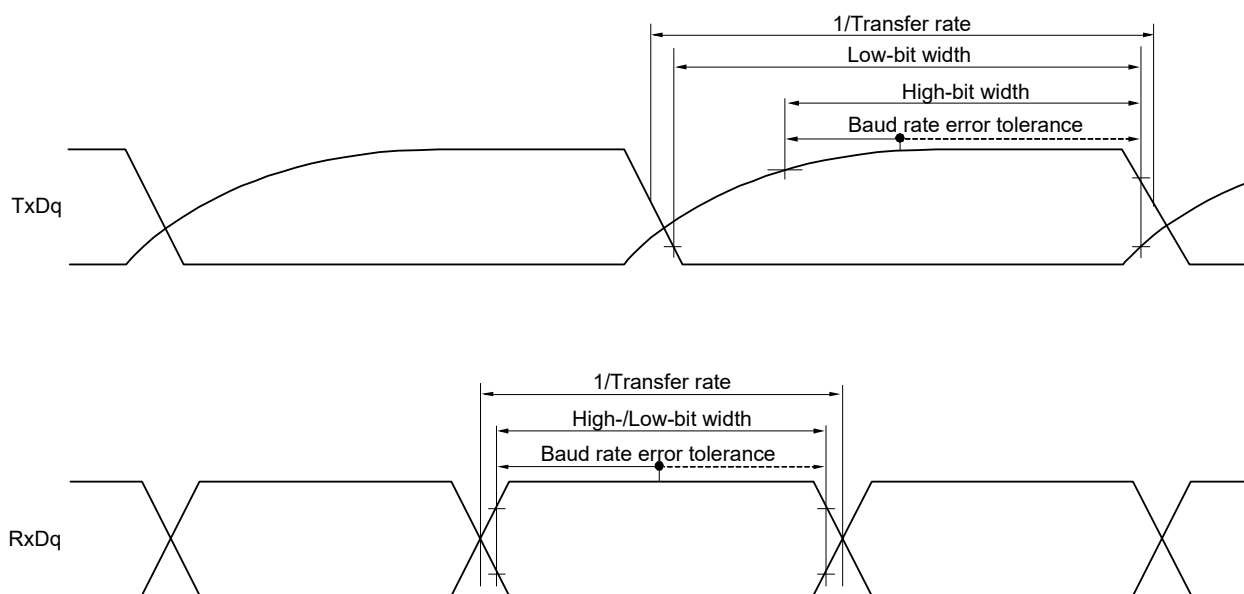
$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

* This value is the theoretical value of the relative difference between the transmission and reception sides.

Note 6. This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 5** above to calculate the maximum transfer rate under conditions of the customer.

Caution Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V_{DD} tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL} , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

UART mode connection diagram (during communication at different potential)**UART mode bit width (during communication at different potential) (reference)**

Remark 1. R_b [Ω]: Communication line (TxDq) pull-up resistance,
 C_b [F]: Communication line (TxDq) load capacitance, V_b [V]: Communication line voltage

Remark 2. q: UART number (q = 0, 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
 m: Unit number, n: Channel number (mn = 00, 01))

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(1/3)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|-----------------------|-------------------|--|----------------------------|------|------|
| | | | MIN. | MAX. | |
| SCKp cycle time | t _{KCY1} | t _{KCY1} ≥ 4/f _{CLK} 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 600 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 1000 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 2300 | | ns |
| SCKp high-level width | t _{KH1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 150 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 340 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | t _{KCY1} /2 - 916 | | ns |
| SCKp low-level width | t _{KL1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | t _{KCY1} /2 - 24 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | t _{KCY1} /2 - 36 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | t _{KCY1} /2 - 100 | | ns |

Caution Select the TTL input buffer for the SIp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(2/3)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|---|-------------------|--|---------------------------|------|------|
| | | | MIN. | MAX. | |
| Slp setup time (to SCKp↑) <i>Note</i> | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 162 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 354 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 958 | | ns |
| Slp hold time (from SCKp↑) <i>Note</i> | t _{KSI1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 38 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 38 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 38 | | ns |
| Delay time from SCKp↓ to SOp output <i>Note</i> | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | 200 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | 390 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | | 966 | ns |

Note When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

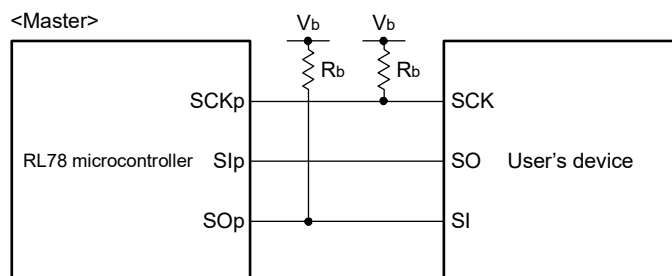
(Remarks are listed on the page after the next page.)

(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (master mode, SCKp... internal clock output)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(3/3)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|--|-------------------|--|---------------------------|------|------|
| | | | MIN. | MAX. | |
| Slp setup time (to SCKp↓) Note | t _{SIK1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 88 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 88 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 220 | | ns |
| Slp hold time (from SCKp↓) Note | t _{KSI1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | 38 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | 38 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | 38 | | ns |
| Delay time from SCKp↑ to SOp output Note | t _{KSO1} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | 50 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | 50 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | | 50 | ns |

Note When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V_{DD} tolerance) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

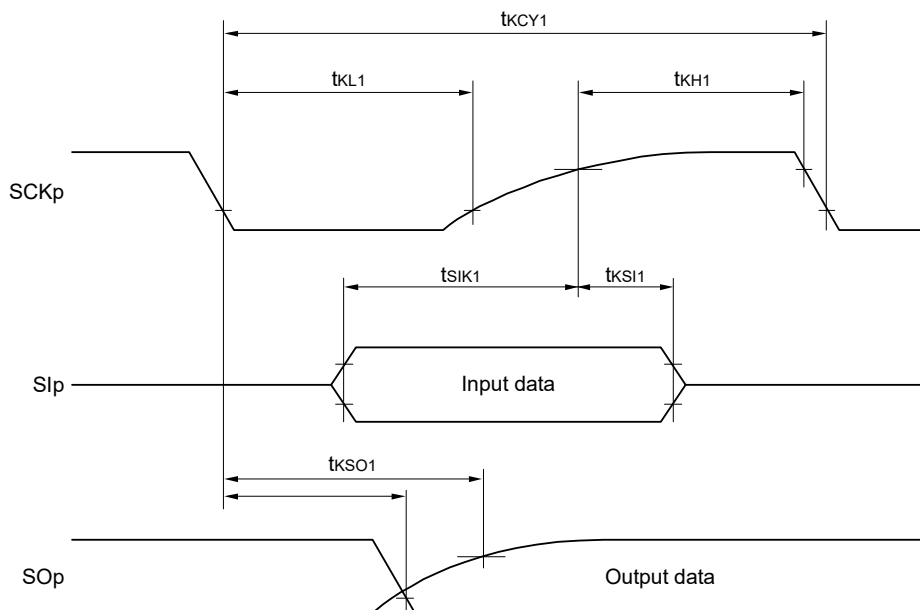
Simplified SPI (CSI) mode connection diagram (during communication at different potential

Remark 1. R_b [Ω]: Communication line (SCKp, SOp) pull-up resistance, C_b [F]: Communication line (SCKp, SOp) load capacitance, V_b [V]: Communication line voltage

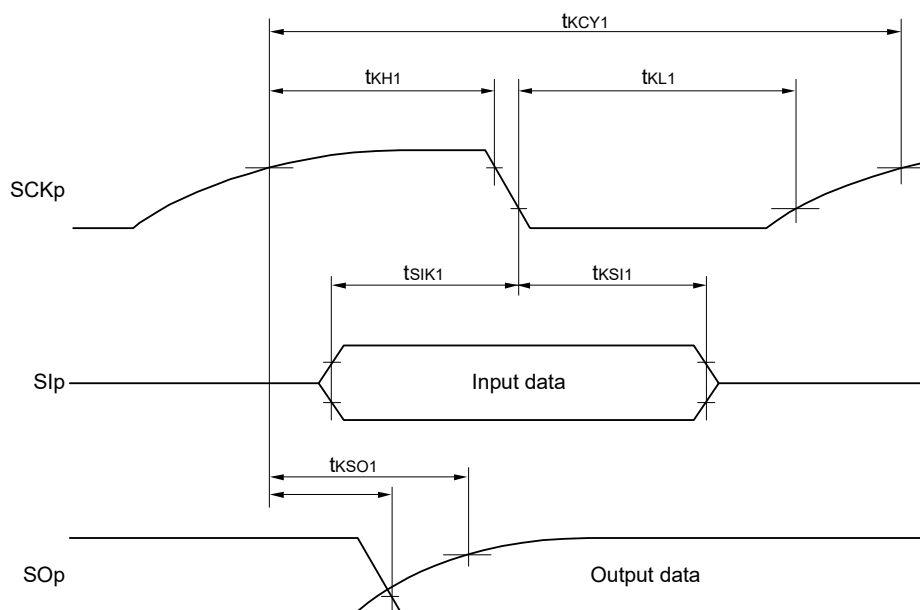
Remark 2. p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (master mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)

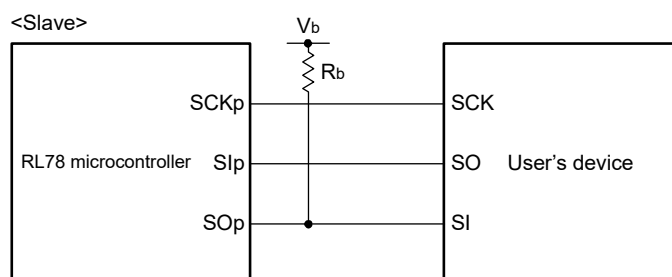
(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (Simplified SPI(CSI) mode) (slave mode, SCKp... external clock input)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)**

| Parameter | Symbol | Conditions | | HS (high-speed main) mode | | Unit |
|---|-------------------------------------|---|------------------------------------|----------------------------|---------------------------|------|
| | | | | MIN. | MAX. | |
| SCKp cycle time ^{Note 1} | t _{KCY2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | 20 MHz < f _{MCK} ≤ 24 MHz | 24/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 20 MHz | 20/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 4 MHz | 12/f _{MCK} | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | 20 MHz < f _{MCK} ≤ 24 MHz | 32/f _{MCK} | | ns |
| | | | 16 MHz < f _{MCK} ≤ 20 MHz | 28/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 16 MHz | 24/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 16/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 4 MHz | 12/f _{MCK} | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | 20 MHz < f _{MCK} ≤ 24 MHz | 72/f _{MCK} | | ns |
| | | | 16 MHz < f _{MCK} ≤ 20 MHz | 64/f _{MCK} | | ns |
| | | | 8 MHz < f _{MCK} ≤ 16 MHz | 52/f _{MCK} | | ns |
| | | | 4 MHz < f _{MCK} ≤ 8 MHz | 32/f _{MCK} | | ns |
| | | | f _{MCK} ≤ 4 MHz | 20/f _{MCK} | | ns |
| SCKp high-/low-level width | t _{KH2} , t _{KL2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | t _{KCY2} /2 - 24 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | t _{KCY2} /2 - 36 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | | t _{KCY2} /2 - 100 | | ns |
| Slp setup time (to SCKp↑) ^{Note 2} | t _{SIK2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V | | 1/f _{MCK} + 40 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V | | 1/f _{MCK} + 40 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V | | 1/f _{MCK} + 60 | | ns |
| Slp hold time (from SCKp↑) ^{Note 2} | t _{KS12} | | | 1/f _{MCK} + 62 | | ns |
| Delay time from SCKp↓ to SOp output ^{Note 3} | t _{KSO2} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 30 pF, R _b = 1.4 kΩ | | | 2/f _{MCK} + 240 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 30 pF, R _b = 2.7 kΩ | | | 2/f _{MCK} + 428 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 30 pF, R _b = 5.5 kΩ | | | 2/f _{MCK} + 1146 | ns |

(Notes, Cautions, and Remarks are listed on the next page.)

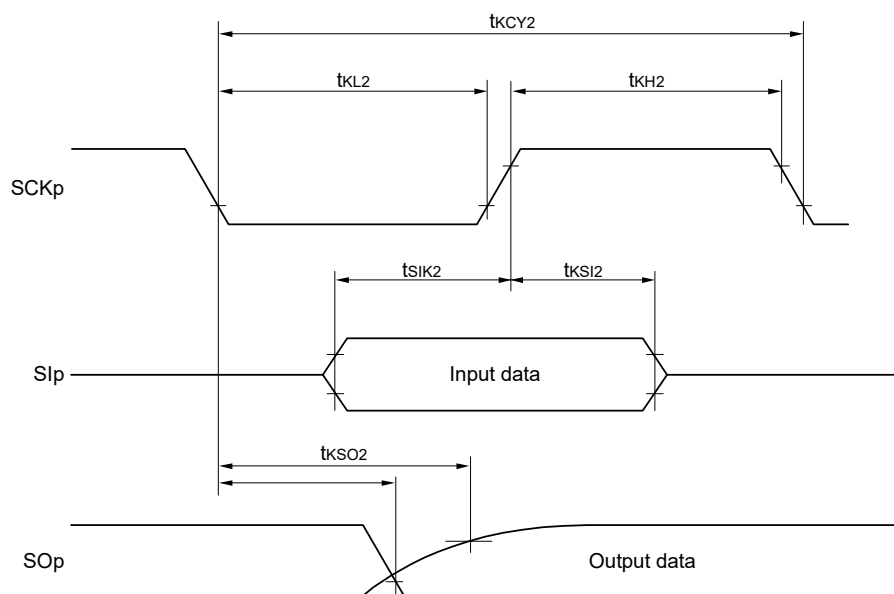
- Note 1.** Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The SIp setup time becomes "to SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0. The SIp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.
- Caution** Select the TTL input buffer for the SIp and SCKp pins, and the N-ch open drain output (VDD tolerance) mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

Simplified SPI(CSI) mode connection diagram (during communication at different potential)

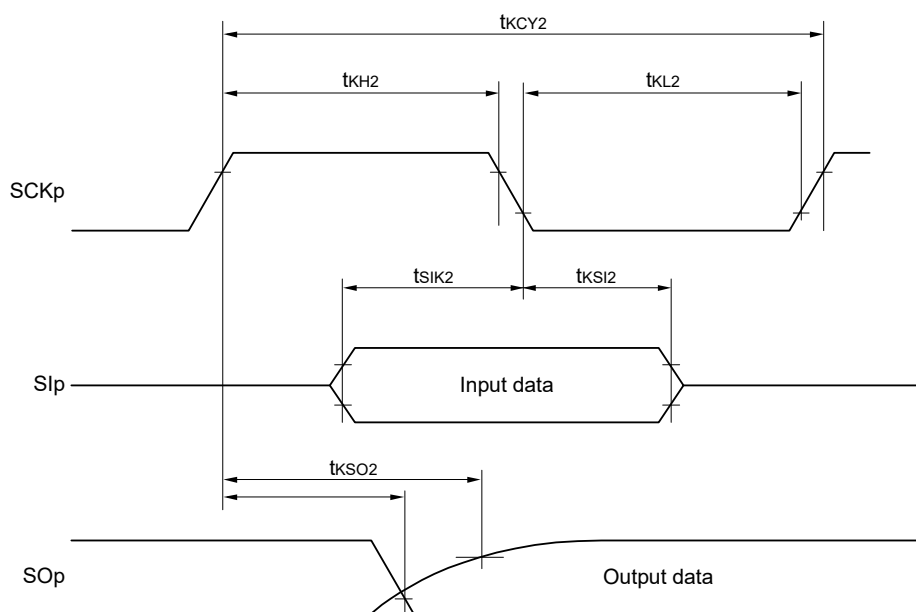


- Remark 1.** Rb [Ω]: Communication line (SOp) pull-up resistance, Cb [F]: Communication line (SOp) load capacitance, Vb [V]: Communication line voltage
- Remark 2.** p: Simplified SPI(CSI) number (p = 00, 01), m: Unit number (m = 0), n: Channel number (n = 0, 1), g: PIM or POM number (g = 1)
- Remark 3.** fMCK: Serial array unit operation clock frequency
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).
m: Unit number, n: Channel number (mn = 00, 01))
- Remark 4.** Communication at different potential cannot be performed during clocked serial communication with the slave select function.

Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



Simplified SPI(CSI) mode serial transfer timing (slave mode) (during communication at different potential)
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



Remark 1. p: Simplified SPI(CSI) number ($p = 00, 01$), m: Unit number ($m = 0$), n: Channel number ($n = 0, 1$), g: PIM or POM number ($g = 1$)

Remark 2. Communication at different potential cannot be performed during clocked serial communication with the slave select function.

(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(1/2)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|---------------------------|-------------------|---|---------------------------|------------|------|
| | | | MIN. | MAX. | |
| SCLr clock frequency | f _{SCL} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | | 400 Note 1 | kHz |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | | 400 Note 1 | kHz |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | | 100 Note 1 | kHz |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | | 100 Note 1 | kHz |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | | 100 Note 1 | kHz |
| Hold time when SCLr = "L" | t _{LOW} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 1200 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 4600 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 4600 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 4600 | | ns |
| Hold time when SCLr = "H" | t _{HIGH} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 620 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 500 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 2700 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 2400 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 1830 | | ns |

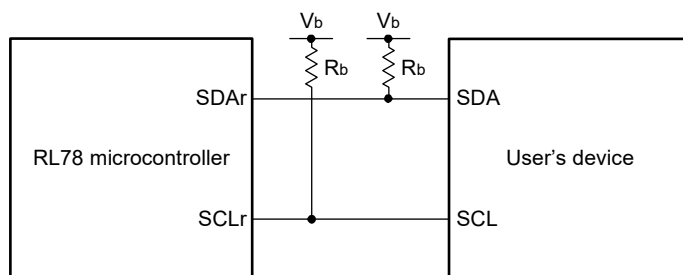
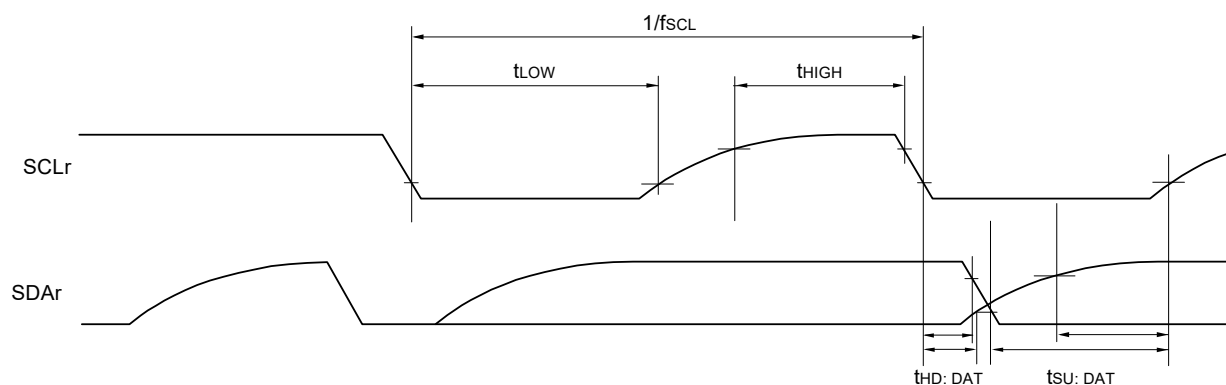
(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I²C mode)**(TA = -40 to +125°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)****(2/2)**

| Parameter | Symbol | Conditions | HS (high-speed main) mode | | Unit |
|-------------------------------|---------------------|---|---------------------------------|------|------|
| | | | MIN. | MAX. | |
| Data setup time (reception) | t _{SU:DAT} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 340 Note 1 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 340 Note 2 | | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 1/f _{MCK} + 760 Note 2 | | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 1/f _{MCK} + 760 Note 2 | | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 1/f _{MCK} + 570 Note 2 | | ns |
| Data hold time (transmission) | t _{HD:DAT} | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 770 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 50 pF, R _b = 2.7 kΩ | 0 | 770 | ns |
| | | 4.0 V ≤ V _{DD} ≤ 5.5 V, 2.7 V ≤ V _b ≤ 4.0 V, C _b = 100 pF, R _b = 2.8 kΩ | 0 | 1420 | ns |
| | | 2.7 V ≤ V _{DD} < 4.0 V, 2.3 V ≤ V _b ≤ 2.7 V, C _b = 100 pF, R _b = 2.7 kΩ | 0 | 1420 | ns |
| | | 2.4 V ≤ V _{DD} < 3.3 V, 1.6 V ≤ V _b ≤ 2.0 V, C _b = 100 pF, R _b = 5.5 kΩ | 0 | 1215 | ns |

Note 1. The value must also be equal to or less than f_{MCK}/4.**Note 2.** Set the f_{MCK} value to keep the hold time of SCLr = "L" and SCLr = "H".

Caution Select the TTL input buffer and the N-ch open drain output (V_{DD} tolerance) mode for the SDAr pin and the N-ch open drain output (V_{DD} tolerance) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V_{IH} and V_{IL}, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

Simplified I²C mode connection diagram (during communication at different potential)**Simplified I²C mode serial transfer timing (during communication at different potential)**

Remark 1. R_b [Ω]: Communication line (SDAr, SCLr) pull-up resistance, C_b [F]: Communication line (SDAr, SCLr) load capacitance, V_b [V]: Communication line voltage

Remark 2. r: IIC number (r = 00, 01), g: PIM, POM number (g = 1)

Remark 3. f_{MCK} : Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0), n: Channel number (n = 0), mn = 00, 01)

3.6 Analog Characteristics

3.6.1 Programmable gain instrumentation amplifier and 24-bit $\Delta\Sigma$ A/D converter

(1) Analog input in differential input mode

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---------------------|--|--|---------------------------|--|------|
| Full-scale differential input voltage range | V _{ID} | V _{ID} = (PGAxP - PGAxN) (x = 0 to 3) | | ± 800 /G _{TOTAL} | | mV |
| Input voltage range | V _I | Each of PGAxP and PGAxN pins (x = 0 to 3) | 0.2 | | 1.8 | V |
| Common mode input voltage | V _{COM} | doFR = 0 mV | 0.2+(V _{ID} x G _{SET1})/2 | | 1.8-(V _{ID} x G _{SET1})/2 | V |
| Input bias current | I _{IN} | V _I = 1.0 V | | | ± 50 | nA |
| Input offset current | I _{INOFFR} | V _I = 1.0 V | | | ± 20 | nA |

(2) Analog input in single-ended input mode

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------|-----------------|---|------|------|------|------|
| Input voltage range | V _I | Each of PGAxP and PGAxN pins (x = 0 to 3) G _{SET1} = 1, G _{SET2} = 1 | 0.2 | | 1.8 | V |
| Input bias current | I _{IN} | V _I = 1.0 V | | | ± 50 | nA |

(3) Programmable gain instrumentation amplifier and 24-bit $\Delta\Sigma$ A/D converter

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used, in differential input mode) (1/2)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------|--------------------|--|------------------------|----------------------|------------------------|------|
| Resolution | RES | | | | 24 | bit |
| Sampling frequency | fs1 | Normal mode | | 1 | | MHz |
| | fs2 | Low power mode | | 0.125 | | MHz |
| Output data rate | f _{DATA1} | Normal mode | 0.48828 | | 15.625 | ksps |
| | f _{DATA2} | Low power mode | 61.03615 | | 1953.125 | sps |
| Gain setting range | G _{TOTAL} | G _{TOTAL} = G _{SET1} × G _{SET2} | 1 | | 64 | V/V |
| 1st gain setting range | G _{SET1} | In differential input mode only | | 1, 2, 3, 4, 8 | | V/V |
| 2nd gain setting range | G _{SET2} | In differential input mode only | | 1, 2, 4, 8 | | V/V |
| Offset adjustment bit range | doFFB | | | 5 | | bit |
| Offset adjustment range | doFR | Referred to input | -164/G _{SET1} | | +164/G _{SET1} | mV |
| Offset adjustment steps | doFS | Referred to input | | 11/G _{SET1} | | mV |

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, normal mode: fs1 = 1 MHz, FDATA1 = 3.90625 ksps, low-power mode: fs2 = 0.125 MHz, FDATA2 = 488.28125 sps, SBIAS = 1.2 V, doFR = 0 mV, VCOM = 1.0 V, external clock input used, in differential input mode) (2/2)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|--------|--|------|---------|---------|--------|
| Gain error | EG | TA = 25°C GSET1 = 1, GSET2 = 1 Excluding SBIAS error | | ±0.2 | ±2.7 | % |
| | | TA = 25°C GSET1 = 8, GSET2 = 4 Excluding SBIAS error | | ±0.1 | | % |
| Gain drift ^{Note} | dEG | GSET1 = 1, GSET2 = 1 Excluding SBIAS drift | | (5.6) | (22.0) | ppm/°C |
| | | GSET1 = 8, GSET2 = 4 Excluding SBIAS drift | | (9.1) | | ppm/°C |
| Offset error | Eos | TA = 25°C GSET1 = 1, GSET2 = 1 Referred to input | | ±0.32 | ±2.90 | mV |
| | | TA = 25°C GSET1 = 8, GSET2 = 4 Referred to input | | ±0.03 | | mV |
| Offset drift ^{Note} | dEos | GSET1 = 1, GSET2 = 1 Referred to input | | (±0.02) | (±6.00) | μV/°C |
| | | GSET1 = 8, GSET2 = 4 Referred to input | | (±0.02) | | μV/°C |
| SND ratio | SNDR | GSET1 = 1, GSET2 = 1, fin = 50 Hz Normal mode, pin = -1 dBFS | (82) | (85) | | dB |
| | | GSET1 = 8, GSET2 = 4, fin = 50 Hz Normal mode, pin = -1 dBFS | (73) | (80) | | dB |
| Noise | Vn | GSET1 = 1, GSET2 = 1, OSR = 2048 | | (13) | | μVRms |
| | | GSET1 = 8, GSET2 = 4, OSR = 2048 | | (0.6) | | μVRms |
| Integral non-linearity error | INL | GSET1 = 1, GSET2 = 1, OSR = 2048 | | (±10) | | ppmFS |
| Common mode rejection ratio | CMRR | VCOM = 1.0 ± 0.8 V, fin = 50 Hz GSET1 = 1, GSET2 = 1 Differential input mode | (72) | (90) | | dB |
| Power supply rejection ratio | PSRR | AVDD = 2.7 to 5.5 V GSET1 = 1, GSET2 = 1 Differential input mode | | (85) | | dB |
| ΔΣ A/D converter input clock frequency | fADC | | 3.8 | 4 | 4.2 | MHz |

Note Calculate the gain drift and offset drift by using the following expression (for 125°C products):
 For gain drift: (MAX(EG(T(-40) to T(125))) - MIN(EG(T(-40) to T(125)))) / (125°C - (-40°C))
 For offset drift: (MAX(Eos(T(-40) to T(125))) - MIN(Eos(T(-40) to T(125)))) / (125°C - (-40°C))
 MAX(EG(T(-40) to T(125))): The maximum value of gain error when the temperature range is -40°C to 125°C
 MIN(EG(T(-40) to T(125))): The minimum value of gain error when the temperature range is -40°C to 125°C
 MAX(Eos(T(-40) to T(125))): The maximum value of offset error when the temperature range is -40°C to 125°C
 MIN(Eos(T(-40) to T(125))): The minimum value of offset error when the temperature range is -40°C to 125°C

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

3.6.2 Sensor power supply (SBIAS)

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, COUT = 0.22 μF, VOUT = 1.0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------|--------|--|------|------|------|------|
| Output voltage range | VOUT | | 0.5 | | 2.2 | V |
| Output voltage setting steps | VSTEP | | | 0.1 | | V |
| Output voltage precision | VA | IOUT = 1 mA | (-3) | | (+3) | % |
| Maximum output current | IOUT | | 5 | | | mA |
| Short circuit current | ISHORT | VOUT = 0 V | | 40 | 65 | mA |
| Load regulation | LR | 1 mA ≤ IOUT ≤ 5 mA | | | (15) | mV |
| Power supply rejection ratio | PSRR | AVDD = 5.0 V + 0.1 Vpp ripple f = 100 Hz, IOUT = 2.5 mA | (45) | (50) | | dB |

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

3.6.3 Temperature sensor

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------------|--------|------------|------|-------|------|-------|
| Temperature coefficient for sensor | TCSNS | | | (756) | | μV/°C |
| Sensor output voltage | VTEMP | TA = 25°C | | 226.4 | | mV |

Remark In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

3.6.4 A/D converter characteristics

- (1) When positive reference voltage (+) = AVDD (ADREFP1 = 0, ADREFP0 = 0), negative reference voltage (-) = AVss (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVss = Vss = 0 V, positive reference voltage (+) = AVDD, negative reference voltage (-) = AVss)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|--------|--|----------------------|--------|------|-------|------|
| Resolution | RES | | | 8 | | 10 | bit |
| Overall error Note 1 | AINL | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | 1.2 | ±6.5 | LSB |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | 1.2 | ±7.0 | LSB |
| Conversion time | tCONV | 10-bit resolution | 4.0 V ≤ AVDD ≤ 5.5 V | 2.125 | | 39 | μs |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | 3.1875 | | 39 | μs |
| Zero-scale error Notes 1, 2 | Ezs | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | | ±0.50 | %FSR |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±0.60 | %FSR |
| Full-scale error Notes 1, 2 | Efs | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | | ±0.50 | %FSR |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±0.60 | %FSR |
| Integral linearity error Note 1 | ILE | 10-bit resolution ANI0 to ANI9, SBIAS | 4.0 V ≤ AVDD ≤ 5.5 V | | | ±3.5 | LSB |
| | | | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±4.0 | LSB |
| Differential linearity error Note 1 | DLE | 10-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±2.0 | LSB |
| Analog input voltage | VAIN | ANI0 to ANI9 | | AVss | | AVDD | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Caution The number of pins depends on the product. For details, see a list of pin functions.

- (2) When positive reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), negative reference voltage (-) = AVss (ADREFM = 0), pins subject to A/D conversion: ANI0 to ANI9 and SBIAS

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVss = Vss = 0 V, positive reference voltage (+) = VBGR, negative reference voltage (-) = AVss)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|--------|----------------------|----------------------|-------------|------|-------|------|
| Resolution | RES | | | 8 | | | bit |
| Conversion time | tCONV | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | 17 | | 39 | μs |
| Zero-scale error Notes 1, 2 | Ezs | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±0.60 | %FSR |
| Integral linearity error Note 1 | ILE | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±2.0 | LSB |
| Differential linearity error Note 1 | DLE | 8-bit resolution | 2.7 V ≤ AVDD ≤ 5.5 V | | | ±1.0 | LSB |
| Internal reference voltage (+) | VBGR | 2.7 V ≤ AVDD ≤ 5.5 V | | VBGR Note 3 | | | V |
| Analog input voltage | VAIN | ANI0 to ANI9 | | 0 | | VBGR | V |

Note 1. Excludes quantization error (±1/2 LSB).

Note 2. This value is indicated as a ratio (%FSR) to the full-scale value.

Note 3. See the Internal reference voltage characteristics.

3.6.5 12-bit D/A converter

(1) When positive reference voltage (+) = AVDD (DACVRF = 0)

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, positive reference voltage (+) = AVDD)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|--------|---|------|------|-----------|------|
| Resolution | DARES | | | | (12) | bit |
| Output voltage range | DAOUT | 12-bit resolution | 0.35 | | AVDD-0.47 | V |
| Integral non-linearity error | DAILE | 12-bit resolution | | | ±4.0 | LSB |
| Differential non-linearity error | DADLE | 12-bit resolution | | | ±1.0 | LSB |
| Offset error | DAErr | 12-bit resolution | | | ±30 | mV |
| Gain error | DAEG | 12-bit resolution | | | ±20 | mV |
| Settling time | DAtset | 12-bit resolution, CL = 50 pF, RL = 10 kΩ | | | (60) | μs |

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.

(2) When positive reference voltage (+) = internal reference voltage (DACVRF = 1)

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, positive reference voltage (+) = VREFDA)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|----------------------------------|--------|--|------|------|--------|------|
| Resolution | DARES | | | | (8) | bit |
| Internal reference voltage | VREFDA | 8-bit resolution | 1.34 | 1.45 | 1.54 | V |
| Output voltage range | DAOUT | 8-bit resolution | 0.35 | | VREFDA | V |
| Integral non-linearity error | DAILE | 8-bit resolution | | | ±1.0 | LSB |
| Differential non-linearity error | DADLE | 8-bit resolution | | | ±1.0 | LSB |
| Offset error | DAErr | 8-bit resolution | | | ±30 | mV |
| Gain error | DAEG | 8-bit resolution | | | ±20 | mV |
| Settling time | DAtset | 8-bit resolution, CL = 50 pF, RL = 10 kΩ | | | (60) | μs |

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

Remark 2. The 12-bit D/A converter characteristics are the values obtained with the configurable amplifier connected.

Remark 3. Offset error and gain error do not include error in the internal reference voltage.

3.6.6 Configurable amplifier

(TA = -40 to +125°C, 2.7 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V, VCOM = 1/2 AVDD, internally connected voltage follower)

AMP0 configuration SW setting: Positive (+) pin = ANX1, negative (-) pin = ANX0

AMP1 configuration SW setting: Positive (+) pin = ANX3, negative (-) pin = ANX2

AMP2 configuration SW setting: Positive (+) pin = ANX5, negative (-) pin = ANX4

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|--------|---|---------------|---------------|---------------|--------|
| Input voltage | VIN | | AVSS | | AVDD | V |
| Output voltage | VOL | IL = -1 mA, AVDD = 2.7 to 5.5 V | | AVSS +0.02 | AVSS +0.07 | V |
| | VOH | IL = 1 mA, AVDD = 2.7 to 5.5 V | AVDD -0.15 | AVDD -0.02 | | V |
| Maximum output current | IOUT | 4.5 V ≤ AVDD ≤ 5.5 V | ±10 | | | mA |
| | | 2.7 V ≤ AVDD ≤ 5.5 V | ±5 | | | mA |
| Input-referred offset voltage | VOFF | TA = 25°C without trimming IL = 0 mA, VCOM = 1.0 V | | ±1 | ±4 | mV |
| | | TA = 25°C with trimming IL = 0 mA, VCOM = 1.0 V | | | ±0.35 | mV |
| Temperature coefficient for input-referred offset voltage | VOTC | IL = 0 mA | | (±2) | (±8) | μV/°C |
| Slew rate | SR1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (0.1) | | V/μs |
| | SR2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (0.8) | | V/μs |
| Gain bandwidth | GBW1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (350) | | kHz |
| | GBW2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (1.8) | | MHz |
| Phase margin | θM1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (70) | | deg |
| | θM2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (60) | | deg |
| Settling time | tset1 | Normal mode CL = 50 pF, RL = 10 kΩ | | (20) | | μs |
| | tset2 | High-speed mode CL = 50 pF, RL = 10 kΩ | | (10) | | μs |
| Peak-to-peak voltage noise | Enb | 0.1 to 10 Hz Normal mode CL = 50 pF, RL = 10 kΩ | | (2.0) | | μVrms |
| Input-referred noise | En | f = 1 kHz Normal mode CL = 50 pF, RL = 10 kΩ | | (70) | | nV/√Hz |
| Common mode rejection ratio | CMRR | f = 1 KHz, CL = 50 pF, RL = 10 kΩ | | (70) | | dB |
| Power supply rejection ratio | PSRR | 2.7 V ≤ AVDD ≤ 5.5 V CL = 50 pF, RL = 10 kΩ | | (62) | | dB |

(Remarks are listed on the next page.)

Remark 1. In the ratings column, values in parentheses are the target design values and therefore are not tested for shipment.

Remark 2. The TYP. conditions are the conditions when TA = 25°C and AVDD = 5.0 V.

Remark 3. Unless otherwise specified, offset trimming has proceeded.

Remark 4. Unless otherwise specified, values are for operation in normal mode.

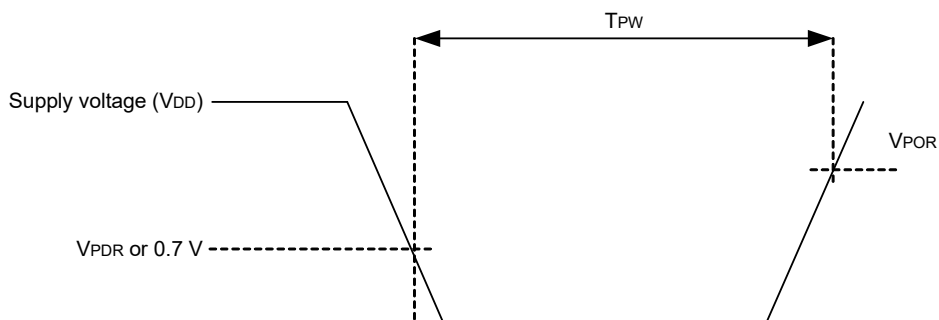
3.6.7 POR characteristics

(TA = -40 to +125°C, VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------------------|--------|--|------|------|------|------|
| Power on/down reset threshold | VPOR | Voltage threshold on VDD rising | 1.48 | 1.56 | 1.62 | V |
| | VPDR | Voltage threshold on VDD falling ^{Note 1} | 1.47 | 1.55 | 1.61 | V |
| Minimum pulse width ^{Note 2} | TPW | | 300 | | | μs |

Note 1. However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 3.4 AC Characteristics.

Note 2. Minimum time required for a POR reset when VDD exceeds below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HISTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



3.6.8 LVD characteristics

(1) LVD detection voltage in reset mode and interrupt mode

(TA = -40 to +125°C, VPDR ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------|--------|--------------|------|------|------|------|
| Voltage detection threshold | VLVD0 | Rising edge | 4.62 | 4.74 | 4.94 | V |
| | | Falling edge | 4.52 | 4.64 | 4.84 | V |
| | VLVD1 | Rising edge | 4.50 | 4.62 | 4.82 | V |
| | | Falling edge | 4.40 | 4.52 | 4.71 | V |
| | VLVD2 | Rising edge | 4.30 | 4.42 | 4.61 | V |
| | | Falling edge | 4.21 | 4.32 | 4.51 | V |
| | VLVD3 | Rising edge | 3.13 | 3.22 | 3.39 | V |
| | | Falling edge | 3.07 | 3.15 | 3.31 | V |
| | VLVD4 | Rising edge | 2.95 | 3.02 | 3.17 | V |
| | | Falling edge | 2.89 | 2.96 | 3.09 | V |
| | VLVD5 | Rising edge | 2.74 | 2.81 | 2.95 | V |
| | | Falling edge | 2.68 | 2.75 | 2.88 | V |
| | VLVD6 | Rising edge | 2.55 | 2.61 | 2.74 | V |
| | | Falling edge | 2.49 | 2.55 | 2.67 | V |
| Minimum pulse width | tlw | | 300 | | | μs |
| Detection delay time | | | | | 300 | μs |

(2) LVD detection voltage in interrupt & reset mode

(TA = -40 to +125°C, VPDR ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | | MIN. | TYP. | MAX. | Unit |
|-----------------------------|--------|--|------------------------------|------|------|------|------|
| Voltage detection threshold | VLVD6 | VPOC2, VPOC1, VPOC0 = 0, 0, 0, falling reset voltage | | 2.49 | 2.55 | 2.67 | V |
| | VLVD4 | LVIS1, LVIS0 = 0, 1 | Rising release reset voltage | 2.95 | 3.02 | 3.17 | V |
| | | | Falling interrupt voltage | 2.89 | 2.96 | 3.09 | V |
| | VLVD3 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 3.13 | 3.22 | 3.39 | V |
| | | | Falling interrupt voltage | 3.07 | 3.15 | 3.31 | V |
| | VLVD5 | VPOC2, VPOC1, VPOC0 = 0, 0, 1, falling reset voltage | | 2.68 | 2.75 | 2.88 | V |
| | VLVD2 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 4.30 | 4.42 | 4.61 | V |
| | | | Falling interrupt voltage | 4.21 | 4.32 | 4.51 | V |
| | VLVD5 | VPOC2, VPOC1, VPOC0 = 0, 1, 0, falling reset voltage | | 2.68 | 2.75 | 2.88 | V |
| | VLVD1 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 4.50 | 4.62 | 4.82 | V |
| | | | Falling interrupt voltage | 4.40 | 4.52 | 4.71 | V |
| | VLVD5 | VPOC2, VPOC1, VPOC0 = 0, 1, 1, falling reset voltage | | 2.68 | 2.75 | 2.88 | V |
| | VLVD3 | LVIS1, LVIS0 = 0, 1 | Rising release reset voltage | 3.13 | 3.22 | 3.39 | V |
| | | | Falling interrupt voltage | 3.07 | 3.15 | 3.31 | V |
| | VLVD0 | LVIS1, LVIS0 = 0, 0 | Rising release reset voltage | 4.62 | 4.74 | 4.94 | V |
| | | | Falling interrupt voltage | 4.52 | 4.64 | 4.84 | V |

3.6.9 Power supply voltage rising slope characteristics

(TA = -40 to +125°C, Vss = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------------|--------|------------|------|------|------|------|
| Power supply voltage rising slope | SVDD | | | | 50 | V/ms |

Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until VDD reaches the operating voltage range shown in 3.4 AC Characteristics.

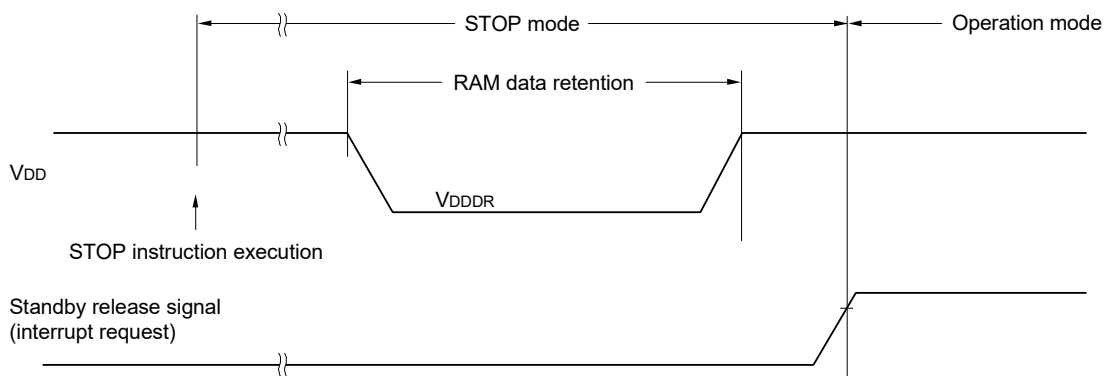
3.7 RAM Data Retention Characteristics

(TA = -40 to +125°C, Vss = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------|--------|------------|-----------------|------|------|------|
| Data retention supply voltage | VDDDR | | 1.47 Notes 1, 2 | | 5.5 | V |

Note 1. The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.

Note 2. Enter STOP mode before the supply voltage falls below the recommended operating voltage.



3.8 Flash Memory Programming Characteristics

(TA = -40 to +125°C^{Note 4}, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVss = Vss = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--|-------------------|--|---------|-----------|------|-------|
| System clock frequency | fCLK | 2.4 V ≤ VDD ≤ 5.5 V | 1 | | 24 | MHz |
| Number of code flash rewrites Notes 1, 2, 3 | C _{erwr} | Retained for 20 years TA = 85°C ^{Note 5} | 1,000 | | | Times |
| Number of data flash rewrites Notes 1, 2, 3 | | Retained for 1 year TA = 25°C ^{Note 5} | | 1,000,000 | | |
| | | Retained for 5 years TA = 85°C ^{Note 5} | 100,000 | | | |
| | | Retained for 20 years TA = 85°C ^{Note 5} | 10,000 | | | |

Note 1. 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

Note 2. When using flash memory programmer and Renesas Electronics self-programming library

Note 3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

Note 4. The range is from TA = -40 to +105°C when if the flash memory programmer is in use.

Note 5. This temperature is the average value at which data are retained.

3.9 Dedicated Flash Memory Programmer Communication (UART)

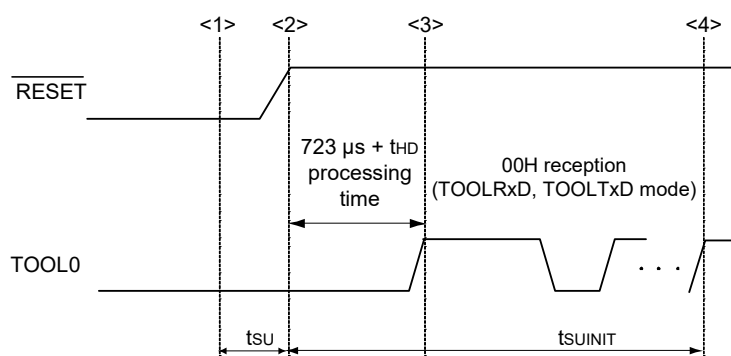
(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---------------|--------|---------------------------|---------|------|-----------|------|
| Transfer rate | | During serial programming | 115,200 | | 1,000,000 | bps |

3.10 Timing for Switching Flash Memory Programming Modes

(TA = -40 to +105°C, 2.4 V ≤ AVDD = VDD ≤ 5.5 V, AVSS = VSS = 0 V)

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|---|---------|--|------|------|------|------|
| How long from when an external reset ends until the initial communication settings are specified | tsuINIT | POR and LVD reset must end before the external reset ends. | | | 100 | ms |
| How long from when the TOOL0 pin is placed at the low level until an external reset ends | tsu | POR and LVD reset must end before the external reset ends. | 10 | | | μs |
| How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory) | thd | POR and LVD reset must end before the external reset ends. | 1 | | | ms |



<1> The low level is input to the TOOL0 pin.

<2> The external reset ends (POR and LVD reset must end before the external reset ends).

<3> The TOOL0 pin is set to the high level.

<4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

Remark tsuINIT: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.

tsu: How long from when the TOOL0 pin is placed at the low level until a pin reset ends

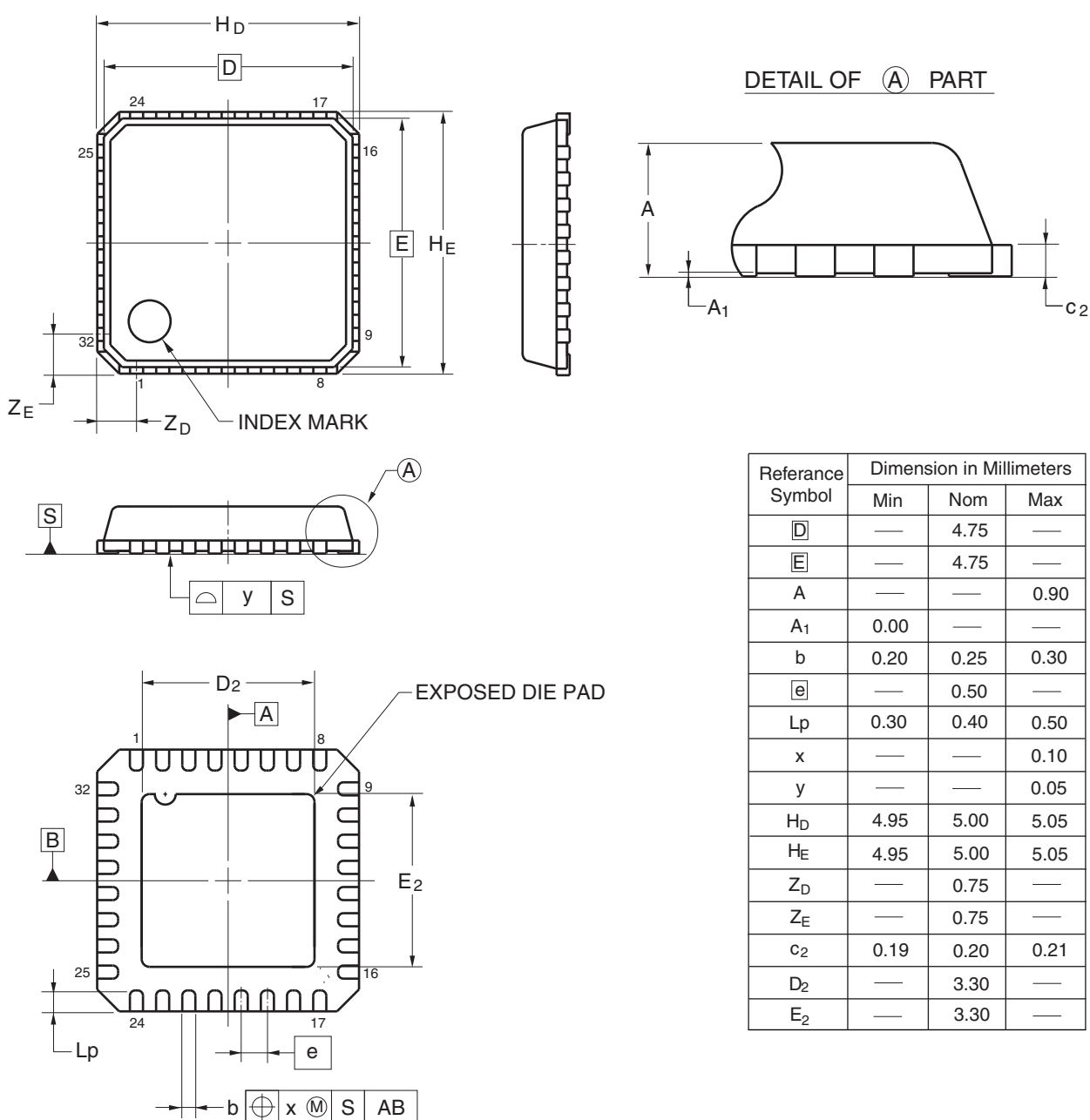
thd: How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

4. PACKAGE DRAWINGS

4.1 32-pin products

R5F11CBCGNA, R5F11CBCMNA

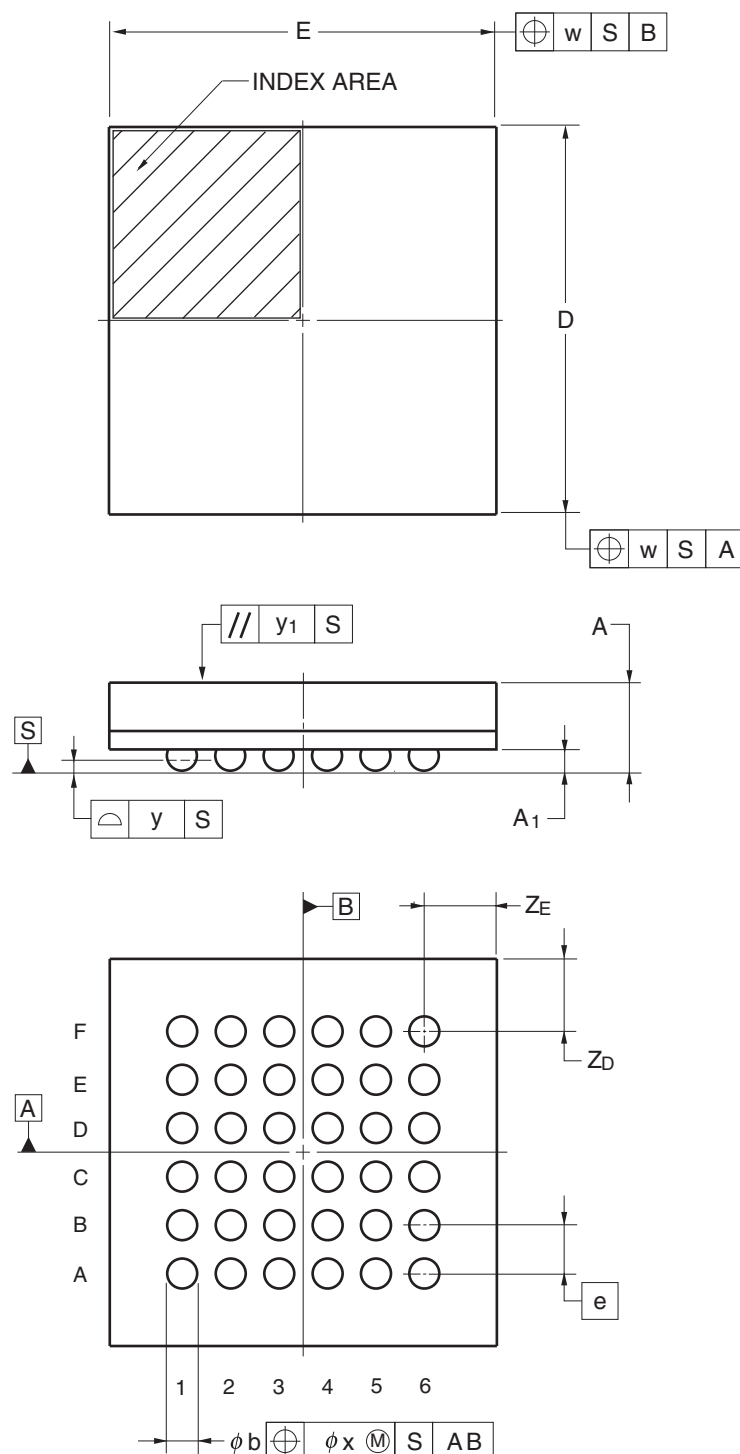
| JEITA Package code | RENESAS code | Previous code | MASS(TYP.)[g] |
|--------------------|--------------|---------------|---------------|
| P-HVQFN32-5x5-0.50 | PVQN0032KE-A | P32K9-50B-BAH | 0.058 |



4.2 36-pin products

R5F11CCCGBG, R5F11CCCMBG

| JEITA Package code | RENESAS code | Previous code | MASS(TYP.)[g] |
|--------------------|--------------|---------------|---------------|
| P-TFBGA36-4x4-0.50 | PTBG0036KA-A | P36F1-50-AA6 | 0.027 |



| Reference Symbol | Dimension in Millimeters | | |
|------------------|--------------------------|------|------|
| | Min | Nom | Max |
| D | 3.90 | 4.00 | 4.10 |
| E | 3.90 | 4.00 | 4.10 |
| A | — | — | 1.10 |
| A ₁ | 0.17 | 0.22 | 0.27 |
| e | — | 0.50 | — |
| b | 0.26 | 0.31 | 0.36 |
| x | — | — | 0.05 |
| y | — | — | 0.08 |
| y ₁ | — | — | 0.20 |
| Z _D | — | 0.75 | — |
| Z _E | — | 0.75 | — |
| w | — | — | 0.20 |

| | |
|------------------|--------------------|
| REVISION HISTORY | RL78/I1E Datasheet |
|------------------|--------------------|

| Rev. | Date | Description | |
|------|--------------|-------------|---|
| | | Page | Summary |
| 1.30 | Mar 29, 2024 | p.3 | Modification of Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E |
| | | | Modification of Ordering Part Number in 1.2 Ordering Information |
| 1.20 | May 31, 2023 | All | The module name for CSI was changed to simplified SPI. |
| | | p.2 | Addition of Note in 1.1 Features |
| | | p.3 | Modification of Figure 1 - 1 Part Number, Memory Size, and Package of RL78/I1E |
| | | | Addition of R5F11CBCGNA#00 in Fields of Application Notes G |
| 1.10 | Jun 30, 2016 | 4 | Addition of products name in 1.3.1 32-pin products |
| | | 5 | Addition of products name in 1.3.2 36-pin products |
| | | 10 | Change of DTC in 1.6 Outline of Functions |
| | | 10 | Addition of Note1 in 1.6 Outline of Functions |
| | | 43 | Change of 2.5.1 (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock in input) |
| | | 57 | Change of 2.7 RAM Data Retention Characteristics |
| | | 57 | Change of 2.8 Flash Memory Programming Characteristics |
| | | 62 | Change of 3.2.2 On-chip oscillator characteristics |
| | | 91 | Change of 3.5.1 (7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock in input) |
| | | 105 | Change of 3.7 RAM Data Retention Characteristics |
| | | 105 | Change of 3.8 Flash Memory Programming Characteristics |
| 1.00 | Jul 31, 2015 | — | First Edition issued |

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General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between V_{IL} (Max.) and V_{IH} (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between V_{IL} (Max.) and V_{IH} (Min.).

7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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